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PRELIMINARY DO NOT DESTROY

TECHNICAL MANUAL

for

TRANSISTORIZED SSB

TRANSMITTER/RECEIVER

MODEL TTR-10A



THE TECHNICAL MATERIEL CORPORATION

MAMARONECK, N.Y. OTTAWA, ONTARIO

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700 FENIMORE ROAD

MAMARONECK, N. Y.

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- 2. Serial Number of Equipment.
- 3. TMC Part Number.
- 4. Nature of defect or cause of failure.
- 5. The contract or purchase order under which equipment was delivered.

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- 1. Quantity Required.
- 2. TMC Part Number.
- 3. Equipment in which used by TMC or Military Model Number.
- 4. Brief Description of the Item.
- 5. The Crystal Frequency if the order includes crystals.

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THE TECHNICAL MATERIEL CORPORATION
Engineering Services Department
700 Fenimore Road
Mamaroneck, New York

CHANGE NO.	1
CUMITOR 1121	



INSTRUCTION BOOK CHANGE NOTICE

		Date	Nove	nber 14,	1969
Manual affected	TTR-10A		IN]	L004X	

On Page 6-15, change TMC Part Number for Relay K1601 from RL165-2 to RL156-2.

RECORD OF CORRECTIONS MADE

Change No.	Date of Change	Date Entered	Entered By
	_1	1	<u> </u>

TABLE OF CONTENTS

SE	CTION 1 — GENERAL INFORMATION		SEC	TION 4 - PRINCIPLES OF OPERATION	
Para	graph P	age	Parag	graph Pa	ıge
1-1 1-2 1-3 1-4	Functional Description	l - 2 l - 4	4-1 4-2 4-3	General 4 Receiver Section Theory 4 Transmitter Section Theory 4	-0
SE	CTION 2 - INSTALLATION		SEC	CTION 5 - MAINTENANCE	
2-1 2-2 2-3 2-4 2-5	Unpacking and Handling	2-1 2-1 2-2	5-1 5-2 5-3 5-4 5-5 5-6 5-7	Preventive Maintenance 5 Receiver Section Troubleshooting 5 Transmitter Section Troubleshooting 5 Receiver Section Alignment	-1 -1 -1 -2
SE	CTION 3 — OPERATOR'S SECTION		SEC	CTION 6 — PARTS LIST	
			6-1	Introduction 6	-1
3-1 3-2	Controls and Indicators		SEC	TION 7 — SCHEMATIC DIAGRAMS	
SE	LIST OF	ILLU		IONS	ont.)
Figur	<u>P</u>	age	Figur	<u>e</u> <u>Pa</u>	ige
1-1	Transistorized SSB Transmitter/ Receiver, Model TTR-10 1	-0	4-4	TTR-10 Transmitter Section, Block Diagram (Sheet 1 of 2)	.7
SEC	CTION 2 — INSTALLATION		4-4 4-5	TTR-10 Transmitter Section, Block Diagram (Sheet 2 of 2) 4- Frequency Inversion in SSB Trans-	.9
2-1	Rear Panel, TTR-102	-3 A	4-6	mission 4- Linear Amplifier, Simplified Schematic 4-	
SE	CTION 3 - OPERATOR'S SECTION				20
3-1	Front Panel Controls and Indicators,		SEC	TION 5 - MAINTENANCE	
SECTION 4—PRINCIPLES OF OPERATION		5-1 5-2 5-3	TTR-10, Bottom View 5- TTR-10, Bottom View With Under-	-8 -10	
4-1	TTR-10 Receiver Section, Block	posed		side of Hinged Board Assemblies Exposed 5-	-11
4-2	Diagram 4. Frequency Inversion in SSB Reception				
4-3	tion	- 3 - 5			

LIST OF ILLUSTRATIONS (CONT)

SECTION 5 - MAINTENANCE (Cont.)

SECTION 7 - SCHEMATIC DIAGRAMS

Figure Page Figure	Page
TTR-10, Top View With TTRA Modules Removed	7-17 7-19 7-21

LIST OF TABLES

SECTION 1 - GENERAL INFORMATION

SECTION 6 - PARTS LIST

ii

<u> Fable</u>	<u>.</u>	Page	Table	Page
1-1	Equipment Supplied			Final Tune Module, 2-4 MC 6-2 Final Tune Module, 4-8 MC 6-3 Final Tune Module, 8-16 MC · · · 6-4 Final Tune Module, 16-32 MC · · · 6-5 Main Chassis Assembly 6-6
SEC	TION 3 — OPERATOR'S SECTION			IF And Audio Receiver Board Assemblies 6-13
3-1 3-2 3-3	Controls and Indicators Transmitter Control Settings Changing Plug-In Modules	3-5		IF And Audio Transmitter Board Assemblies 6-21
SEC	TION 5 - MAINTENANCE			
5-1 5-2 5-3	Test Equipment Required Transistor And Tube Voltage Measurements	5-4		

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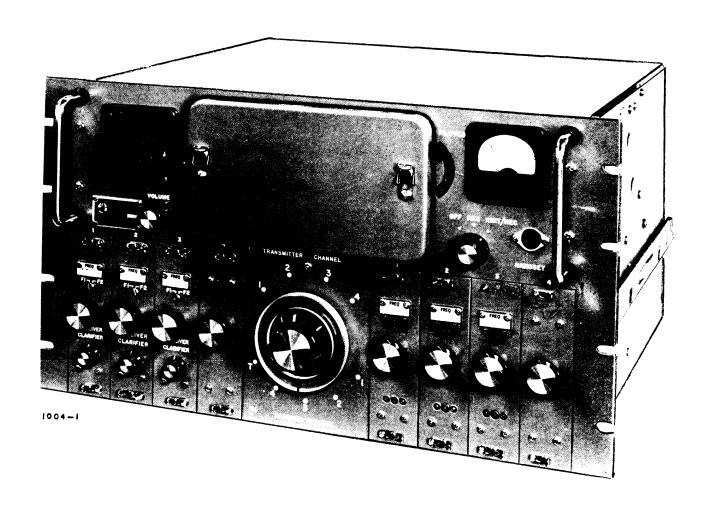


Figure 1-1. Transistorized SSB Transmitter/Receiver, Model TTR-10

SECTION 1 GENERAL DESCRIPTION

1-1. FUNCTIONAL DESCRIPTION.

a. GENERAL. - Transistorized SSB Transmitter/Receiver, Model TTR-10A (figure 1-1) is a four-channel transmitter/receiver covering the 2- to 32-mc frequency range and with the capability of simplex or duplex operation. The TTR-10 contains both a fully-transistorized superheterodyne receiver, and a fully transistorized transmitter that is coupled with a high-power vacuum-tube linear amplifier. Operating potentials for the TTR-10 are provided by one of six different plug-in power-supply modules; these power supplies are available for use with a-c or d-c input power (refer to paragraph 1-4). For information regarding any of the power-supply modules, refer to the TPS()-1 manual.

Operating frequencies for the transmit and receive sections of the TTR-10 are obtained from fixed-tuned, crystal-controlled, plug-in modules (TTRR modules for receiver section; TTRT modules for transmitter section). Various combinations of these plug-in modules may be used to provide frequency coverage in accordance with operating requirements (refer to module emparagraph 1-4). Each TTRR ployed in the TTR-10 has two selectable, crystalcontrolled, local-oscillator frequencies that permit operation on either of two signals frequencies (F1 or F2) within the r-f bandpass of the module, without necessitating realignment. Field change to new operating frequencies is easily accomplished (refer to section 5 and the appropriate TTRR manual.

The TTR-10 is designed so that remote selection of upper or lower sideband (receive) is possible. Remote selection of transmit and/or receive channels (TTRR and TTRT modules) and tuned antenna circuits is also possible upon special request at time of order or upon field modification.

b. RECEIVER SECTION. - The TTR-10 is capable of receiving amplitude modulation (AME), continuous wave (CW), facsimile (FAX), frequency shift keying (FSK), modulated continuous wave (MCW), and single sideband (SSB) transmission.

NOTE

Converter equipment is required to process FAX and FSK signals.

The receiver section uses one of four selectable, fixed-tuned, plug-in modules (TTRR-1, TTRR-2, TTRR-3, or TTRR-4) for its r f section. For infor-

mation pertaining to any of the TTRR modules, refer to the TTRR manual. Performance specifications for the receiver section are given in paragraph 1-4; other features of the receiver section include:

- (1) High sensitivity for good reception under weak signal conditions.
- (2) A sharp cutoff bandpass filter for optimum selectivity.
- (3) Double conversion and three tuned r-f amplifier stages.
 - (4) Manual selection of LSB or USB reception.
- (5) An adjustable squelch circuit that mutes the audio output (except for the 600-ohm line output) when no input signal is being received. This circuit also provided an external output (for alarm purposes) to indicate that the receiver is squelched.
- (6) The receiver section produces two separate audio outputs. These are 500 milliwatts into 4 ohm load (built-in or external speaker) and 1 milliwatt into a 600-ohm balanced load. The speaker output level can be varied by means of a VOLUME control.
- c. TRANSMITTER SECTION. The TTR-10 can transmit amplitude modulation equivalent (AME), continuous wave (CW), facsimile (FAX), frequency shift keying (FSK), modulated continuous wave (MCW), and single sideband (SSB) signals.

NOTE

Additional equipment is required to provide FAX and FSK input signals.

The transmitter section uses one of four selectable, fixed-tuned plug in modules (TTRT-1, TTRT-2, TTRT-3, TTRT-4) for its exciter r-f section. The linear-amplifier tuning circuits employed in the transmitter section are also contained in plug-in modules (TTRA-1, TTRA-2, TTRA-3, TTRA-4). TTRT and TTRA modules are selected in pairs and must be of the same model number (TTRT-1 and TTRA-1, TTRT-2 and TTRA-2, etc.). Information concerning TTRA modules can be found in this manual; for information pertaining to the TTRT module, refer to the TTRT manual.

The transmitter section is designed to accept a wide variety of audio inputs including carbon microphone, high-impedance microphone, low-impedance microphone, and 600-ohm balanced line. Provision is also made for operation with a handset (also avail-

able from TMC). The transmitter section contains an audio oscillator that can be externally keyed for CW and MCW transmission. Performance specifications for the transmitter section are given in paragraph 1-4; other features of the transmitter section include:

- (1) ALDC circuitry to limit high drive peaks (which can be developed during signal transmission) thus suppressing unwanted distortion.
- (2) Built-in power compensation circuit to prevent transmitter overload when mode of operation is changed.
- $(\mathbf{\mathcal{J}})$ Automatic compression circuit for higher average power output.
- (4) Selectable voice or push-to-talk operation of transmitter with provision for disabling the receiver section while transmitting (for simplex operation).
- (5) A built-in meter for monitoring the linear amplifier excitation, plate current, drive and output.
- (6) An automatic high-voltage cutout circuit to protect the linear amplifier when overload occurs.

1-2. PHYSICAL DESCRIPTION.

a. <u>EXTERNAL</u>. - The TTR-10 is normally provided for mounting in a standard 19-inch rack, but can also be provided in a sturdy metal case for general use. Two handles are located on the front panel for ease of handling. Dust covers protect the unit when it is rack-mounted.

All operator's controls with the exception of the

MIKE/LINE and OVEN VOLTAGE switches are located on the front panel; the MIKE/LINE and OVEN VOLTAGE switches are located on the rear of the unit. All controls are described in section 3 and illustrated in figures 2-1 and 3-1. A removable control cover is provided to prevent inadvertent changing of front-panel control settings. boards (TB1500, TB1501 and TB1502), two BNC connectors (RCVR ANT and ANTENNA jacks), and two twistlock plugs (EXTERNAL OVEN VOLTAGE and AC INPUT) on the rear of the unit provide for all input and output connections. Coaxial cable assembly W900 is provided for connecting the receiver section input to the transmitting antenna for simplex operation.

b. INTERNAL. - Most of the smaller components in the TTR-10 are located on printed circuit boards that are mounted to the chassis; the larger components are chassis mounted. There are six printed circuit boards (xmtr audio, xmtr i-f, receiver audio, receiver i-f, CW oscillator, and preamplifier) not including those in the TTRR and TTRT modules. The transmitter i-f and audio boards are mounted back-toback on a hinged assembly that permits the boards to swing out so that the components of the audio board (normally facing the interior of the chassis) are exposed. The receiver i-f and audio boards are similarly mounted. All six printed circuit boards are located on the bottom side of the TTR-10 chassis. Four TTRA modules are located on the top side of the chassis. These are plug-in tuning modules for the linear amplifier. The two vacuum tubes for the linear amplifier are located in a compartment between the TTRA modules.

Figures 5-1 through 5-8 show the location of most of the components in the TTR-10.

1-3. EQUIPMENT SUPPLIED.

Table 1-1 lists the equipment supplied with the TTR-10.

TABLE 1-1. EQUIPMENT SUPPLIED

NAME	DESIGNATION	FUNCTION	QUANTITY
Transistorized SSB Transmitter/Re- ceiver	TTR-10 A	Communications trans- mitter and receiver	1
Fanning strip		Aid for rear panel wiring	2
Rf connector		Antenna connection	1
Service extension module	AX-436	Aid for adjustment of TTRR and TTRT modules	1

1-4. TECHNICAL SPECIFICATIONS.

a. RECEIVER SECTION.

Frequency range

Band 2: 4-8 mc, TTRR-2 Band 3: 8-16 mc, TTRR-3

Band 4: 16-32 mc, TTRR-4

4 (each having a separate TTRR module) Number of channels

Each TTRR module is fixed-tuned to a particular frequency within its band. The receiver section is tuned by selecting one of the different TTRR modules

ing TTRR modules.

Band 1: 2-4 mc, TTRR-1

(channels).

Crystal-controlled oscillators are used throughout the receiver section.

2 to 32 mc divided into four bands using the follow-

AME, CW, FAX, FSK, MCW, and SSB (upper or lower).

15 db or better

1 microvolt input for 15 db signal-plus-noise to noise ratio.

3 kc, ± 2 db between 300 and 3300 cps.

Double conversion from 1.75 mc to 250 kc on all bands.

A minimum of 50 db from 2 to 28 mc, a minimum of 40 db from 28 to 32 mc.

Intermodulation products are at least 35 db below a 100 microvolt two tone input at the antenna.

With a 100 db increase in the signal input from 1 microvolt, the output level will not rise more than 6 db.

At least 40 db below full output.

50 ohms (nominal) unbalanced.

- 1. 500 milliwatts into 4 ohms for built in or external speaker.
- 2. 1 milliwatt in 600-ohm balanced load.

Tuning System

Frequency control

Types of signals

Noise Figure

Sensitivity

Audio bandwidth

I-f frequency

Image rejection

Intermodulation

AGC

Hum and noise level

Antenna input impedance

Audio output

*With appropriate counter

103671004X 1-3

1-4. TECHNICAL SPECIFICATIONS.

b. TRANSMITTER SECTION.

Frequency range

2--32~mc divided into four bands using the following TTRT and TTRA modules:

Band 1: 2-4 mc, TTRT-1 and TTRA-1

Band 2: 4-8 mc, TTRT-2 and TTRA-2

Band 3: 8-16 mc, TTRT-3 and TTRA-3

Band 4: 16-32 mc, TTRT-4 and TTRA-4

Number of channels

Tuning system

Frequency control

Types of signals transmitted

Audio bandwidth

I-f frequency

Power Output

Signal-to-distortion ratio

Unwanted sideband rejection

Spurious signal level

Noise level

Carrier suppression

Band 6. 6-10 me, 11R1-3 and 1TRA-3

4 (each having separate TTRT and TTRA modules).

Each TTRT and TTRA module is fixed-tuned to a particular frequency within its band. The transmitter section is tuned by selecting one of the different TTRT modules (channels); the corresponding TTRA module is selected automatically.

Crystal-controlled oscillators are used throughout the transmitter section.

AME, CW, FAX, FSK, MCW, and SSB

2. 75 kc ± 2 db between 250 and 3000 cps.

5 mg/e conversion; 1.75 mc

100 watts PEP. 50 watts CW.

35 db minimum at full PEP output.

40 db minimum at full PEP output.

Down a minimum of 50 db at full PEP output.

Down a minimum of 40 db at full PEP output.

Automatically preset at -50 db, -20 db, or -6 db from sideband envelope power depending upon operating mode selected as follows:

CW and SSB:

-40 db

-20 DB

-20 db

AME and MCW:

-6 db

50 ohms (nominal) unbalanced into a load with up to 3:1 VSWR.

Output impedance

^{*} With appropriate counter

1-4. TECHNICAL SPECIFICATIONS. (CONT)

c. OVERALL.

Primary power input

Power consumption

115 VAC Single Phase, TPSA module.

1. 230 watts when in XMIT/REC and transmitting.

2. 25 watts when in XMIT/REC but not transmitting.

3. 8 watts when in REC.

4. Crystal ovens require 6 watts each in addition to the above.

Dimensions

Length: 16-1/2 inches

Width: 19 inches

Hight: 10-1/2 inches

Weight, uncrated

65 pounds (rack mounted version only).

SECTION 2 INSTALLATION

2-1. UNPACKING AND HANDLING.

The TTR-10 is shipped from the factory in a wooden crate to ensure maximum protection from damage in transit. The inside of the crate contains additional packing material to protect the unit not only from breakage due to shock, but also from the elements. The equipment supplied with the TTR-10 (table 1-3) is packed in the box as loose items.

As soon as the TTR-10 is unpacked, it should be visually inspected to make sure that it is not damaged. This examination should include the testing of each front panel control. All of the covers on the unit should be removed, and the inside of the unit checked carefully for damaged components and loose items.

With respect to damage to the equipment for which the carrier is liable, the Technical Materiel Corporation will assist in describing methods of repair and the furnishing of replacement parts.

2-2. POWER REQUIREMENT.

a. MAIN POWER. - Power consumption for the TTR-10 is given in paragraph 1-4. The TTR-10 can operate with either an a-c or d-c power input depending upon the type of power supply module (TPS()-1) used in the unit. If the TTR-10 is to be operated from a source other than that for which the power-supply is wired, the power supply module must either be modified or replaced. Modification instructions are provided in the appropriate TPS()-1 manual. Removal and replacement of the power supply module is described below.

(1) REMOVAL.

- (a) Deenergize TTR-10.
- (b) Disconnect main-power and oven-power (if used) cables from rear of TTR-10.
 - (c) Disconnect antenna from ANTENNA jack.
- (d) Disconnect W900 (at rear of TTR-10) from RCVR ANT jack J1502 (simplex hookup only).
- (e) Disconnect W901 (inside the power supply module, but accessible from the top of the TTR-10) from XMTR OUTPUT jack J1501.
- (f) Remove the four large Philips head screws on rear panel that secure power supply module to TTR-10 chassis. There are two screws on each side, located near the two handles.
- (g) Pull power supply module out of TTR-10 chassis. The handles are provided for this purpose.

(2) REPLACEMENT.

CAUTION

Power supply modules should always be inserted with no power cables attached.

- (a) Pick up power supply module by handles and plug it into TTR-10 chassis.
- (b) Secure power supply module to TTR-10 chassis using the four Philips head screws removed in step (1) (f).
- (c) Connect W901 (inside power supply module) to XMTR OUTPUT jack J1501.
- (d) For simplex operation, connect W900 (at rear of TTR-10) to RCVR ANT jack J1502.
 - (e) Connect antenna to ANTENNA jack.
- (\underline{f}) Make sure power switch is set at OFF, and connect main-power and oven-power (if used) cables.

NOTE

If the power supply module inserted was not previously in use in the TTR-10, adjust the PA OVLD circuit breaker trip point according to paragraph 5-7 c.

b. OVEN POWER. - If ovens are used in the TTRT and TTRR modules, the voltage rating of the ovens must be the same as the main power input, or an external oven supply is required. It is most important to make sure the oven supply power is correct before energizing the unit.

2-3. EQUIPMENT LOCATION.

Before installing the TTR-10, consideration must be given to its location. Two factors are important:

- a. ACCESSIBILITY. The TTR-10 should be located so that there is sufficient clearance for insertion and removal of plug-in modules (TTRR, TTRT, TTRA, and TPS()-1). Also, sufficient space for fuse replacement and accessibility to rear-panel controls is required.
- $\underline{\text{b. }}$ VENTILATION. Although the majority of TTR- $\overline{10}$ components are solid-state and do not re-

quire ventilation, the vacuum tube linear amplifier requires that air flow is not restricted immediately above or below the unit. If the air flow is restricted, serious damage to the linear amplifier might result.

2-4. ELECTRICAL INSTALLATION.

The only considerations for electrical installation are that the proper power-supply module is used (paragraph 2-2) and that external equipment is connected in accordance with paragraphs \underline{a} through \underline{k} below. Refer to figure 2-1.

a. ANTENNA. - The TTR-10 requires a 50-ohm unbalanced antenna with a coaxial-cable lead-in for simplex operation. This antenna is connected to the ANTENNA jack on the rear panel. In addition, coaxial-cable assembly W900 should be connected from jack J902 to the RCVR ANT jack J1502.

For duplex operation, two 50-ohm unbalanced antennas with coaxial-cable lead-in are required. The transmitting antenna is connected to the ANTENNA jack and the receiving antenna is connected to RCVR ANT jack J1502. Coaxial-cable assembly W900 is not used for duplex operation.

- b. AUDIO INPUT (600-OHM LINE). Terminals 1 and 3 of terminal board TB1500 are used to connect a 600-ohm input line. If the 600-ohm line is balanced, terminal 2 of TB1500 should be grounded.
- c. MICROPHONE INPUTS. Terminals 4, 5, and 6 of terminal board TB1500 are provided for various types of microphone inputs. Connect the microphone between ground and the appropriate terminal as identified by rear-panel markings (CAR, LOZ, and HIZ). Also, if a high-impedance microphone is used, a jumper must be connected between terminals 14 and 15 on the CW oscillator printed circuit board (refer to figure 5-2).
- d. PUSH-TO-TALK. Connect a push-to-talk switching device between ground and terminal 8 of TB1500.
- e. KEY LINE. Terminals 11 and 12 of terminal board TB1500 are provided for the attachment of a dry-keying device.

NOTE

An audio signal is used in the TTR-10 keying system. The keying line should be kept as short as possible, preferably under 50 feet.

f. REMOTE SIDEBAND CONTROL,

RECEIVER SECTION. - Connect a
USB/LSB switching device (SPST switch) between ground and terminal 10 of TB1501.

- g. 600-OHM AUDIO OUTPUT. Connect a 600-ohm audio load between terminals 1 and 3 of terminal block TB1501. If the load (telephone line, speaker, frequency shift converter, etc.) is balanced, ground should be connected to terminal 2.
- h. 4-OHM AUDIO OUTPUT. Remove the jumper between terminals 8 and 9 of terminal board TB1501; this disables the internal speaker. Connect a 4-ohm audio load between ground and terminal 8 of TB1501.
- i. LOW-LEVEL AUDIO OUTPUT (HEADSET OR EARPIECE MONITORING DEVICE). Connect the headset or earpiece (or other low-level monitoring device) between ground and terminal 12 of terminal board TB1500.
- j. REMOTE XMTR ON/OFF CONTROL. Connect a switching device between ground and terminal 9 of TB1500. Ground at terminal 9 energizes the high-voltage control relay in the power supply.
- k. SQUELCH ALARM. Terminals 4, 5, and 6 of TB1501 are provided for attachment of a squelch-indicating device. For an alarm indication when the receiver is squelched, make connections between terminals 4 and 5. For alarm indications when the receiver is not squelched, make connections between terminals 5 and 6.
- 1. ANTENNA TUNER. Terminals 7 through 11 of TB1502 are provided for converter to an antenna tuner. Refer to TTC-1 instruction manual and schematic diagram CK1290 for interconnection details.

2-5. PERFORMANCE CHECK.

Immediately after the TTR-10 has been installed, it should be checked for proper operation as follows.

a. RECEIVER SECTION. - The receiver section is checked by attempting to receive signals on each of the four channels; LSB and USB reception should also be checked. When signals are received, the operation of the VOLUME and SQUELCH controls should be checked.

b. TRANSMITTER SECTION. -

NOTE

For the following tests, a 50 ohm 100 watt dummy load should be connected to the ANTENNA jack.

NOTE

When performing this procedure note that only AME operation is possible in channel 1.

- (1) Select the AME, -20DB CARRIER, or SSB mode, and check voice mode operation using all possible audio inputs. The EoRF scale of the front-panel meter can be used to indicate that the signal is present at the antenna outputput. The channel used is not important in this test. Check the XMTR AF GAIN control for proper operation as indicated by a variation in the meter reading.
- (2) Repeat step (1) for each of two modes not selected in step (1) using any one of the audio inputs.
- (3) Check operation as in step (1) with an external key in both the CW and MCW modes.
- (4) Check operation as in step (1) for each of the four channels.
- (5) Connect two tone gererator (refer to table 5-1) between terminal 6 of TB1500 and ground.
- (6) Connect a-c vtvm across dummy load.
- (7) Increase output of TTR-10 until indication of 70.7 volts is obtained on vtvm.

- (8) Adjust potentiometer R1562 until indication on vtvm begins to decrease. Lock R1562.
- (9) Check the VOX circuit as follows.
- (\underline{a}) Set PTT/VOX switch at VOX.
- (\underline{b}) Turn VOX GAIN control fully counterclockwise.
- (\underline{c}) Turn ANTI-VOX control fully counterclockwise.
- (\underline{d}) Select the AME, -20DB CARRIER, or SSB mode.
- (\underline{e}) Apply the normal audio input; XMTR AF GAIN must be set for normal operation.
- (\underline{f}) Rotate the VOX GAIN control slowly clockwise. A point should be reached where a click will be heard, which is the transmit/receive relay energizing.

NOTE

Be sure to set the VOX GAIN and ANTI-VOX controls according to the applicable operating procedure given in section 3 before using the TTR-10 for transmitting.

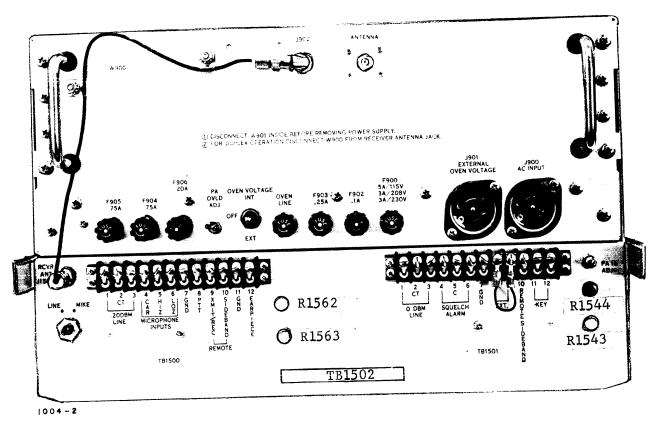


Figure 2-1. Rear Panel, TTR-10

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SECTION 3 OPERATOR'S SECTION

3-1. CONTROLS AND INDICATORS.

Before attempting to operate the TTR-10, the operator should become familiar with the controls and indicators listed in table 3-1. These are shown in figure 3-1. The type and purpose of each control is described in the table. It is important to stress that these descriptions are not operating instructions.

For Specific operating instructions, see paragraph 3-2.

NOTE

Operating instructions for the TTRR and TTRT modules are included in this section as part of the overall operating procedure for the TTR-10.

TABLE 3-1. CONTROLS AND INDICATORS

TABLE 3-1. CONTROLS AND INDICATORS			
ITEM (See fig. 3-1)	DESIGNATION	FUNCTION	
1	VOLUME control (R1515)	Controls the loudspeaker and earpiece audio output of the receiver.	
2	ANTI-VOX control (R1517)	Adjusts the anti-vox input to the transmitter from the receiver. The anti-vox circuits prevents receiver audio output from actuating the VOX circuit.	
3	PA METER switch (S1511)	Permits the front panel meter (Item 15) to indicate power amplifier tube grid r-f voltage, power amplifier tube plate current, or transmitter output r-f voltage.	
4	RCVR switch (S1503)	A two-position rotary switch that selects reception of either LSB or USB signals. When the RCVR switch is set at USB/REMOTE, either LSB or USB reception can be selected remotely.	
5	SIMPLEX/DUPLEX switch (S1506)	When set at SIMPLEX, the receiver section of the TTR-10 is disabled when the transmitter is keyed; when set at DUPLEX, the receiver can operate even though the transmitter is keyed.	
6	SQUELCH control (R1518)	Selects the r-f input level required to enable the speaker, earpiece, and antivox outputs of the receiver.	
7	POWER lamp (DS1500)	Lights when primary power is applied to the low voltage power supply.	
8	Mode switch (S1505)	Selects mode of operation of the transmitter. Operation in the CW, SSB (suppressed carrier), -20 DB (SSB with reduced carrier), AME, or MCW mode can be selected.	

Figure 3-1. Front Panel Controls and Indicators, TTR-10

005651004 3-1

TABLE 3-1. CONTROLS AND INDICATORS (CONT)

ITEM (See fig. 3-1)	DESIGNATION	FUNCTION
9	PTT/VOX switch (S1501)	Selects either voice-actuated, or pushto-talk keying of the transmitter.
10	XMTR switch (S1502)	Has no function in TTR-10A
11	XMTR AF GAIN control (R1514)	Adjusts the gain of the audio amplifier stage of the transmitter.
12	VOX-GAIN control (R1513)	Selects audio level required to key transmitter when PTT/VOX switch (Item 5) is set at VOX.
13	PA OVLD circuit breaker (CB1500)	Controls application of power to the linear-amplifier stages; removes power to these stages when power—amplifier tube plate current is excessive.
14	OFF-REC-XMIT/ NEC switch (S1500)	When set at OFF, removes power from all TTR-10 circuits except TTRR and TTRT ovens: when set at REC, turns on low voltage power supply, permits remote transmitter ON/OFF control; when set at XMIT/REC, turns on low voltage power supply and, in conjunction with PA OVLD circuit breaker (item 13), linear amplifier operating power.
15	Front panel meter (M1500)	Indicates power-amplifier tube grid r-f voltage, power amplifier tube plate current, or transmitter output r-f voltage as selected by PA METER switch (item 3).
16	HANDSET jack (J1515)	Permits connection of handset.
10	(none one on each	A screwdriver controlled trimmer
18	(none, one on each TTRT module)	capacitor that permits fine adjust- ment of transmitter output frequency.
19	RECEIVER CHANNEL switch (S1507)	Selects frequency of reception in conjunction with F1/F2 switch (item 22); when set at T, TRANS-MITTER CHANNEL switch (item 20) selects frequency of reception.

TABLE 3-1. CONTROLS AND INDICATORS (CONT)

ITEM (See fig. 3-1)	DESIGNATION	FUNCTION
20	TRANSMITTER CHAN- NEL switch (S1508)	Selects frequency of transmission also selects frequency of reception when RECEIVER CHANNEL switch (item 19) is set at T.
21	RECEIVER CLARIFIER control (one on each TTRR module)	Permits fine tuning of receiver.
22	F1/F2 switch (one on cach TTRR module)	Selects frequency of reception in conjunction with RECEIVER CHANNEL switch (item 19) or TRANSMITTER CHANNEL switch (item 20). F1 and F2 frequencies on a particular module must be within a 0.5% bandpass.
	MIKE/LINE switch (on rear of unit) (S1504)	When set at MIKE, clipper circuit of transmitter stage is operative; clipper circuit limits high modulation peaks permitting higher average output power for voice transmission.
	OVEN VOLTAGE switch (on rear of power supply module)	When set at EXTERNAL, oven heaters of TTRR and TTRT modules are connected to EXTERNAL OVEN VOLTAGE jack; when set at INTERNAL, oven heaters of TTRR and TTRT modules are connected to same primary power source as remainder of TTR-10.

3-2. OPERATING PROCEDURES.

NOTE

Almost all operating controls are protected by a control cover (see figure 1-1). To remove this cover, slide both catches up and lift off the cover. To prevent inadvertent changing of control settings, it is good practice to keep the cover on at all times except when adjusting the controls.

a. RECEIVING.

(1) TYPES OF RECEPTION. - The TTR-10 can receive AME, CW, FSK, MCW, and SSB signals and also one sideband of AM and ISB transmission. All of the above signals are received as if they were SSB transmissions. Procedures for receiving each of the signals are given in the following paragraphs.

(2) VOICE RECEPTION. - The following procedures describe the reception of voice signals that are transmitted as AME or SSB.

CONTROL

(a) Set controls at positions given below.

SETTING

RCVR switch	Sideband to be received. If the sideband to be received is not known, set at USB/RE- MOTE. If the sideband is to be selected remotely, set at USB/REMOTE.
F1/F2 switch	At appropriate position to receive incoming signal.
RECEIVER CLARIFIER control	Any

CONTROL	SETTING	CONTROL	SETTING
VOLUME control	Fully counterclockwise.	RECEIVER CHANNEL	Channel to be received unless position is desired so that
RECEIVER CHAN- NEL switch	Channel to be received unless position is desired so that the channel will be selected by the TRANSMITTER CHANNEL	switch	the channel will be selected by the TRANSMITTER CHANNEL SWITCH.
	SWITCH.	SQUELCH control	Fully clockwise.
SQUELCH control	Fully clockwise.		
•		Power switch	REC or XMIT/REC depending
Power switch	REC or XMIT/REC depending upon type of operation desired.		upon type of operation desired.
		(b) T	urn VOLUME control clockwise
(b) Turn V	OLUME control clockwise until	until comfortable	signal level is obtained.

(b) Turn VOLUME control clockwise until comfortable signal level is obtained.

NOTE

If no signal is obtained, reduce the volume and set RCVR switch at LSB. Repeat step (b).

- (c) Adjust RECEIVER CLARIFIER control for maximum voice clarity.
- (d) Adjust SQUELCH control by waiting until no signal is being received, and then turning the control slowly counterclockwise until the noise from the speaker disappears.
- (3) CW AND MCW RECEPTION. CW and MCW signals are received in exactly the same manner as voice signals (paragraph (2). For these signals, however, the RECEIVER CLARIFIER control is used to vary the pitch of the audio tone.

NOTE

In CW operation, the receiver channel frequency (F1 or F2) must be displaced slightly (300- to 3300-cps) from the transmitted signal.

- (4) FAX RECEPTION. In receiving facsimile, the setting of the RECEIVER CLARIFIER control is critical. Proceed as follows:
- (a) Turn receiver on and set controls at positions given below.

SETTING

	RCVR switch	Sideband to be received. If side-	(<u>a</u>) Tu position given belo	ırn receiv <mark>er</mark> ow.
		band to be received is not known, set at USB/REMOTE. If the sideband is to be selected remotely,	CONTROL	SE
		set at USB/REMOTE.	RCVR switch	Sideband sideband
	F1/F2 switch	At appropriate position to receive incoming signal.		known, s
	RECEIVER CLARIFIER	Any		remotely MOTE.
	control		Fl/F2 switch	At appro
	VOLUME control	Fully counterclockwise.		ceive inc

NOTE

If no signal is obtained, reduce the volume and set RCVR switch at LSB. Repeat step (b).

- (c) Connect 600-ohm line output of receiver to vertical input of an oscilloscope.
- (d) Connect an audio oscillator to horizontal input of oscilloscope.
 - (e) Set oscillator frequency at 1500 cps.
- (f) Adjust RECEIVER CLARIFIER control to obtain an unsteady, but circular (1:1) Lissajous pattern. This corresponds to the white or black areas of the picture, depending upon positive or negative reception.

NOTE

A similar pattern, corresponding to the other limit of shift of the picture, will be obtained if the oscillator frequency is set at 2300 cps.

- (5) FSK RECEPTION. In receiving frequency shift signals, the setting of the RECEIVER CLARIFIER control is critical. The procedure given below is one method of tuning the receiver for FSK reception. Most FSK converters have built-in indicating devices that allow accurate receiver tuning without the necessity for an external scope and oscillator.
- er on and set controls at

CONTROL	SETTING	
RCVR switch	Sideband to be received. If the sideband to be received is not known, set at USB/REMOTE. If the sideband is to be selected remotely, set at USB/RE-MOTE.	
Fl/F2 switch	At appropriate position to receive incoming signal.	

CONTROL

CONTROL SETTING

RECEIVER Any
CLARIFIER
control

(e) Adjust RECEIVER CLARIFIER control to obtain an intermittent, but circular (1:1) Lissajous pattern. This corresponds to a mark.

NOTE

A similar pattern can be obtained if the oscillator is set at the space frequency (generally 2975 cps).

- b. TRANSMITTING. Proceed as follows:
 - (1) Set controls as shown in table 3-2.
- (b) Connect 600-ohm line output of receiver to vertical input of an oscilloscope.
- (\underline{c}) Connect an audio oscillator to horizontal input of oscilloscope.
- (d) Set oscillator frequency at the mark frequency. This frequency is generally 2125 cps, but another is sometimes specified.

TABLE 3-2. TRANSMITTER CONTROL SETTINGS

ITEM NO. (FIG. 3-1)	PANEL DESIGNATION	POSITION
. 20	TRANSMITTER CHANNEL switch	To correspond with TTRT that includes desired operating frequency.
		·
5	SIMPLEX/DUPLEX switch	To select type of operation desired.
8	CW/SSB/-20DB CARRIER AM/MCW switch	To select mode of operation desired.
2	ANTI-VOX control	Maximum counterclockwise.
12	VOX-GAIN control	Maximum counterclockwise.
11	XMTR AF GAIN control	Maximum counterclockwise.
3	PA METER switch	Ib
13	PA OVLD circuit breaker	Down.

NOTE

If audio clipping is desired, the MIKE LINE switch on the rear of the TTR-10 should be set at MIKE. Audio clipping should not be employed for CW, MCW, FSK, or FAX transmissions.

- (2) Set OFF REC XMIT REC switch (3) at REC XMIT.
 - (3) Set PTT VOX switch (30) at PTT.

NOTE

If the microphone or other audio source does not have a push-to-talk switch, terminal 8 on TBI500 must be grounded. If this terminal has been permanently grounded, do not leave the PTT-VOX switch at its PTT position for more than a few minutes.

- (4) Depress push-to-talk switch on microphone, and supply audio signal to the transmitter. For CW or MCW operation, close telegraph key.
- (5) Adjust XMTR AF GAIN control (33) until meter (2) indicates 125 ma on peaks.
- (6) If VOX operation (voice operated excitation) is desired, set PTT/VOX switch (30) at VOX, and adjust VOX-GAIN control (34) until transmitter is turned on when audio is applied.

NOTE

If audio from the loudspeaker actuates the VOX circuit, rotate ANTI-VOX control clockwise until transmitter is unkeyed when no external audio is applied.

- (7) If remote transmitter on/off control is desired, set OFF-REC-XMIT/REC switch at REC.
- 3-3. CHANGING PLUG-IN MODULES.
 - a. CHANGING TTRR AND TTRT MODULES

NOTE

When a change in a TTRT module results in a change in the frequency band, the corresponding TTRA module must also be changed (refer to paragraph b).

CAUTION

Be sure to deenergize the unit before changing TTRT modules.

Serious damage to the modules can result if the unit is not deenergized.

- (1) Deenergize TTR-10.
- (2) Loosen snapslides located on top and bottom of module to release module (snapslides on TTRR slide to left; snapslides on TTRT slide to right).
- (3) Pull module out of unit. A knob is provided in the center of the module for this purpose.

CAUTION

Before continuing, be sure that the voltage rating of the crystal oven (if used) in the module to be inserted is the same as the voltage rating for the crystal oven in the module just removed.

- (4) Insert new module.
- (5) Secure snapslides to lock module in place.
- (b). CHANGING TTRA MODULES. Each time a TTRT module is changed in one of the channels of the transmitter section, the TTRA module for that channel must also be changed unless the new TTRT module covers the same frequency band as the TTRT module it replaces. If the frequency band covered changes, a different model of TTRA module must be selected.

NOTE

In any case, the linear amplifier of the transmitter section must be aligned for the new frequency according to paragraph 5-7 c.

The following are the bands covered by each model of TTRA module.

TTRA-1: Band 1 (2-4 mc)

TTRA-2: Band 2 (4-8 mc)

TTRA-3: Band 3 (8-16 mc)

TTRA-4: Band 4 (16-32 mc)

To change a TTRA module, refer to figure 5-4 and proceed as follows:

(1) Deenergize the TTR-10.

WARNING

Dangerously high voltage is present near the TTRA modules whenever the transmitter section is energized. Be sure to

- deenergize the unit and use a grounding stick before proceeding.
- (2) Lift module out of unit using the two knurled knobs on module for handles.
- (3) Carefully insert new module.
- (4) Align linear amplifier in transmitter section for new TTRA module according to paragraph 5-7c.

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SECTION 4 PRINCIPLES OF OPERATION

4-1. GENERAL.

The TTR-10 comprises 5 major assemblies: main chassis assembly, linear amplifier, receiver converter module (TTRR), transmitter converter (TTRT), and power supply (TPS()-1). Circuit analysis given in this section for the TTRR, TTRT, and TPS()-1 modules is limited to inputs, outputs, and generalized information. Detailed circuit analysis for any of these units can be found in the appropriate TTRR, TTRT, or TPS()-1 manual.

4-2. RECEIVER SECTION THEORY (SEE FIGURES 4-1 AND 7-1).

a. INPUT CIRCUITS. - The rf input to the receiver section is supplied through RCVR ANT jack J1502 to the wiper of RECEIVER CHANNEL selector switch S1507. In duplex operation, this switch is used to connect the rf input to one of four TTRR plug-in rf modules, each of which is fixed-tuned to a different frequency. Thus, the TTR-10 can receive signals on any one of four frequencies (determined by the TTRR modules) as selected by S1507. Additional sections of S1507 provide operating voltages and a delayed agc voltage to the selected TTRR module.

In simplex operation, S1507 is set at T, so that the rf input is supplied to the wiper of TRANSMITTER CHANNEL selector switch S1508, which is part of the transmitter section also. Now, the TTRR module is selected by S1508. Because S1508 also selects the rf module in the transmitter section, both the transmitter and receiver frequencies are selected simultaneously. Additional sections of S1508 provide the operating voltages and the delayed agc voltage.

The operating voltages for the TTRR modules are +12 V REC and -12 V REC. These voltages originate in the transmitter section. (See paragraph 4-3).

b. TTRR PLUG-IN MODULES. - Each of the TTRR modules contains three rf amplifiers, a mixer and a local oscillator. The module amplifies the selected rf signal and converts it to the first i-f frequency. Figure 4-2 shows the input and the output of a TTRR module. Both sidebands are shown although only one might be received in actual practice. The bandwidth of the rf amplifiers is sufficient to pass both sidebands of a received signal (if both are present). The local oscillator is tuned 1.75 mc above the carrier frequency of the received signal. Thus, the spectrum of the received frequencies is inverted (the highest frequencies in the sideband(s) produce the lowest difference frequency) as shown in the illustration. The carrier frequency of the i-f output from a TTRR module is 1.75 mc.

c. I-F AND MIXER STAGES. - I-f amplifier Q1601 receives an i-f signal from one of the four TTRR modules as selected by either S1507 or S1508, amplifies it, and supplies the signal to mixer Q1602. The mixer is also supplied with the output of either the LSB oscillator (1.5 mc) or the USB oscillator (2.00 mc) depending upon the setting of the RCVR switch. Figure 4-2 shows the input and the two possible outputs of the mixer. If the LSB oscillator output is supplied to the mixer (250 kc below the carrier frequency of the i-f signal), the frequency spectrum of the input signal is not inverted. If the USB oscillator output is supplied to the mixer (250 kc above the carrier frequency of the i-f signal), the frequency spectrum of the input signal is inverted. Because the crystal filter passes only a band of frequencies above 250 kc, the selection of the desired sideband depends upon which oscillator output is supplied to the mixer.

LSB oscillator Q1607 and USB oscillator Q1608 are modified Colpitts oscillators. The LSB oscillator is tuned to exactly 1.5 mc by C1629. The USB oscillator is tuned to exactly 2.0 mc by C1631. The output of each oscillator is taken from its base. The position of receiver sideband relay K1501 determines which of the two oscillators supplies the mixer. If RCVR switch S1503 is at LSB, relay K1501 is energized, and +12 V CONT is applied across LSB ADJ R1543. The positive voltage supplied by R1543 to the emitter of Q1607 forward biases Q1607. The USB oscillator transistor is not forward biased and is cutoff. The magnitude of the emitter voltage determines the magnitude of the oscillator output; maximum output occurs when the oscillator is biased at its maximum gain point. When S1503 is at USB/ REMOTE, and no remote sideband input (from TB1501) is present, K1501 is deenergized and +12 V CONT is applied across USB ADJ R1544. Thus, Q1608 is forward biased and the LSB oscillator is cutoff. If ground is supplied as a remote sideband input, K1501 is energized, and the LSB oscillator is activated. This is how the desired sideband is selected remotely.

The output of the selected oscillator is supplied to mixer Q1602 through buffer amplifier Q1609, which minimizes the loading of the oscillator. The output of this mixer, the second intermediate frequency, is supplied to crystal bandpass filter FL1601. This is a highly selective fi'ter with a bandpass of 2.75 kc, which rejects frequencies below 250.25 kc and above 253.0 kc. Thus, only the sideband whose frequency range is above 250 kc will be passed by the filter, while all noise and signal frequencies outside of the selected sideband are eliminated. The output of the filter is supplied to two stages: detector CR1601-CR1604 and i-f amplifier Q1610 in the

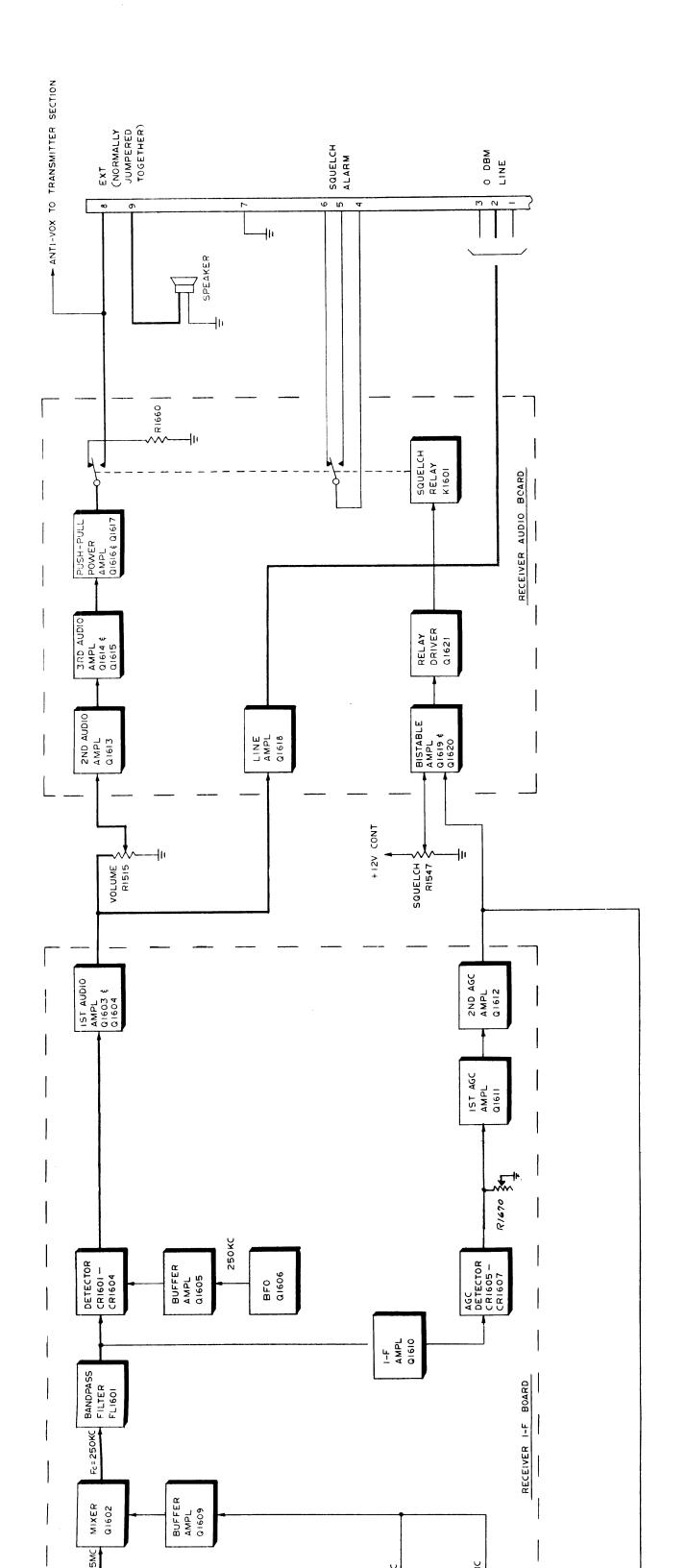
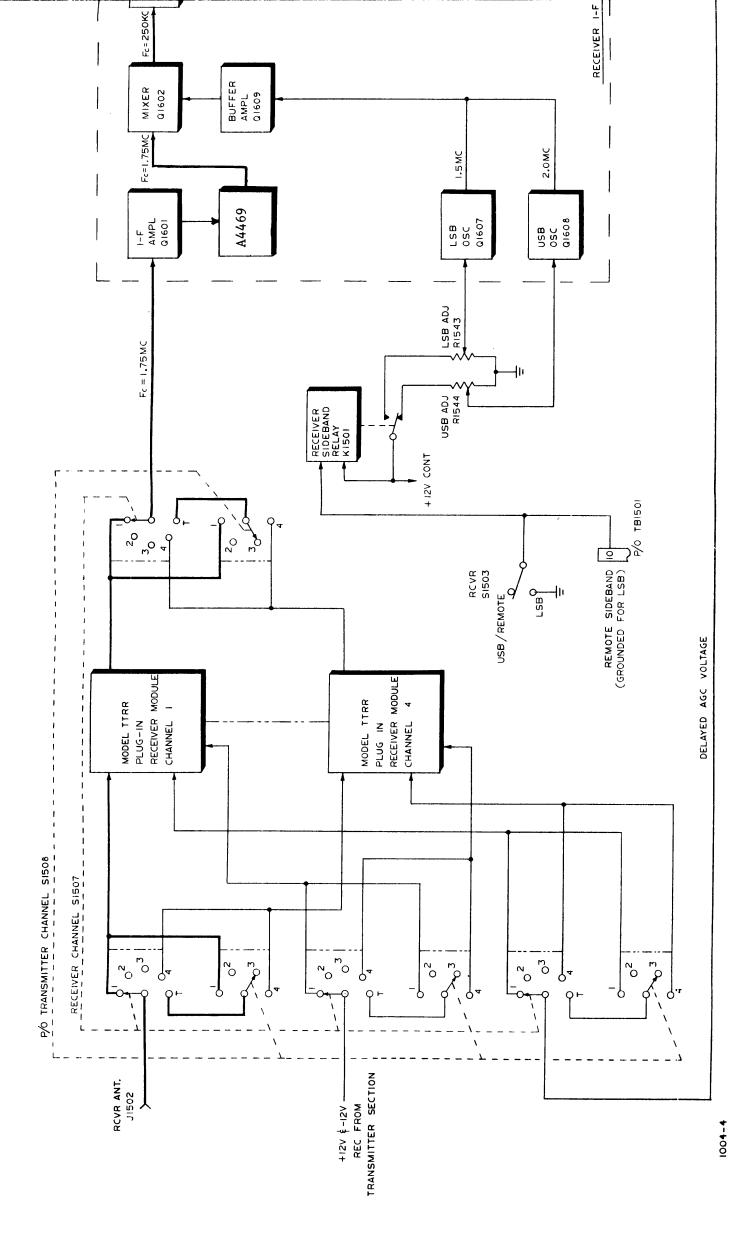


Figure 4-1. TTR-10 Receiver Section, Block Diagram



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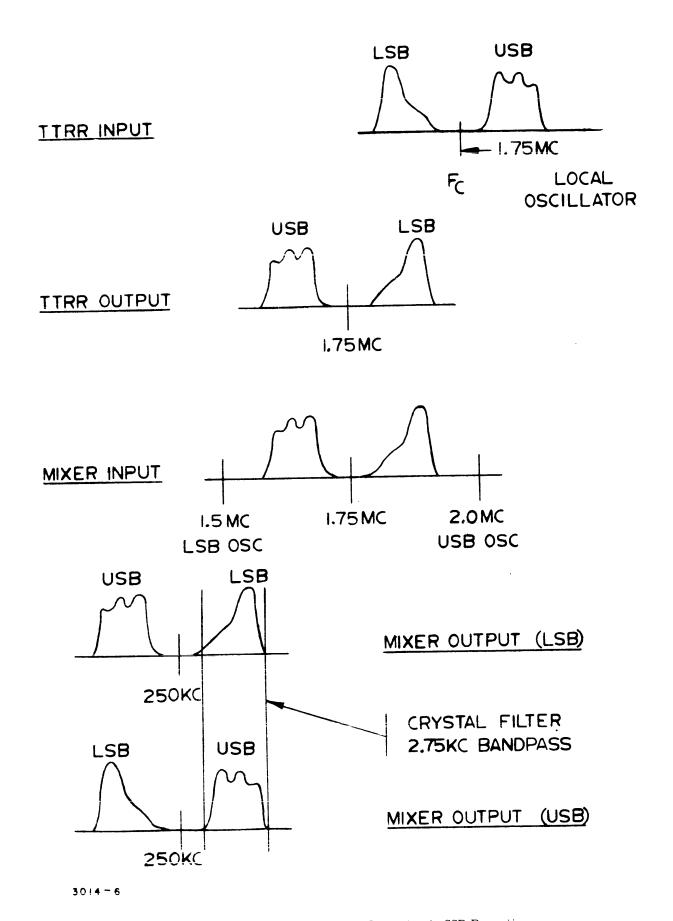


Figure 4-2. Frequency Inversion in SSB Reception

d. DETECTOR AND BFO. - The detector, CR1601 through CR1604, receives the selected sideband and the output of bfo (250 kc). The i-f signal and the bfo output beat together in the detector to derive the audio information from the i-f signal.

Bfo Q1606 (figure 7-1 sheet 2) is a modified Colpitts oscillator whose frequency is 250 kc. Its output is supplied through buffer amplifier Q1605 to potentiometer R1663. R1663 is adjusted so that the bfo signal is self-cancelling at the balanced output of the detector.

The bfo signal controls the switching of the diode network. For positive half-cycles of the bfo signal, CR1601 and CR1604 are forward biased and CR1602 and CR1603 are reverse biased. For negative half-cycles of the bfo signal, CR1601 and CR1604 are reverse biased and CR1602 and CR1603 are forward biased. The balanced i-f signal from FL1601 is supplied to the detector through C1610 and C1611. The amplitude of the i-f signal is small compared to the bfo signal so that the bfo signal so that the bfo signal does not lose control of the diode switching.

Figure 4-3 shows idealized waveforms for the detector. For this illustration, the i-f signal is a constant frequency in the passband of the filter. Assume that the output shown is taken across R1608 and the i-f input is applied at the anode of CR1601 and the cathode of CR1603. When the i-f and bfo signals are in phase (between T1 and T2), CR1601 is at maximum conduction and voltage across R1608 is at its maximum positive value. As the i-f signal begins to lead the bfo signal (between T2 and T7), CR1601 conducts less and CR1602 begins to conduct more. When the i-f and bfo signal are 180° out of phase (between T7 and T8), CR1602 is at its maximum conduction, and voltage across R1608 is at its maximum negative value. As the bfo signal begins to lead the i-f signal (between T8 and T14), CR1602 conducts less and CR1601 begins to conduct more. Between T14 and T15, the i-f and bfo signals are again in phase.

Since the i-f signal at the anode of CR1604 is $180^{\rm o}$ out of phase with the i-f signal at the anode of CR1601, the output across R1609 will always be a mirror image of the output across R1608.

Capacitors C1613 and C1614 remove the i-f and any residual bfo components from the detector output. The output of the detector is supplied to the first audio amplifier.

e. AUDIO AMPLIFIERS. - First audio amplifier Q1603 and Q1604 converts the balanced input from the detector to a single-ended signal, and amplifies it. This signal is developed across VOLUME control R1515, and is also supplied to line amplifier Q1618. The line amplifier supplies the balanced 600-ohm line output. The signal level determined by the setting of the VOLUME control is further amplified by second audio amplifier Q1613, third audio amplifier Q1614 and Q1615, and push-pull audio power amplifier Q1616 and Q1617. The third audio amplifier is a differential

amplifier that converts the single-ended signal to a balanced signal for the push-pull amplifier. The output of the push-pull amplifier is supplied through a contact of squelch relay K1601 (when K1601 is energized) to terminal 9 of TB1501 and to the transmitter section as anti-vox input. Terminals 8 and 9 of TB1501 are normally jumpered together so that the speaker of the TTR-10 is connected. If an external speaker is used, the jumper is removed and the speaker is connected between terminals 9 and 7 of TB1501. The anti-vox output is used in the transmitter section to prevent the speaker output from keying the transmitter.

f. AGC AND SQUELCH CIRCUITS. - I-f amplifier Q1610 amplifies the output of crystal filter FL1601. Agc detector CR1605-CR1609 produces a delayed dc agc voltage, which is supplied through first and second agc amplifiers Q1611 and Q1612 to the TTRR module and to the squelch circuit.

Bistable amplifier Q1619 and Q1620 controls relay driver Q1621, which controls squelch relay K1601. When a signal is being received, the bistable amplifier is held in its unsquelched state by the agc voltage and the relay driver is on. When the signal level decreases, the agc voltage drops. At a point selected by SQUELCH control R1547, the bistable amplifier changes to its squelched state and the relay driver turns off.

When the relay driver is on, K1601 is energized, and the output of the audio power amplifier is connected to the speaker terminal and anti-vox circuit. When the relay driver is off, K1601 is deenergized, and the output of the audio-power amplifier is disconnected from the speaker terminal and anti-vox circuit, and is connected instead to dummy load R1660. Thus, the receiver output is muted when a received signal is not present and only noise is being generated by the receiver. The other set of contacts of K1601 can be used to provide squelched and non-squelched indications for external alarm circuitry.

g. POWER SUPPLY. - The operating voltages for the receiver section of the TTR-10 are provided by a power supply module, which also supplies operating voltages for the transmitter section. Operating voltages for the receiver section are +12 V and -12 V. The TTRR modules operate with +12 V REC and -12 V REC. These voltages are always present in duplex operation, but are only present in simplex operation when the transmitter is not keyed. The receiver i-f board is also supplied with the same voltages. The receiver audio board is supplied with +12 V CONT and -12 V CONT, which are present continuously whenever TTR-10 is energized.

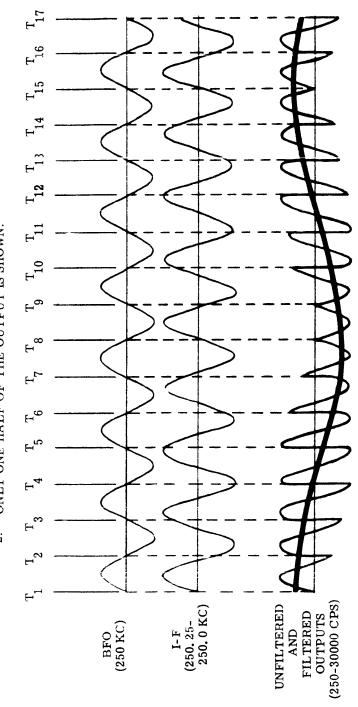
4-3. TRANSMITTER SECTION THEORY (SEE FIGURES 4-4 AND 7-1)

a. GENERAL. - The TTR-10 transmitter is a

Figure 4-3. Demodulator, Idealized Forms



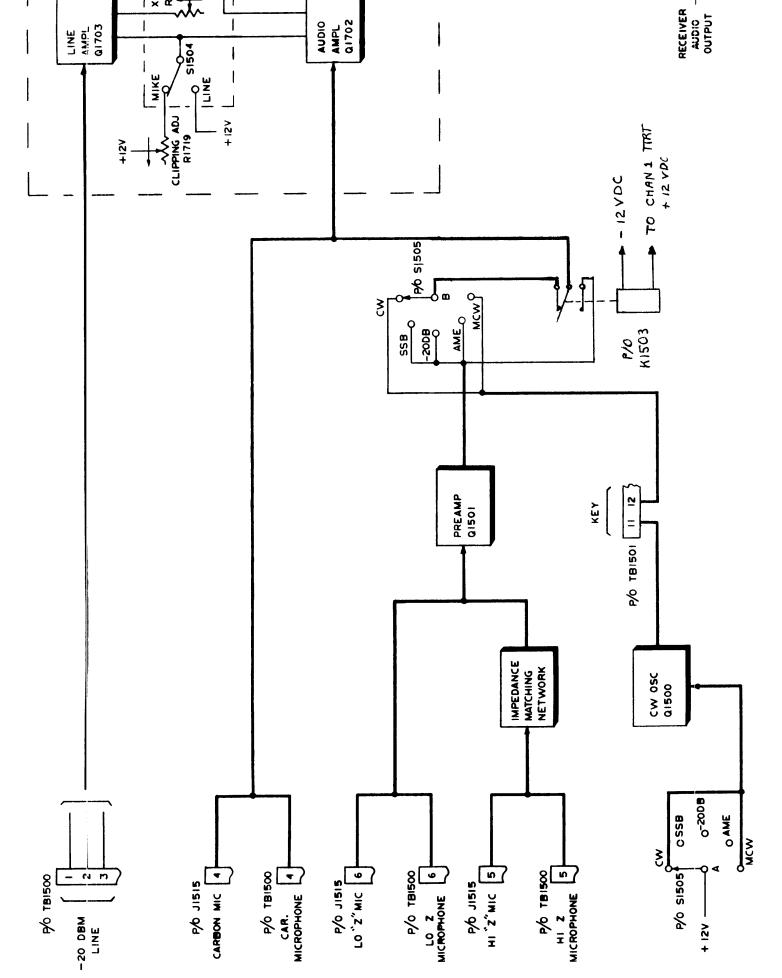
- 1. THE I-F SIGNAL HAS BEEN ENLARGED FOR CLARITY.
- 2. ONLY ONE HALF OF THE OUTPUT IS SHOWN.



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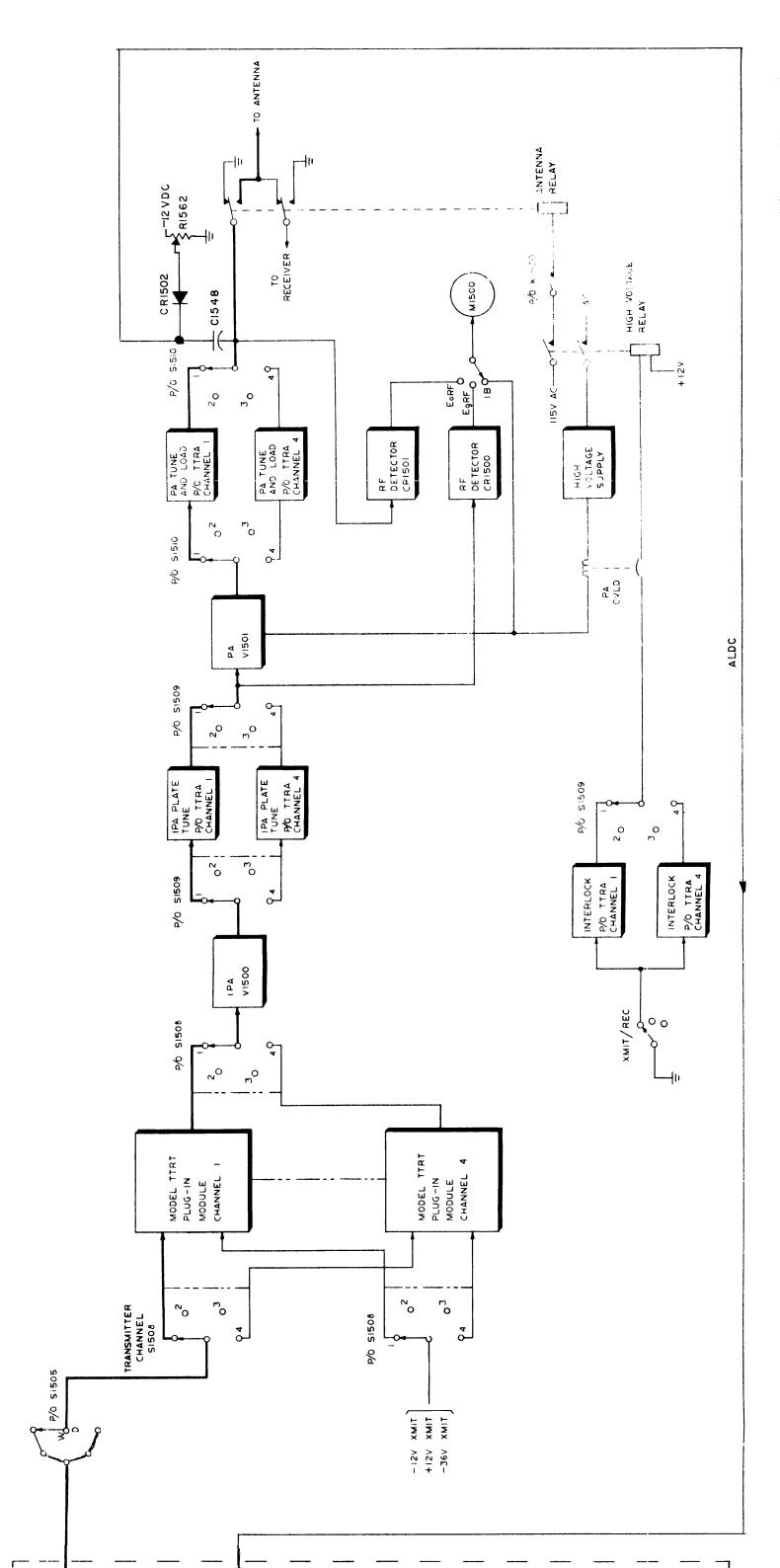
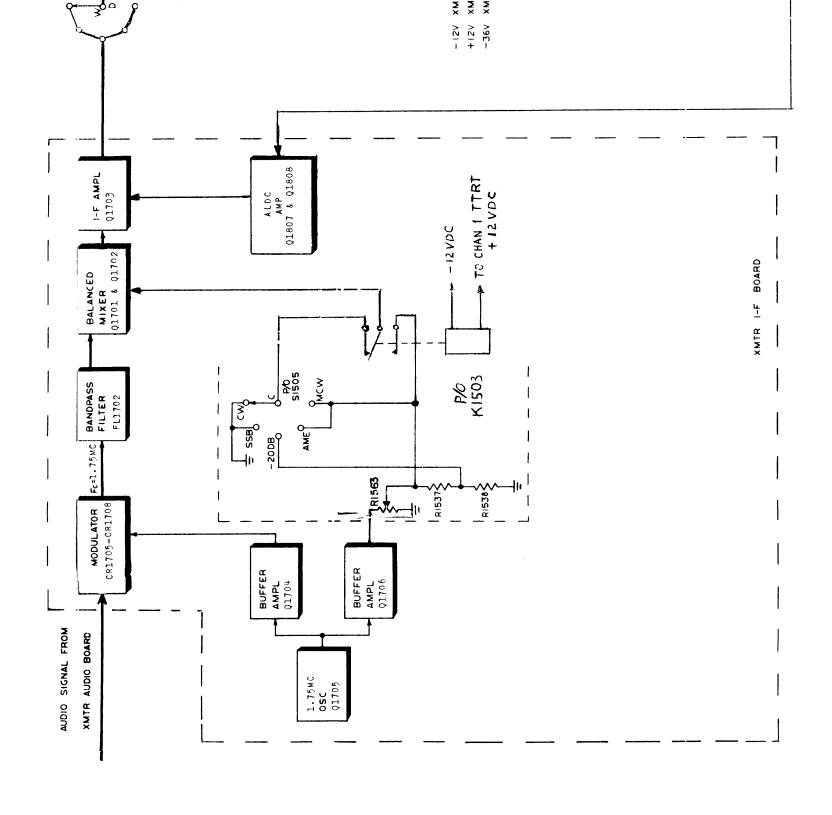


Figure 4-4. TTR-10 Transmitter Section, Block Diagram (Sheet 2 of 2)



single sideband instrument, and is designed to transmit AME, CW, FAX, FSK, MCW and SSB.

The transmitter section consists of a completely transistorized superheterodyne exciter and a vacuum-tube linear amplifier. It also includes four model TTRA amplifier tuning modules for switch selected tuning of the linear amplifier in paragraphs \underline{b} through \underline{g} , the linear amplifier in paragraph \underline{h} , the TTRA modules in \underline{i} , the power supply and overload protection circuits in \underline{j} , and antenna switching for simplex and duplex operation in \underline{k} . A meter circuit for tuning the linear amplifier is described in paragraph 1.

b. INPUT CIRCUITS. - The audio signal for the exciter can be provided from any one of the following sources: carbon microphone, low-impelance microphone, high-impedance microphone, 600-chm line, or internal CW oscillator. Any of the microphones can be wired to TB1502 or be incorporated in a handset plugged into J1515.

The carbon microphone and 600-ohm line inputs are supplied directly to the audio stages. The low-impedance and high-impedance microphone inputs are supplied to preamplifier Q1501. In the SSB, -20DB, AM, and AME modes of operation, the amplified output of Q1501 is supplied to the audio stages by one of two means: (1) through section B of S1505 and on set of de-energized contacts of relay K1503 for transmit channels 2,3, and 4; (2) through one set of energized contact of relay K1503 for transmit channel 1. The audio tone of CW and MCW is supplied by CW oscillator Q1500, a phase-shift oscillator energized in the CW and MCW modes by +12 V CONT from section A of S1505. The ouput of the CW oscillator is supplied through an external key (connected to TB1501) and section B of S1505 in the CW and MCW modes to the audio stages.

2. AUDIO STAGE. - Transistors 01702 and 01703 are connected as a push-pull amplifier and phase inverter whose gain is determined by the setting of XMTR AF GAIN control R1514. The output to this stage can be supplied to either transistor as shown. LINE/MIKE switch S1504 permits the insertion of a compression circuit, described below, that prevents abnormally high inputs from overmodulating the exciter. By flattening the sharp peaks of the input signal, the compression circuit permits increasing the average sideband power generated. The output of the differential amplifier is supplied to the modulator and to the VOX stages.

With S1504 set at LINE, +12 V CONT is supplied directly to the emitter resistor of both transistors 01702 and 01703. The emitter resistors establish an operating point that is in the cen-

ter of the transfer curve for each transistor. Thus, provided the input signal does not overdrive the stage, the amplifiecation of the stage is linear. With S1504 set at MIKE, +12V CONT is supplied through CLIPPING ADJ R1719 to the emitter resistors of both transistors. The additional resistance shifts each operating point down the transfer curve towards the cutoff region. The amount that the operating point is shifted is determined by the clipping adjustment. The operating point is selected so that abnormally high input amplitudes and voice peaks drive the transistors into the nonlinear amplification region. As a result, these signals are compressed. The amount of compression is determined by the setting of the clipping adjustment.

d. VOX AND ANTI-VOX STAGES.— The vox stages permit input-controlled operation of the transmitter by energizing the exciter output stages only when an audio input is present. The antivox stages prevent the receiver section output from keying the exciter if the output of the speaker is picked up by a microphone connected to the exciter.

The outut of the audio stages is supplied to vox detector CR1704 through VOX GAIN control R1513, emitter follower Q1704, and vox amplifier Q1705. The vox detector produces a positive dc voltage that is proportional to the magnitude of the vox signal. In the CW and MCW modes, the oscillator signal produces the dc voltage. When a microphone is used, however, the dc voltage can be produced either by the signal intended for transmission, or by the output of the receiver speaker unintentionally picked up by the microphone.

To prevent the output of the speaker from keying the exciter, the output of the receiver section is upplied to the transmitter section as an anti-vox input. This signal is supplied to anti-vox detector CR1701 through ANTI-VOX control R1517, and anti-vox amplifier Q1701; the anti-vox signal can be monitored by phones connected to either J1515 or TB1500. The anti-vox detector produces a negative voltage that is proportional to the magnitude of the anti-vox signal.

The outputs of the vox and anti-vox detectors are added algebraically at the input to emitter follower Q1706. When the vox detector produces an output (positive) with so anti-vox present the output of the emitter follower is positive. When, however, the vox signal result from pick up from the speaker, and a negative anti-vox voltage is also present, the algebraic sum of the two results in a slightly negative output from the emitter follower.

When VOX/PTT switch S1501 is set at VOX, the output of the emitter follower is supplied through de amplifier 01707 to relay driver 01708, which controls transmit/receive relay K1500. When the output of the emitter follower is negative, K1500 is deenergized, +12 V XMIT, -12 V XMIT and -36 V XMIT voltages are disconnected from the exciter i-f and r-f stages, power amplifier tube V1501 is cut off, and +12 V REC and -12 V REC

voltages are connected to the receiver r-f and i-f stages. When the output of the emitter follower goes positive, K1500 is energized, +12V XMIT, -12 V XMIT, and -36 V XMIT voltages are connected to the exciter i-f and r-f stages, V1501 is normally biased, and +12 V REC and -12V REC voltages are disconnected from the receiver r-f and i-f stages.

NOTE

If SIMPLEX/DUPLEX switch S1506 is set at DUPLEX, the +12V REC and -12V REC voltages are continuously applied to the receiver section.

In operation, the VOX GAIN control is adjusted so that the normal microphone output; or the output of the CW oscillator, is sufficient to energize the transmit/receive relay. The ANTI-VOX control is then adjusted to prevent loudspeaker to microphone feedback from K1500.

e. MODULATOR AND 1.75 MC OSCILLATOR. - The balanced audio output from the transmit audio board is extended to the diode balanced modulator (comprisingCR1705 through CR1708) of the transmit i-f board. The output of the diode balanced modulator is; connected—to both sides of balance potentiometer R1716 where the 1.75mc signal is mixed with the audio frequency.

Transistor Q1705 is configured as a modified pierce oscillator producing a 1.75 mc signal that is mixed with the incoming audio frequency.

The output at the collector of Q1705 is capacitively coupled to Buffer amplifiers Q1704 and Q1706. The amplified output at the emitter of Q1704 is capacitively coupled to the wiper of balance potentiometer R1716. The amplified output at the emitter of Q1706 is extended via CARRIER INSERT control R1563 and contacts of switch S1505 to the base of i-f amplifier Q1701. The USB output from the balanced modulator is extended through sideband filter FL1702 and crystal notch filter Y1702 to the bases of transistors Q1701 and Q1702.

f. I-F AMPLIFICATION AND ALDC. - The USB signal (1.75 mc) from filter FL1702 is extended to the input bases of push-pull amplifiers Q1701 and Q1702. Also applied to the base is output from the carrier insertion control which allows the operator to select the desired carrier level. The amplified output at the collectors of Q1701 and Q1702 is transformer coupled to the base of ALDC controled amplifier Q1703.

ALDC voltage developed at the transmitter is extended via potentiometer R1562 to amplifiers 01807 and Q1808. The amplified output at the collector of Q1808 provides the emitter bias voltage for Q1703. Any increase in ALDC is accompanied with a change in emitter bias thus reducing the output of Q1703.

The amplified output at the collector of Q1703 is transformer coupled through section D of S1505 $\,$

and through TRANSMITTER CHANNEL selector switch S1508 to the selected TTRT module. In the CW, SSB, and -20DB modes, the signal is coupled directly through S1505. When TRANSMITTER CHANNEL switch S1508 is set at 1 (i.e. channel 1 operation), relay K1503 is energized, contacts of switch S1505 are bypassed, and only AME mode of transmission is possible.

g. TTRT PLUG-IN MODULES. - The i-f signal from S1505 is supplied to one of four TTRT modules through S1508 depending upon the channel selected. In addition, the selected module is energized by -12 V XMIT, +12 V XMIT and -36 V XMIT through other sections of S1508 and contacts of relay K1500. Each TTRT module is fixed-tuned to a preselected frequency, and contains a crystal controlled local oscillator, a balanced mixer, and three r-f amplifiers; the module converts the i-f input to an r-f signal and amplifies it. Thus, the TRANSMITTER CHANNEL selector switch enables an operator to select any one of four transmission frequencies.

Figure 4-5 shows the input and output of a TTRT module. In each case, the local oscillator in the module is tuned 1.75 mc above the carrier of the desired transmission frequency. Thus, the frequency spectrum of the i-f signal input is inverted as shown in the illustration. The bandpass of the r-f amplifiers in the TTRT modules is sufficient to pass either the upper or lower sideband.

The output of the selected TTRT module is supplied through S1508 to intermediate power amplifier V1500 in the linear amplifier.

h. LINEAR AMPLIFIER. - The linear amplifier consists of two power-amplifier stages, switch-selected tuning networks, and overload protection circuits. The linear amplifier produces an output of 100 watts maximum peak envelope power from an input of 250 milliwatts.

The r-f signal from S1508 is supplied to class AB1 intermediate power amplifier V1500. The tuned circuit for the plate is located in the TTRA module selected by TRANSMITTER CHANNEL selector switch S1500. Each of the four TTRA modules installed in the TTR-10A corresponds with one of the four TTRT module frequencies. The output of the selected TTRA module is supplied through S1508 to class AB2 power amplifier V1501. The control grid bias for V1501 is determined by the condition of the transmit-receive relay. When the transmitter is not keyed, the relay is deenergized, and -105 volts is applied to the grid to keep the tube completely cut off. When the transmitter is keyed, the relay is energized, and a voltage determined by the setting of PACb ADJ R1500 provides part of the class-AB2 bias. In addition, the TTRA contains the pi network for V1501 plate tuning and matching to the transmission line. The output of the selected TTRA module is supplied to XMTR OUTPUT jack J1501.

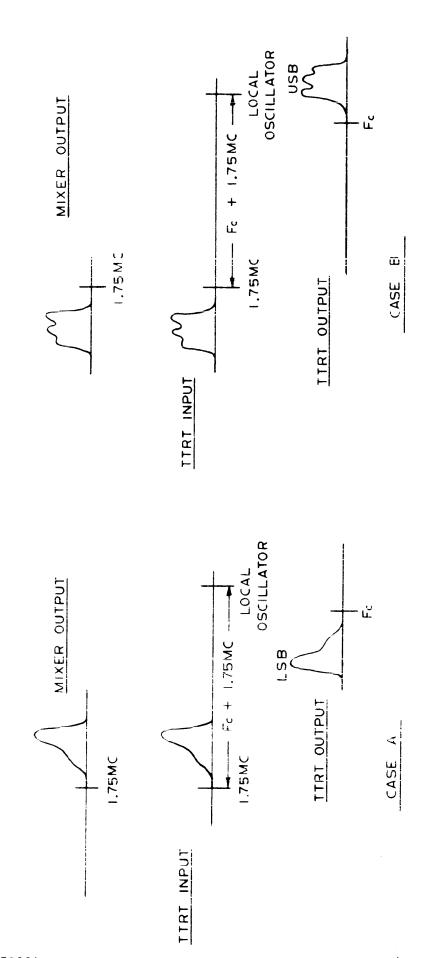


Figure 4-5. Frequency Inversion in SSB Transmission

The power amplifier is protected from overload by a circuit that automatically interrupts the high voltage supply if overload occurs. See paragraph $\underline{\mathbf{j}}$. In addition, a front panel meter can indicate various parameters of the power output stage. See paragraph $\underline{\mathbf{l}}$.

A sample of the high level r-f output of V150: is rectified and applied to an automatic load and drive control (ALDC) circuit in the transmitter i-f board (see schematic CK1290). A control voltage is applied to the transmitter i-f board whenever any pre-set r-f signal level (determined by settings of R1562) is exceeded. This control circuit limits high driver peaks (which can be developed during signal transmission) thus suppressing unwanted distortion.

A rectified sample of the high level r-f output, applied to pin 13 (see CK1285) undergoes two stages of amplification by Transistors Q1807 and Q1808. The output at the collector of Q1808 is applied to the emitter of Q1703 therefore controlling the output of the transmitter i-f board.

Figure 4-7 is a simplified schematic of the linear amplifier. It shows the plate tuning circuits for the intermediate power amplifier and the pi output network for the power amplifier which are in the TTRA module selected by TRANS-MITTER CHANNEL selector switch S1508; the tuned circuits are peaked for the frequency of the TTRT module output and the antenna loading. Filtering, biasing, and overload protection circuits are also shown.

j. TTRA MODULES. - There are four models of the TTRA module that may be used in the TTR-10A. Each is designed to cover particular frequency range as follows:

TTRA-1 (Figure 7-2): 2-4mc

TTRA-2 (Figure 7-3): 4-8mc

TTRA-3 (Figure 7-4): 8-16mc

TTRA-4 (Figure 7-5): 16-32mc

The model of TTRA module used depends upon the model of TTRT module used. The TTRA model is swim ted to cover the frequency range of the TTRT which is used.

Each TTRA module contains two basic circuits; a plate-tuning circuit for the intermediate power-amplifier circuit for the power amplifier, and a load tuning circuit. The tuning of the IPA circuit is variable over the entire frequency range of the module. Coarse tuning and loading of the PA circuits is accomplished by two switches that divide the frequency range of the module incommerce frequency bands; the switches select the tuning components. Fine tuning is then accomplished by means of variable capacitors. Thus, to tune and load the power amplifier, the PA TCAL switch and PA LOAD switch must be positioned to select the narrow band that includes the specified operating frequency of the TTRT

module for the selected channel, and then the TTRA module must be fine tuned and loaded at the specified frequency.

Each TTRA module is interlocked to prevent operation of the linear amplifier if the module is removed (paragraph \underline{k}).

j. POWER SUPPLY AND OVERLOAD PROTECTION. The power supply used in the TTR-10 is a plug-in module that can be any one of several types and is described in a separate book. However, the power supply is described here to the extend required for understanding the operation of the overload and interlock circuitry.

The power-supply module contains a low-voltage supply and a high-voltage supply. The low voltage outputs (+12 V, -12 V, and -36 V) are provided whenever power switch S1500 is set at either REC or XMIT/REC. The low voltage outputs are used in both the receiver section and in the exciter of the transmitter section.

The high-voltage power supply is energized only when power switch S1500 is set at XMIT/REC; other conditions described further on must also be met. The high-voltage outputs are +800, +400, +315 and -105 volts; these are the supply and bias voltages for the linear amplifier.

The ac supply for the high-voltage supply is connected through normally open contacts of a high-voltage relay. This relay is energized by +12 V whenever the ground return is completed through the power switch, PA OVLD circuit breaker CB1500, and the interlock in the selected TTRA module, and is interrupted whenever the breaker is tripped or the TTRA module for the selected channel is not in place; the circuit breaker trips whenever excessive plate current is drawn by V1501.

ANTENNA SWITCHING .- The power-supply module also contains an antenna relay that provides switching of the receiver input and transmitter output for operation with one antenna (simplex operation). The untenna relay is energized through normally open contacts of the highvoltage relay and (ransmit/redeive relay connected in series. Thus, the antenna relay is deenergized except when the transmitter is keyed and the high-vortage relay is energized. When the TTRR-10A is wired for simplex operation and the antenna relay is deenergized, RCVR ANT jack J1502 is connected to the ANIENNA jack; the output of the transmitter through XMTR OUTPUT jack J1501 is grounded. When the antenna relay is energized, XMTR OUTPUT jack J1501 is connected to the AN TENNA jack and the input to the receiver section through RCVR ANT. juck 31502 to grounded.

In duplex operation, the interconnection be tween the RGVR ANT. jack is removed so that the receiver input does not pass through the antenna relay. The transmitter connections are not changed so that the transmitter output to the ANTENNA jack is still switched by the antenna celay.

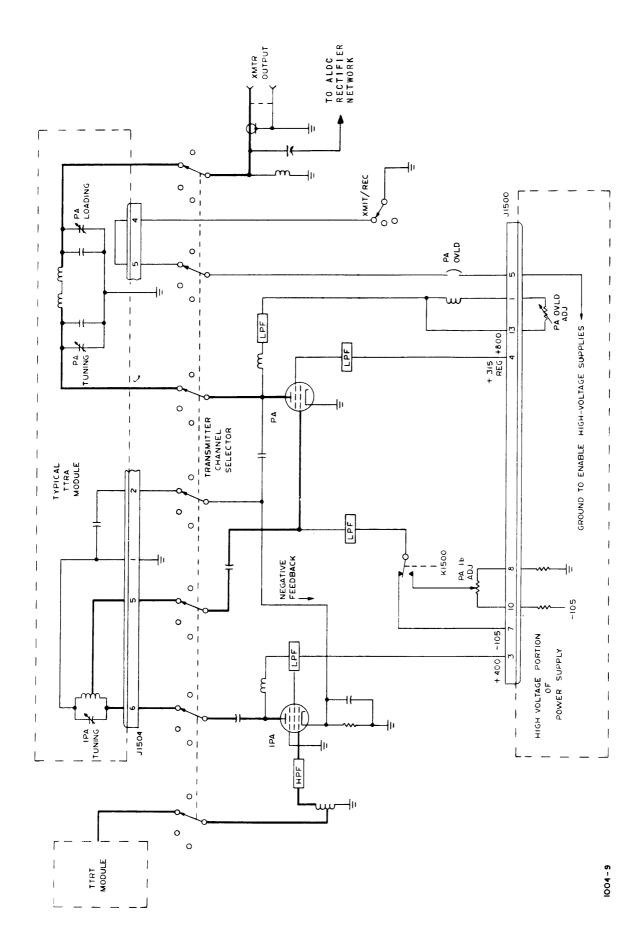


Figure 4-7. Linear Amplifier, Simplified Schematic

1. METER CIRCUIT. - PA METER switch S1511 can select any one of three power-amplifier parameters for indication on the front-panel meter. With the switch at Ib the plate current of the power amplifier is measured. With the switch at EgRF a portion of the r-f signal input to the power amplifier is rectified by r-f detector CR1500 and is indicated on the meter. With the switch at EgRF, a portion of the r-f signal output at the antenna is rectified by r-f detector CR1501 and is indicated by the meter.

SECTION 5 MAINTENANCE

5-1. GENERAL.

As mentioned before, the TTR-10 comprises five major sections. Troubleshooting and repair procedures given in this section are limited to the main chassis assembly and to the linear amplifier (TTRA). For troubleshooting and repair information concerning the receiver converter (TTRR) transmitter converter (TTRT), and power supply (TPS()-1), referred to the appropriate TTRR, TTRT or TPS()-1 manual. Refer to figures 5-2 through 5-9 at the end of this section for aid in locating components.

5-2. TEST EQUIPMENT REQUIRED.

Test equipment required for procedures given in this section are listed in Table 5-1.

5-3. PREVENTIVE MAINTENANCE.

Preventive maintenance of the TTR-10 consists of routine visual inspection and cleaning. Cleaning is necessary because dust may accumulate on certain components and not only reduce the efficiency of the

TTR-10, but also increase component wear. Either a vacuum cleaner or a compressed air hose is the quickest and most effective method of cleaning the unit.

Visually checking the unit when it is opened for cleaning can prevent downtime due to component failure. Often a deteriorating component will look bad before it actually affects the operation of the unit. Some indications of trouble are: discolored components, dirty or pitted switch and relay contacts, warped printed circuit boards, and damaged wiring. Any components found in this condition should be replaced. In addition, all hardware should be checked for tightness.

5-4. RECEIVER SECTION TROUBLE-SHOOTING.

a. QUICK TESTS USING FRONT PANEL CONTROLS.

- Try to receive signals on all four frequencies selected by RECEIVER CHANNEL switch. If reception is possible on some but not all of the channels, the TTRR module for the channel on which reception is not possible is defec-

TABLE 5-1. TEST EQUIPMENT REQUIRED.

ITEM	FUNCTION
600 ohm $1/2$ watt resistor.	Used in receiver section trouble- shooting and alignment.
R-f signal generator, Hewlett Packard Model 606A, or equivalent.	
50-ohm, 100 watt dummy load with low-level monitor facility	Used in transmitter section trouble- shooting and alignment.
A-f signal generator, General Radio Model 1304B, or equivalent.	
Vacuum tube voltmeter, Hewlett Packard Model 410B, or equivalent.	Used in transmitter section and receiver section troubleshooting and alignment.
Oscilloscope, Tektronix Type 545, or equivalent.	
Frequency counter, Hewlett Packard Model 524C, or equivalent.	
Volt-ohm-milliameter, Simpson Model 260, or equivalent.	
Spectrum Analyzer, TMC Model PTE-4A, or equivalent.	

tive. If reception is not possible on any channel, additional tests are required to isolate the trouble.

b. SYSTEMATIC TROUBLESHOOTING.

- (1) Disconnect antenna from J1502 and all external wiring from TB1501.
- (2) Connect a 600 ohm, 1 watt resistor across terminals 1 and 3 of TB1501. Set OFF-REC-XMIT/REC switch at REC.
- (3) Set RCVR switch at LSB. Measure r-f signal at emitter of Q1602 on receiver i-f board; level should be between 0.5 and 1.0 v rms. If this signal was not obtained, check circuitry of LSB oscillator Q1607 and buffer Q1609.
- (4) Set RCVR switch at USB/REMOTE. Measure r-f signal at emitter of Q1602; level should be between 0.5 and 1.0 v rms. If this signal is not obtained, check circuitry of USB oscillator Q1608.
- (5) Measure r-f signal at arm of potentiometer R1663 on receiver i-f board; level should be between 1.0 and 1.5 v rms. If this signal is not obtained, check circuitry of BFO Q1606 and buffer Q1605.
- (6) Remove channel 1 TTRR module; set RE-CEIVER CHANNEL switch at 1.
- (7) Connect signal generator to terminal 1 of receiver i-f board; adjust signal generator to deliver 1 mv (1000 uv) at 1749 kc.
- (8) Remove crystal Y1601. Measure r-f signal at output of filter FL1601; level should be approximately 0.28 v. If this signal was not obtained, check circuitry of i-f amplifier Q1601 and mixer Q1602.
- (9) Replace crystal Y1601; reduce signal generator output to 30 uv. Measure a-f signal at terminal 11 of receiver i-f board; level should be at least 10 mv (0.01 v). If this signal was not obtained, check product detector and a-f amplifier Q1603/Q1604 circuitry.
- (10) Adjust signal generator until level at terminal 11 is exactly 10 mv.
- (11) Measure a-f signal at terminals 1 and 3 of terminal board TB1501 (across 600 ohm resistor); level should be approximately 0.78 v rms. If this signal was not obtained, check circuitry of line amplifier Q1618.
- (12) Measure signal at ungrounded end of resistor R1660 on receiver a-f board (SQUELCH control

R1518 must be adjusted so that squelch relay K1601 is de-energized); adjust VOLUME control R1515 until level is approximately 1.3 v rms. If this signal was not obtained, check circuitry of audio amplifiers Q1613, Q1614 Q1615, and Q1616/Q1617.

- (13) Connect signal generator to antenna jack J1502, adjust generator to deliver 1 uv at a frequency 1 kc above channel 1 frequency. Replace channel 1 TTR module.
- (14) Measure a-f signal at terminals 1 and 3 on terminal board TB1501; level should be 0.78 v rms. Disconnect signal generator; noise level should be 0.13 v or lower. If this sensivity check is not satisfactory, the TTRR module is defective: refer to the appropriate TTRR technical manual.
- 5-5. TRANSMITTER SECTION TROUBLE-SHOOTING.
- a. QUICK TESTS USING FRONT PANEL CONTROLS.
- (1) CHANNEL TEST. Try to operate transmitter on all four frequencies selected by TRANS-MITTER CHANNEL switch. If the transmitter section operates properly on some but not all channels, the TTRT module for the inoperative channel is probably defective.

NOTE

When performing this procedure note that only AME operation is possible in channel 1.

- (a) VOX/PTT TEST. Set PTT/VOX switch at PTT. Close push-to-talk switch on microphone. Transmitter should key as evidenced by increase of PA plate current (observe front panel meter with PA METER switch set at Ib). If the transmitter does not key, the transmit/receive relay driver is defective. Set PTT/VOX switch at VOX; rotate VOX-GAIN control fully clockwise. Speak into microphone; transmitter should key as the XMTR AF GAIN is rotated clockwise. If the transmitter does not key, the VOX amplifier or detector is probably defective.
- (3) CW/SSB TEST. Alternately try to operate transmitter in the CW and SSB modes. If transmitter operates in CW mode only, the microphone pre-amplifier is probably defective. If transmitter operates in SSB mode only, the CW oscillator is probably defective.

b. SYSTEMATIC TROUBLESHOOTING.

- (1) Disconnect antenna from ANTENNA jack. Disconnect all external wiring from TB1500 and TB1501. Disconnect all audio inputs to TTR-10.
- (2) Connect dummy load to ANTENNA jack.

- (3) Connect jumper wire between terminals 7 and 8 of TB1500; this action keys transmitter.
- (4) Using r-f VTVM, check for presence of r-f at the wiper of potentiometer R1707 and R1716 of XMIT i-f board. If r-f is not present, check Q1704, Q1705 and associated circuitry.
- (5) Remove crystal Y1701. Connect signal generator to terminal 1 and 3 of terminal board TB1500, adjust generator to deliver 78 mv (0.078 v) at 1 kc.
- (6) Measure a-f signal across terminals 1 and 2 on transmitter a-f board; level should be approximately 10 mv (adjust XMTR AF GAIN control as necessary). If this signal is not obtained, check audio amplifier Q1702/Q1703 on XMIT audio board.
- (7) Connect signal generator to terminal 6 on TB1500 and ground; adjust generator to deliver 14 mv (0.014 v) at 1 kc. Signal across terminals 1 and 2 on transmitter a-f board should be as noted in step (7) above. If this signal is not obtained, check audio preamplifier Q1501.
- (8) Set CW/SSB/-20DB CARRIER/AM/MCW switch at CW. Connect jumper wire to terminals 11 and 12 on TB1500. Signal across terminals 1 and 2 at transmitter a-f board should be as noted in step (7) above. If this signal is not obtained, check CW oscillator Q1500.
- (9) Replace crystal Y1701. Measure r-f signal at terminal 9 at transmitter i-f board; level should be approximately 45 mv (0.045 v). If this signal is not obtained, check balanced modulator, balanced mixer on XMIT i-f board Q1701/01702, and ALDC controlled i-f amplifier Q1703.
- (10) Set CW/SSB-20DB CARRIER/AM/MCW switch at MCW. Observe r-f signal at terminal 9 on transmitter i-f board.

If scope pattern does not comply with figure $5-1\underline{d}$, check buffer amplifier 01706.

(11) Set CW/SSB/-20DB CARRIER/AM MCW switch at CW. Measure r-f signal at pin 2 (grid) of V1500; level should be between

2.1 and 2.8 v rms. If defective; refer to appropriate TTRT Technical Manual.

NOTE

When performing steps 12 and 13 below, do not key the transmitter for more than 1 minute at a time. Leaving the transmitter keyed for long periods of time will damage the power_amplifier tube.

- (12) Set PA OVLD circuit breaker down. Measure r-f signal at pin 2 or pin 6 (grid) of V1501; level should be between 15 and 18 v rms. If this signal is not obtained, check intermediate power amplifier V1500.
- (13) Measure r-f signal at J1501, level should be 50 v rms. If this signal is not obtained, check power amplifier V1501.

5-6. RECEIVER SECTION ALIGNMENT.

<u>a.</u> For change of receiver channel frequency, the i-f and a-f stage alignment procedure given in step \underline{b} below need not be performed. For change of receiver channel frequency, perform TTRR alignment as outlined in the TTRR manual.

b. RECEIVER I-F AND A-F STAGES.

- (1) Disconnect all external wiring from TB1501. Connect 600 ohm resistor between terminal 1 and 3 on TB1501.

 Remove channel 1 TTRR module. Set RECEIVER CHANNEL switch at 1.
- (2) Connect VTVM to secondary (terminal 3) of T1602; set VTVM at lowest scale.
- (3) Adjust R1663 as required to obtain minimum indication on VTVM.
- (4) Connect r-f signal generator to terminal 1 on receiver i-f board. Adjust generator to deliver 1 mv at 1740 kc.
- (5) Adjust R1544, C1604, C1602, C1655, and C1656 to obtain maximum signal at secondary of T1602; reduce signal generator output to obtain lowest usable

indication on VTVM while performing this step.

- (6) Set RCVR switch at LSB, tune signal generator to 1751 kc; adjust R1543 to obtain maximum signat at secondart of T1602.
- (7) Readjust C1604 and C1602, R1544 or 1543 until signal levels at secondart of T1602 are equal with upper sideband and lower sideband inputs applid (RCVR switch must be alternately set at USB and LSB respectively).
- (8) Connect counter across 600 ohm resistor on TB1501. Make sure that signal generator output frequency is 1749 kc +cps. Set RCVR switch at USB/REMOTE. Adjust C1631 until counter indicates 1000 cps.
- (9) Tune signal generator to 1751 kc +2 cps. Set RCVR switch at LSB. Adjust C1629 until counter indicates 1000 cps.
- (10) Replace channel 1 TTRR module. Connect signal generator to J1502. Adjust signal generator to deliver 1 microvolt at a frequency of 1 kc below channel 1 frequency.
- (11) Connect VTVM across 600 ohm resistor on TB1501. Adjust R1612 to obtain 0.78 v rms across 600 ohm resistor.

5-7. TRANSMITTER SECTION ALIGNMENT.

- <u>a.</u> For transmitter channel frequency change, perform TTRT module alignment as outlined in the TTRT technical manual and steps (1) through (3), steps (8) through (17), and step (23) of paragraph <u>c</u> below (Linear Amplifier Alignment). Exciter alignment, paragraph <u>b</u>, and the remainder of the linear amplifier alignment are to be used for corrective maintenance purposes only.
- <u>b.</u> EXCITER ALIGNMENT. This procedure must be performed with TTRT module installed.
- (1) Ensure that TTR-10 has been allowed to warm up for at least 30 minutes.

- (2) Using frequency counter, monitor frequency at terminal 8 of XMIT i.f. board. Adjust capacitor C1734 as required to obtain 1.75 Mc indication on frequency counter.
- (3) Turn drive potentiometer (Control D) of associated TTRT module fully counterclockwise.
- (4) Turn potentiometer R1563 (located on rear apron) and potentiometer R1738 fully clockwise.
- (5) Set CW/SSB/-20DB CARRIER/AM/MCW switch at AM.
- (6) Connect a-c VTVM to terminal 9 of XMIT i.f. board. Adjust C1725 and C1728 for maximum indication on VTVM.
- (7) Set CW/SSB/-20DB CARRIER/
 AM/MCW switch at SSB.
- (8) Adjust C1703, C1714, C1744, R1706 and R1716 as required for minimum indication on VTVM.
- (9) Repeat step (8) until no further reduction in signal level is obtained by adjustment of any of the controls.
- (10) Connect a-f signal generator between terminal 6 of TB1500 and ground. Connect a-c VTVM between pin 4 or 6 of XMIT i-f board and ground.
- (11) Tune signal generator to 1 Kc; adjust output level as required to obtain 25 millivoat indication on a-c VTVM.
- (12) Disconnect a-c VTVM from TB1500 and connect it to terminal 9 of XMIT i-f board. Adjust R1738 as required to obtain 100 millivolt indication on VTVM.
- (13) Disconnect signal generator. Repeat steps 7, 8 and 9 to assure prior adjustments to balanced modulator have not been disturbed.

- (14) Disconnect a-c VTVM from terminal 9 and connect between terminal 6 of TB1500 and ground.
- (15) Connect signal generator between terminal 6 of TB1500 and ground (same point as VTVM was connected in step (14) above). Tune signal generator to 1000 cycles, adjust output level to 14 millivolts as indicated on VTVM.
- (16) Connect spectrum analyzer between terminal 9 and 10 of XMIT i-f board. Adjust analyzer to accept 1.75 Mc signal; single tone display should be obtained on spectrum analyzer.
- (17) Increase gain of spectrum analyzer; carrier should appear to right of tone at 40dB below tone. Readjust (fine tune) balance modulator adjustments as outlined in steps 7, 8 and 9 until proper indication is obtained on spectrum analyzer (carrier 40dB down).
- (18) Set CW/SSB/-20DB CARRIER/
 AM/MCW switch at AM; two-tone display
 should be obtained on spectrum analyzer.
 (The added tone is the carrier that
 is automatically reinserted when CW/SSB/
 -20DB CARRIER/AM/MCW switch is set at AM.
 or when the CHANNEL switch is set at 1.
- (19) Adjust R1563 (located on rear apron) as required so that carrier and tone are of equal amplitude.
- (20) Adjust gain of spectrum analyzer as required to bring tone levels 3db below zero reference. Distortion products should be 40db below zero reference; if proper indication is not obtained, alignment procedure (steps 2 through 19) should be repeated.
- (21) Set CW/SSB/ -20DB CARRIER/AM/MCW switch at CW.
- (22) Connect a-c VTVM between terminal 10 of CW OSC board and ground.

 Connect jumper between terminal 11 and 12 of TB1501.
- (23) Adjust potentiometer R1533 on CW OSC board as required to obtain 14 mv indication on VTVM; lock R1533. Single tone display should be obtained on spec-

trum analyzer. Disconnect a-c VTVM.

- (24) Observe spectrum analyzer for second harmonic distortion signals; this distortion signal should be more than 30db below audio oscillator tone.
- (25) Set CW/SSB/-20DB CARRIER/AM/MCW switch at MCW; carrier signal should appear on spectrum analyzer in addition to CW OSC tone (see step 23).

Carrier level should be $8db \pm 2db$ above the audio tone. The second harmonic of the audio tone should be $42db \pm 2db$ below carrier level.

(26) If necessary, align TTRT module/s as outlined in TTRT equipment manual.

c. LINEAR AMPLIFIER ALIGNMENT

NOTE

Make sure that the exciter section of the transmitter has been properly aligned befor attempting alignment of the linear amplifier section.

- (1) Connect dummy load to ANTENNA jack at rear of unit. Connect spectrum analyzer to low-level monitor output of dummy load. Connect r-f VTVM to J1501 (parallel with dummy load).
- (2) Adjust spectrum analyzer as required to provide indication of output frequency.
- (3) Disconnect all external wiring from TB1500 and TB1501. Connect one end of jumper wire to terminal 8 of TB1500.
- (4) Set OFF-REC-XMIT/REC switch at OFF.
- (5) Disconnect jumper between terminals 3 and 4 on CW oscillator board. Connect VOM between these terminals, lead to terminal 4, and + lead to terminal 3. Select current scale on VOM in excess of 50 ma.

WARNING

Lethal voltage will be present

in the circuit under under test when performing step 6 below. Do not touch meter or meter leads.

- (6) Set OFF-REC-XMIT/REC switch at MXIT/REC. Rotate XMTR AF GAIN control fully counter-clockwise. Unground terminal 8 of TB1500. Set PA OVLD circuit breaker down (on). Set PA METER switch at Ib. After five minutes, ground terminal 8 of TB1500. Adjust R1500 (PA Ib ADJ) until VOM indicates 50 ma. Adjust R1507 until fron panel meter indicates 50 ma.
- (7) Set PA OVLD circuit breaker (off). Ground terminals 3 and 4 on CW oscillator board to discharge capacitors, and remove meter leads. Replace jumper disconnected in step (5) above.
- (8) Remove TTRT module of channel on which alignment is being performed; connect TTRT module to module extender and insert module extender into TTRT recepticle.
- (9) Set CW/SSB/ -20DB CARRIER/AM/ MCW switch at SSB.
- (10) Connect a-f signal generator between terminal 6 of TB1500 and ground. Adjust signal generator for 1 kc at 14 mv.
- (11) Set PA OVLD circuit breaker down (on); set OFF-REC-XMIT/REC switch at XMIT/REC. Set PA METER switch at EgRF.

NOTE

When performing steps (12) through (19) below, refer to figure 5-10 for location of TTRA controls.

- (12) Set PA TUNING switch on TTRA module as indicated in table 5-3 for appropriate channel frequency. Set PA LOAD-ING switch at 1. Rotate PA LOADING control fully counterclockwise.
- (13) Ground terminal 8 of TB1500. Rotate XMTR AF GAIN control clockwise, and adjust IPA TUNING control on TTRA to obtain peak indication on front panel meter; keep meter indication as low as possible with XMTR AF GAIN.

TABLE 5-3. PA TUNE SWITCH SETTING

FREQ. (IN MC)	PA TUNE SWITCH SETTING	LINEAR AMPL. MODULE
2 - 2.2	1	TTRA-1
2.2 - 2.5	2	
2.5 - 3.1	3	
3.1 - 4.0	4	
4.0 - 5.0	1	TTRA-2
5.0 - 6.3	2	
6.3 - 8.0	3 & 4	
8.0 - 10.0	1	TTRA-3
10.0 - 12.6	2	•
12.6 - 16.0	3 & 4	
16.0 - 20.0	1	TTRA-4
20.0 - 24.0	2	
24.0 - 28.0	3	
28.0 - 32.0	. 4	

- (14) Set PA METER switch at Ib. Adjust XMTR AF GAIN control to obtain indication of approximately 75 ma on front panel meter. Adjust PA TUNING control to obtain dip on meter.
- (15) Rotate PA LOADING switch clockwise until a sharp increase of PA plate current is indicated on front panel meter. Readjust PA TUNING control to obtain dip on front panel meter.
- (16) Adjust PA TUNING contro, PA LOADING control, and XMTR AF GAIN control until VTVM indicates 50 ν rms at J1501, and front panel meter indicates approximately 125 ma.
- (17) Adjust control D on TTRT module until conditions set forth in step (15) are met with XMTR AF GAIN control at its fully clockwise position.
- (18) Set PA OVLD circuit breaker down; unground terminal 8 of TB1500. Set CW/SSB/-20DB CARRIER/AM/MCW switch at AM.

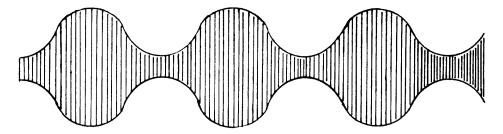
(19) Set PA OVLD circuit breaker up; after five minutes, ground terminal 8 of TB1500. Adjust analyzer gain as required to bring displayed tone levels to -3db from zero reference. Third order distortion products should be at least -30db from zero reference. If necessary, adjust screw A on TTRT module, PA TUNING and PA LOADING controls on TTRA modules to minimize distortion. Adjust screw D on TTRT to keep r-f voltage at J1501 at approximately 70 v rms; front panel meter should indicate approximately 165 ma.

NOTE

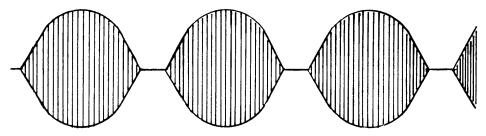
Slight re-adjustment of the PA LOADING controls may be necessary after the dummy load is disconnected and the TTR-10 is connected to its antenna.

- (20) Set PA METER switch at EoRF. Adjust R1511 until front panel meter indicates same value as does VTVM connected to J1501.
- (21) Set PA OVLD circuit breaker up; unground terminal 8 of TB1500. Connect VTVM to grid (pin 2 or 6) of V1501. Set PA METER switch at EgRF.

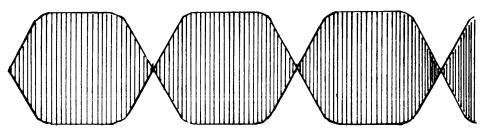
- (22) Set PA OVLD circuit breaker down; ground terminal 8 of TB1500. Adjust R1502 until front panel meter indicates same value as does VTVM.
- (23) Set PA OVLD circuit breaker up; unground terminal 8 of TB1501. Disconnect VTVM from equipment.
- (24) Set PA OVLD circuit breaker down; ground terminal 8 of TB1501. Set PA METER switch at Ib. Adjust screw D on TTRT until front panel meter indicates 180 ma; adjust PA OVLD ADJ control on power supply module until PA OVLD circuit breaker trips. Reduce excitation with screw D on TTRT module, reset PA OVLD circuit breaker, and check the circuit breaker does not trip with approximately 175 ma plate current.
- (25) Adjust ALDC potentiometer R1562 until the output indication on r-f VTVM just begins to drop. Lock R1562.
- (26) Set OFF-REC-XMIT/REC switch at OFF. Disconnect all test equipment from the TTR-10 and jumper wires from the terminal boards. Remove module extender and re-insert TTRT module for normal operation; restore external wiring as required.



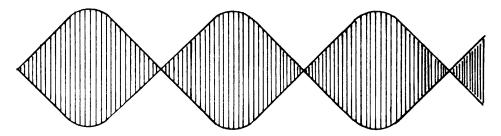
(a) INCORRECT SIDEBAND/CARRIER POWER RATIO



(b) EXCESSIVE DISTORTION (NEGATIVE CLIPPING)



(c) EXCESSIVE DISTORTION (POSITIVE CLIPPING)



(d) CORRECT MODULATION ENVELOPE

1004-10

Figure 5-1. Modulation Envelopes

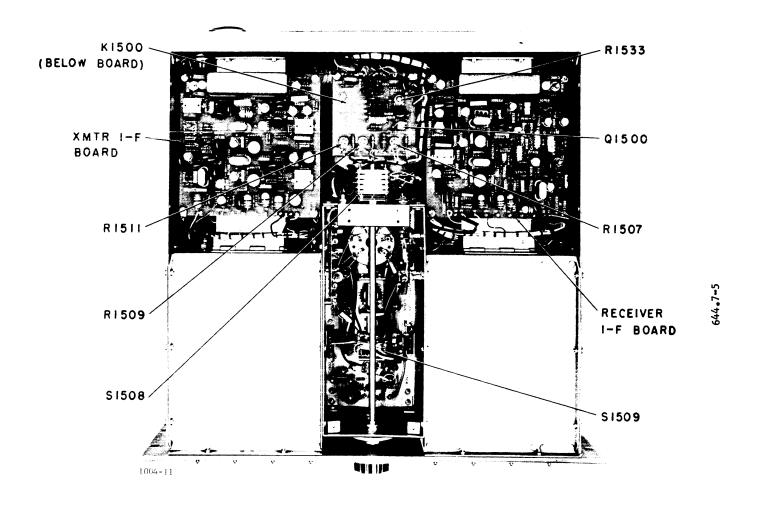


Figure 5-2. TTR-10, Bottom View

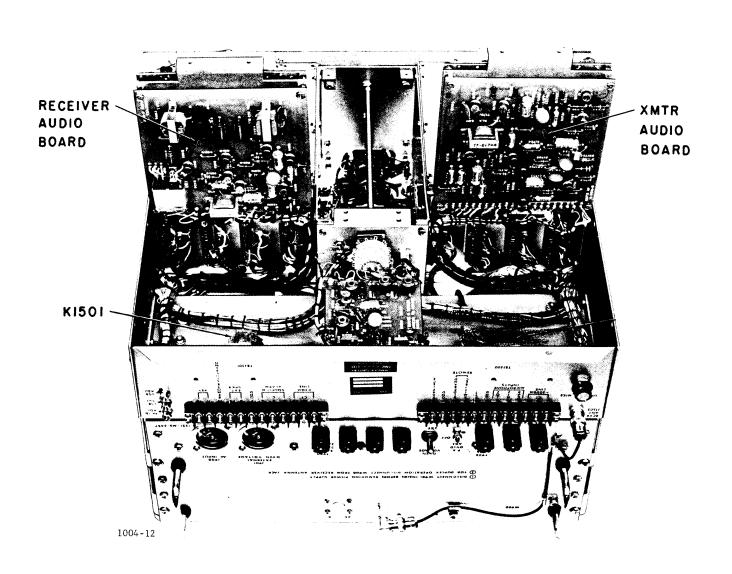


Figure 5-3. TTR-10, Bottom View With Underside of Hinged Board Assemblies Exposed

Figure 5-4. TTR-10, Top View With TTRA Modules Removed

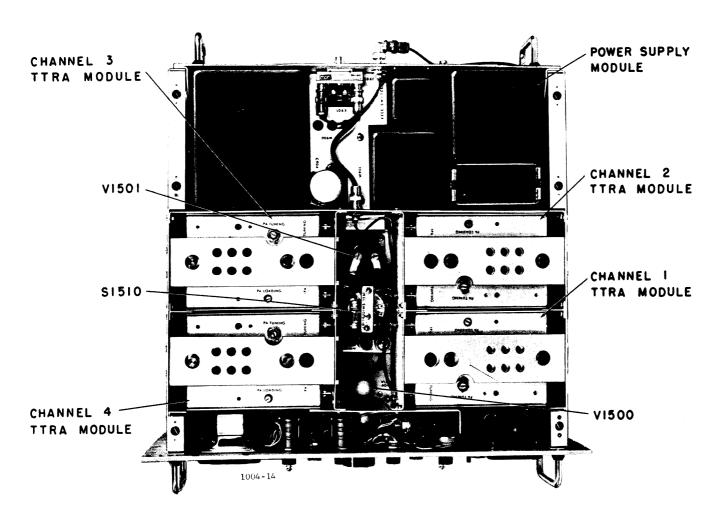


Figure 5-5. TTR-10, Top View

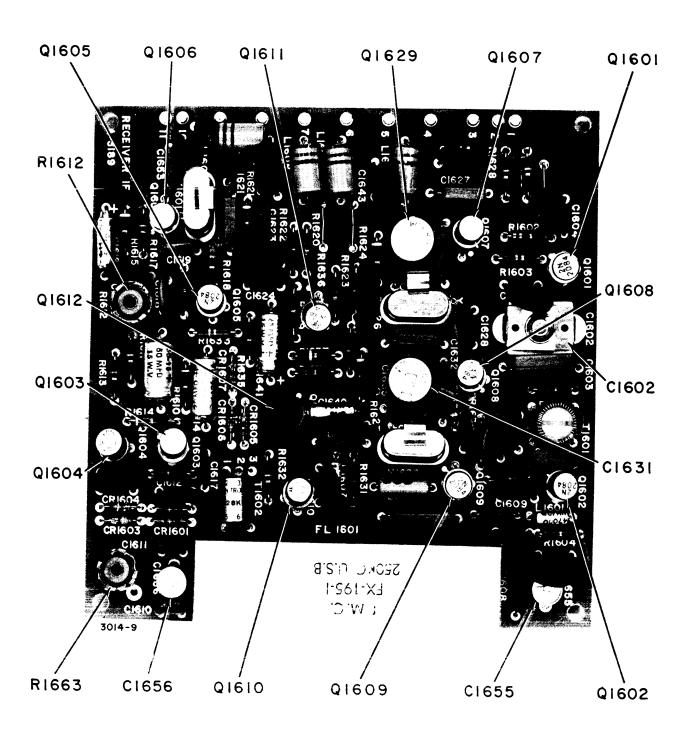


Figure 5-6. Receiver i-f Board, Top View

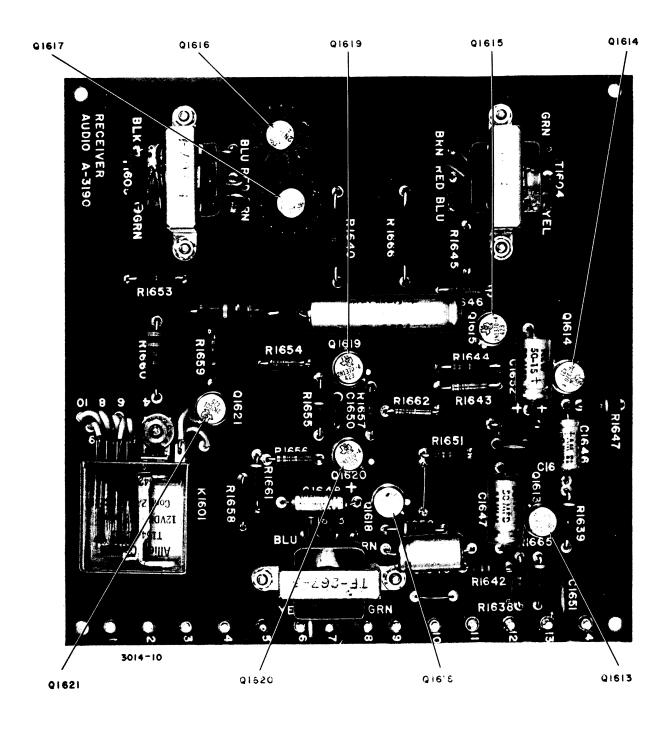


Figure 5-7. Receiver Audio Board, Top View

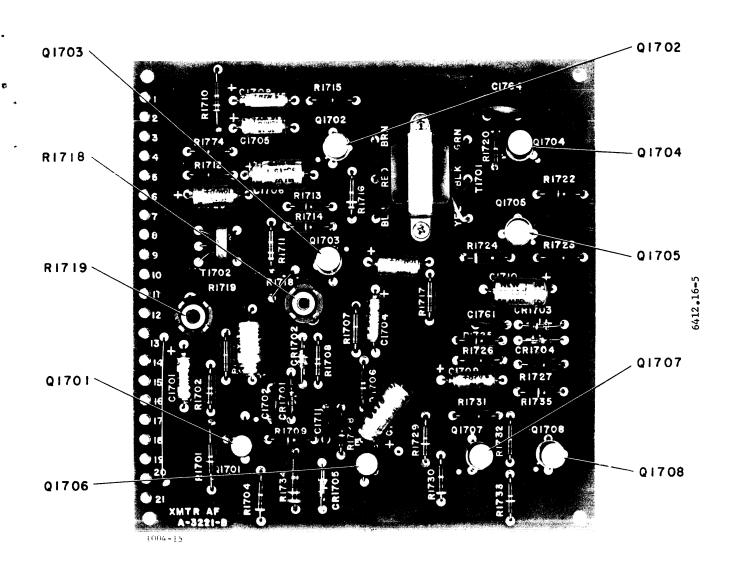


Figure 5-8. Xmtr Audio Board, Top View

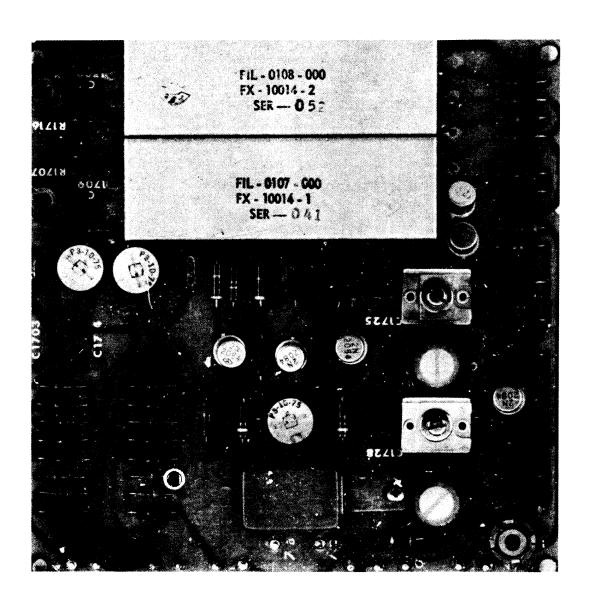


Figure 5-9. Xmtr i-f Board, Top View

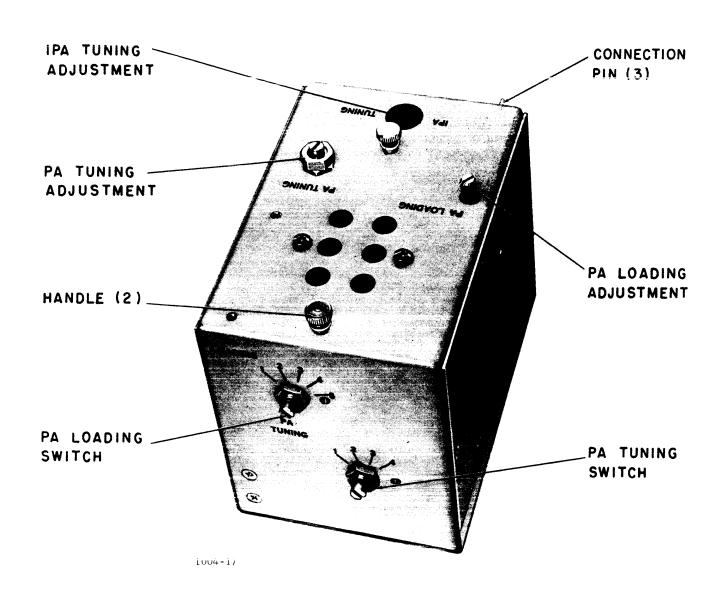


Figure 5-10. TTRA Module

SECTION 6 PARTS LIST

6-1 INTRODUCTION:

Reference designations have been assigned to identify all electrical parts of the equipment. These designations are used for marking the equipment (adjacent to the part they identify) and are included on drawings, diagrams and the parts list. The letters of a reference designation indicate the kind of part (generic group), such as resistor, capacitor, transistor, etc. The number differentiates between parts of the same generic group. Sockets associated with a particular plug-in device, such as transistor or fuse, are identified by a reference designation which includes the reference designation of the plug-in device. For example, the socket for crystal Y101 is designated XY101. To expedite delivery, when ordering replacement parts, specify the TMC part number and the model number of the equipment.

005651004 6-1

REF	ES 1100	TMC
SYMBOL	DESCRIPTION	PART NUMBER
C1101	CAPACITOR, VARIABLE, MICA DIELECTRIC: 11 plates; 1,000 uuf min. when tight, 210 uuf max. at 3 turns; 175 WVDC.	CV113-4
C1102	CAPACITOR, FIXED, MICA DIELECTRIC: 1,500 uuf, +10%; 500 WVDC; char. B.	CM20B152K
C1103	CAPACITOR, VARIABLE, AIR DIELECTRIC: 12.9-342 uuf per sec.; 1 section, 59 plates per section; straight line capacity tuning; AC peak voltage 1,000 V.	CB168-1
C1104	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 10 uuf, ±10%; 5,000 WVDC.	CC109-5
C1105	CAPACITOR, FIXED, MICA DIELECTRIC: 560 uuf, +10%; 2,500 WVDC; char. B.	CM45B561K
C1106	CAPACITOR, FIXED, MICA DIELECTRIC: 390 uuf, ±10%; 2,500 WVDC; char. B.	CM45B391K
C1107	CAPACITOR, FIXED, MICA DIELECTRIC: 330 uuf, ±10%; 2,500 WVDC; char. B.	CM45B331K
C1108	CAPACITOR, FIXED, MICA DIELECTRIC: 220 uuf, $\pm 2\%$; 2,500 WVDC; char. B.	CM45B221G
C1109	CAPACITOR, VARIABLE, MICA DIELECTRIC: 15 plates; 1,400 uuf min. when tight, 390 uuf max. at 3 turns; 175 WVDC.	CV113-8
C1110	CAPACITOR, FIXED, MICA DIELECTRIC: 1,000 uuf, ±10%; 2,500 WVDC; char. B.	CM45B102K
C1111	Same as C1110.	
C1112	Same as C1110.	
C1113	Same as C1110.	
C1114	Same as C1108.	
J1101	CONNECTOR, RECEPTACLE, ELECTRICAL: 6 flat solid type male contacts, current rating 5 amps continuous, 600 VAC RMS.	JJ286-6
S1101	SWITCH, ROTARY: 1 section, 4 positions, 300 angle of throw; non-shorting type, silver alloy contacts.	SW330
S1102	SWITCH, ROTARY: 1 section, 5 positions, 300 angle of throw; shorting type, silver alloy contacts.	SW331
T1101	TRANSFORMER, RADIO FREQUENCY: operating frequency 2-4 MC; inductance, 8 uhy, ±0.20 uhy (BLK-BLU), 2.05 uhy, ±0.2 uhy (BLK-GRN); powdered iron coil form.	TZ117
T1102	TRANSFORMER, RADIO FREQUENCY: operating frequency 2-4 MC; total nom. inductance 9.5 uhy, +0.95 uhy; phenolic coil form, 4 screw type terminals.	TZ120
		<u> </u>

		SYMBOL SERIES 1200
R E F SYMBOL	DESCRIPTION	TMC PART NUMBER
C1201	CAPACITOR, VARIABLE, MICA DIELECTRIC: 6 plates; 480 uuf min. when tight, 80 uuf max. at 3 turns; 175 WVDC.	CV113-2
C1202	CAPACITOR, VARIABLE, AIR DIELECTRIC: 12.9-342 uuf per sec.; 1 section, 59 plates per section; straight line capacity tuning; AC peak voltage 1,000 V.	CB168-1
C1203	CAPACITOR, FIXED, MICA DIELECTRIC: 160 uuf, ±10%; 2,500 WVDC; char. B.	CM45B161K
C1204	CAPACITOR, FIXED, MICA DIELECTRIC: 100 uuf, +10%; 2,500 WVDC; char. B.	CM45B101K
C1205	CAPACITOR, VARIABLE, MICA DIELECTRIC: 12 plates; 1,000 uuf min. when tight, 240 uuf max. at 3 turns; 175 WVDC.	CV113-7
C1206	CAPACITOR, FIXED, MICA DIELECTRIC: 560 uuf, ±10%; 2,500 WVDC; char. B.	CM45B561K
C1207	Same as C1206.	
C1208	Same as C1206.	
C1209	Same as C1206.	
J1201	CONNECTOR, RECEPTACLE, ELECTRICAL: 6 flat solid type male contacts, current rating 5 amps continuous, 600 VAC RMS.	JJ286-6
S1201	SWITCH, ROTARY: 1 section, 4 positions, 30 ⁰ angle of throw; non-shorting type, silver alloy contacts.	SW330
S1202	SWITCH, ROTARY: 1 section, 5 positions, 30 ⁰ angle of throw; shorting type, silver alloy contacts.	SW331
T1201	TRANSFORMER, RADIO FREQUENCY: operating frequency 4-8 MC; inductance, 3.65 uhy, +0.10 uhy (BLK-BLU), 0.91 uhy, +0.05 uhy (BLK-GRN); powdered iron coil form.	TZ118
T1202	TRANSFORMER, RADIO FREQUENCY: operating frequency 4-8 MC; total nom. inductance 4.5 uhy, ±0.40 uhy; phenolic coil form, 4 screw type terminals.	TZ121
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YMBOL SERII REF SYMBOL	DESCRIPTION	TMC PART NUMBER
C1301	CAPACITOR, VARIABLE, AIR DIELECTRIC: 3 plates; 180 uuf min. when tight, 9 uuf max. at 3 turns; 175 WVDC.	CV113-5
C1302	CAPACITOR, VARIABLE, AIR DIELECTRIC: 10-210 uuf per sec.; 1 section, 37 plates per section; straight line capacity tuning; AC peak voltage 1,000 V.	CB169-1
C1303	CAPACITOR, FIXED, MICA DIELECTRIC: 56 uuf, $\pm 10\%$; 2,500 WVDC; char. B.	CM45B560K
C1304	CAPACITOR, VARIABLE, AIR DIELECTRIC: 7 plates; 580 uuf min. when tight, 110 uuf max. at 3 turns; 175 WVDC.	CV113-6
C1305	CAPACITOR, FIXED, MICA DIELECTRIC: 390 uuf, ±10%; 2,500 WVDC; char. B.	CM45B391K
C1306	Same as C1305.	
C1307	Same as C1305.	
C1308	CAPACITOR, FIXED, MICA DIELECTRIC: 160 uuf, ±10%; 500 WVDC; char. B.	CM15B161K
C1309	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 5 uuf, ±10%; 5,000 WVDC.	CC109-3
J1301	CONNECTOR, RECEPTACLE, ELECTRICAL: 6 flat solid type male contacts, current rating 5 amps continuous, 600 VAC RMS.	JJ286-6
S1301	SWITCH, ROTRAY: 1 section, 4 positions, 30° angle of throw; non-shorting type, silver alloy contacts.	SW330
S1302	SWITCH, ROTARY: 1 section, 5 positions, 30 ⁰ angle of throw; shorting type, silver alloy contacts.	SW331
Т1301	TRANSFORMER, RADIO FREQUENCY: operating frequency 8-16 MC; inductance 1.46 uhy, ±0.05 uhy (BLK-BLU), 0.33 uhy, ±0.05 uhy (BLK-GRN); powdered iron coil form.	TZ116
Т1302	TRANSFORMER, RADIO FREQUENCY: operating frequency 8-16 MC; inductance, 2.4 uhy, ±0.24 uhy; phenolic coil form; 4 screw type terminals.	TZ122
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	.	

	SYMBOL SERIE	
REF SYMBOL	DESCRIPTION	TMC PART NUMBER
C1401	CAPACITOR, VARIABLE, MICA DIELECTRIC: 4 plates; 280 uuf min. when tight, 25 uuf max. at 3 turns; 175 WVDC.	CV113-1
C1402	CAPACITOR, VARIABLE, AIR DIELECTRIC: 10-210 uuf per sec.; 1 section, 37 plates per section; straight line capacity tuning; AC peak voltage 1,000 V.	CB169-1
C1403	CAPACITOR, VARIABLE, MICA DIELECTRIC: 7 plates; 580 uuf min. when tight, 110 uuf max. at 3 turns; 175 WVDC.	CV113-6
C1404	CAPACITOR, FIXED, MICA DIELECTRIC: 220 uuf, +10%; 2,500 WVDC; char. B.	CM45B221K
C1405	Same as C1404.	
C1406	CAPACITOR, FIXED, MICA DIELECTRIC: 160 uuf, ±10%; 2,500 WVDC; char. B.	CM45B161K
J1401	CONNECTOR, RECEPTACLE, ELECTRICAL: 6 flat solid type male contacts, current rating 5 amps continuous, 600 VAC RMS.	JJ286-6
S1401	SWITCH, ROTARY: 1 section, 4 positions, 30° angle of throw; non-shorting type, silver alloy contacts.	SW330
S1402	SWITCH, ROTARY: 1 section, 5 positions, 30° angle of throw; shorting type, silver alloy contacts.	SW331
T1401	TRANSFORMER, RADIO FREQUENCY: operating frequency 16-32 MC; inductance, 0.34 uhy, ±0.05 uhy (BLK-BLU), 0.11 uhy, ±0.05 uhy (BLK-GRN); powdered iron coil form.	TZ119
T1402	TRANSFORMER, RADIO FREQUENCY: operating frequency 16-32 MC; inductance, 1.21 uhy, ± 0.12 uhy; cellulose acetate support bars; 2 screw type terminals and 3 wire lead type terminals.	TZ123
	- €-7	

SYMBOL SERI		TMC
SYMBOL	DESCRIPTION	PART NUMBER
C1500	CAPACITOR, FIXED, ELECTROLYTIC: 2,000 uf, 25 WVDC; polarized: hermetically sealed aluminum case with clear vinyl plastic sleeve.	CE116-5VN
C1501	CAPACITOR, FIXED, CERAMIC, FEEDTHRU: 2,000 uuf, +20%; 500 WVDC.	CK70AW202M
C1502	CAPACITOR, FIXED, MICA DIELECTRIC: 510 uuf, ±5%; 500 WVDC; char. B.	CM15B511J
C1503	CAPACITOR, FIXED, MICA DIELECTRIC: 1,000 uuf, ±5%; 500 WVDC; char. B.	CM20B102J
C1504	CAPACITOR, FIXED, MICA DIELECTRIC: 1,000 uuf, ±5%; 500 WVDC/350 WVAC at 85°C.	CM113QE102J
C1505	CAPACITOR, FIXED, MICA DIELECTRIC: 2,000 uuf, +2%; 500 WVDC; char. F.	CM10()-14
C1506	Same as C1504.	
C1507	CAPACITOR, FIXED, MICA DIELECTRIC: 3,000 uuf, ±5%; 500 WVDC; char. B.	CM30B302J
C1508	Same as C1501.	
C1509	Same as C1501.	
C1510	CAPACITOR, FIXED, MICA DIELECTRIC: 8,100 uuf, ±5%; 500 WVDC/350 WVAC at 85°C.	CM113QE812J
C1511	Same as C1503.	
C1512	Same as C1504.	
C1513	Same as C1510.	
C1514	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 5 uuf, +10%; 5,000 WVDC.	CC109-3
C1515	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 3.0 uuf, +0.5 uuf; 500 WVDC; char. CJ.	CC21CJ030D
C1516	Same as C1510.	
C1517	CAPACITOR, FIXED, MICA DIELECTRIC: 15 uuf, +2%; 500 WVDC; char. G.	CM15C150G
C1518	CAPACITOR, FIXED, MICA DIELECTRIC: 1,000 uuf, +5%; 500 WVDC; char. D.	CM20D102J
C1519	Same as C1518.	
C1520	Same as C1501.	
C1521	Same as C1503.	
C1522 thru C1524	Same as C1504.	

		SYMBOL SERIES 1500
REF SYMBOL	DESCRIPTION	TMC PART NUMBER
C1525	CAPACITOR, FIXED, PLASTIC DIELECTRIC: .001 uf, ±5%; 3,000 WVDC; RF current carring capacity 1 amp at 32 MC; hermetically sealed glass case, metalized ends.	CX109-1
C1526	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 1,000 úuf, ±20%; 5,000 WVDC.	CC109-38
C1527	Same as C1526.	
C1528	Same as C1515.	
C1529	Same as C1517.	
C1530	Same as C1501.	
C1531	Same as C1501.	
C1532	NOT USED	
C1533	Same as C1526.	
C1534	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 10,000 uuf, GMV; 500 WVDC.	CC100-16
C1535	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 200,000 uuf, +80% -20%; 25 WVDC.	CC100-33
C1536	Same as C1534.	
C1537	Same as C1534.	
C1538	CAPACITOR, FIXED, ELECTROLYTIC: 50 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-50-15
C1539	NOT USED	
C1540	NOT USED	
C1541	CAPACITOR, FIXED, MICA DIELECTRIC: 39 uuf, +10%; 500 WVDC; char. B.	CM15B390K
C1542	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 5,000 uuf, GMV; 500 WVDC.	CC100-15
C1543	Same as C1535.	
C1544	CAPACITOR, FIXED, ELECTROLYTIC: 5 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-5-15
C1545	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 1,000 uuf, +80% -20%; 500 WVDC.	CC100-32
CB1500	CIRCUIT BREAKER: SPST; magnetic and hydraulic combination blowout; contacts rated at 250 VAC, 50/60 cps, 15 amps; coil rated at 0.06 amps DC; insulated for 1,500 V; shunt trip release; delay curve 5; toggle lever type; overload protection; manual reset.	SW262
CR1500	SEMICONDUCTOR DEVICE, DIODE: silicon; 175 V max. peak inverse voltage; 30 ma at 25°C and 15 ma at 150°C; two axial wire lead	1N463

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YMBOL SERII	ES 1500	TMC
R E F SYMBOL	DESCRIPTION	PART NUMBER
CR1500 (Cont)	type terminals; hermetically sealed glass case.	
CR1501	Same as CR1500.	
DS1500	LAMP, GLOW: cartridge type; white, plastic, unfrosted, stovepipe type lens; 33,000 ohm, 1/3 watt internal resistor; NE-2H neon type lamp rated at 1/15 watt nom., starting voltage 65 VAC or 90 VDC, circuit voltage 100 to 125 VAC/VDC; aluminum clear anodize body.	BI112-2
EV1500	SHIELD, ELECTRON TUBE: heat dissipating; 2-3/4" high x 1" sq.; black cadmium plated finger insert liner.	TS128-7
J1500	CONNECTOR, RECEPTACLE, ELECTRICAL: 24 flat male contacts, rated at 5 amps, 750 WVDC; float mounted.	JJ296-1
J1501	CONNECTOR, RECEPTACLE, ELECTRICAL: RF; 1 round female contact; straight type; 52 ohms; series BNC to BNC.	UG625B/U
J1502	Same as J1501.	
J1503 thru	CONNECTOR, RECEPTACLE, ELECTRICAL: 6 female, flat, solid face contacts, rated at 5 amps continuous, 600 V RMS; green, glass filed diallyl, phthalate.	JJ285-6
J1506 J1507	CONNECTOR, RECEPTACLE, ELECTRICAL: PC board type; 20 female contacts, 5 amps continuous current rating; 600 V RMS.	JJ287-20
J1508 thru J1514	Same as J1507.	
J1515	SOCKET, PANEL MOUNT: 6 male type contacts.	JJ212.
K1500	RELAY, ARMATURE: 6PDT; 185 ohms, +10% DC resistance; operating voltage 12 VDC; current rating 60 ma; 700 mw at 25°C; 20 contacts rated at 2 amps at 29 VDC resistance; clear high impact styrene dust cover case.	RL156-6
K1501 4 K1502	RELAY, ARMATURE: DPDT, miniature; (2 form C) contacts, 0.030 ohm max. per contact; contacts rated at 3 amps, 26.5 VDC; coil rated at 200 ohms DC resistance, 12.6 VDC nom., 0.034 min. operating amps; nom. coil operating power 250 mw; coil dissipation 1 watt at 125°C, 1.5 watts at 25°C; hermetically sealed.	RL143-3
K1503	RELAY, ARMATURE: DPDT; 675 ohms DC resistance; current rating .019 amps; 13.5 V at 25°C; eight contacts rated for 3 amps at 26.5 VDC; hermetically	₹143-6
K1502	sealed case.	
L1500	COIL, RADIO FREQUENCY: fixed; inductance, 2.55 uhy, ±0.1 uh; 0.008 ohms DC resistance; current rating 3.5 amps at 60 cps; solid coil form.	CL318
L1501	COIL, RADIO FREQUENCY: fixed; 120.0 uh, ±10%; 3.2 ohms DC resistance; molded case.	CL240-120
L1502 thru L1504	Same as L1501.	

R E F SYMBOL	DESCRIPTION	TMC PART NUMBER
L1505	Same as L1500.	
L1506	Same as L1501.	
L1507	COIL, RADIO FREQUENCY: fixed; 1.1 uhy nom.; operating frequency 7.9 MC; powdered iron core.	CL139
L1508	CHOKE, RADIO FREQUENCY: inductance, 750 uh, ±10%; current rated at 75 to 100 ma; approx. resistance 16.0 ohms; molded bakelite form.	CL100-5
L1509 thru L1513	Same as L1501.	,
L1514	COIL, RADIO FREQUENCY: fixed; inductance, 180 uh (170-190 uh); operating frequency 790 KC; powdered iron core.	CL319
L1515	COIL, RADIO FREQUENCY: fixed; inductance, 180 uh (170-190 uh); operating frequency 790 KC; powdered iron core.	CL317
L1516	NOT USED	
L1517	Same as L1501.	
L1518	Same as L1501.	
L1519	Same as L1515.	
LS1500	LOUDSPEAKER, PERMANENT MAGNET: operating frequency range 200 to 5,000 cps; voice coil impedance 3.2 ohms; input wattage, nom. 1 watt, peak 2 watts; 2-17/32" square x 1-19/32" deep.	LS106
M1500	METER, ARB SCALE: 0-50 ua movement; approx. resistance 2,000 ohms; black molded phenolic case.	MR172
PS1500	SUPPRESSOR, PARASITIC	AX163
PS1501	SUPPRESSOR, PARASITIC	AX391
PS1502	Same as PS1501.	
Q1500	TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controled hie limit of 80-150; JEDEC type T05 case.	TX106
R1500	RESISTOR, VARIABLE, COMPOSITION: 50,000 ohms, ±20%; continuous power rating 0.5 watt at 70°C; 350 V RMS; linear taper.	RV106UX8B503B
R1501	RESISTOR, FIXED, COMPOSITION: 220 ohms, $\pm 5\%$; 1 watt.	RC32GF221J
R1502	RESISTOR, FIXED, COMPOSITION: 10,000 ohms, ±5%; 1/2 watt.	RC20GF103J
R1503	RESISTOR, FIXED, COMPOSITION: 47 ohms, $\pm 10\%$; $1/2$ watt.	RC20GF470K
R1504	RESISTOR, FIXED, COMPOSITION: 180 ohms, $+5\%$; 2 watts.	RC42GF181J
R1505	RESISTOR, FIXED, COMPOSITION: 4,700 ohms, $\pm 5\%$; 1 watt.	RC32GF472J
R1506	RESISTOR, FIXED, COMPOSITION: 10 ohms, ±5%; 1 watt.	RC32GF100J

R E F SYMBOL	DESCRIPTION	TMC PART NUMBER
R1507	RESISTOR, VARIABLE, COMPOSITION: 50,000 ohms, ±10%; nom. power rating 0.25 watt at 70°C; linear taper.	RV111U503A
R1508	RESISTOR, FIXED, COMPOSITION: 27,000 ohms, ±5%; 1/2 watt.	RC20GF273J
R1509	RESISTOR, VARIABLE, COMPOSITION: 250,000 ohms, ±10%; nom. power rating 0.25 watt at 70°C; linear taper.	RV111U254A
R1510	RESISTOR, FIXED, COMPOSITION: 1,000 ohms, ±5%; 1/2 watt.	RC20GF102J
R1511	Same as R1509.	
R1512	Same as R1510.	
R1513	RESISTOR, VARIABLE, COMPOSITION: 10,000 ohms, ±20%; 2 watts; taper A.	RV4NAYSA103BYY
R1514	RESISTOR, VARIABLE, COMPOSITION: 5,000 ohms, ±20%; 2 watts; taper A.	RV4NAYSA502BYY
R1515	RESISTOR, VARIABLE, COMPOSITION: 5,000 ohms, ±20%; 2 watts; taper A.	RV4NAYSC502BYY
R1516	NOT USED	
R1517	RESISTOR, VARIABLE, COMPOSITION: 500 ohms, ±20%; 2 watts; taper A.	RV4NAYSA501BYY
R1518	Same as R1514.	
R1519	Same as R1510.	
R1520	RESISTOR, FIXED, COMPOSITION: 68 ohms, $\pm 5\%$; 1/2 watt.	RC20GF680J
R1521	Same as R1520.	•
R1522	Same as R1502.	
R1523	Same as R1502.	
R1524	RESISTOR, FIXED, COMPOSITION: 3,900 ohms, $\pm 5\%$; 1/2 watt.	RC20GF392J
R1525	Same as R1524.	
R1526	Same as R1502.	
R1527	RESISTOR, FIXED, COMPOSITION: 43,000 ohms, ±5%; 1/2 watt.	RC20GF433J
R1528	RESISTOR, FIXED, COMPOSITION: 4,700 ohms, ±5%; 1/2 watt.	RC20GF472J
R1529 thru R1531	Same as R1528.	
R1532	RESISTOR, FIXED, COMPOSITION: 1,800 ohms, ±5%; 1/2 watt.	RC20GF182J
R1533	RESISTOR, VARIABLE, COMPOSITION: 10,000 ohms, $\pm 10\%$; nom. power rating 0.25 watt at 70° C; counter clockwise modified log taper.	RV111B103A
R1534	Same as R1528.	

MAIN CHASSIS ASSEMBLY SYMBOL SERIES 1500

REF		SYMBOL SERIES 1500
SYMBOL	DESCRIPTION	PART NUMBER
R1535	RESISTOR, FIXED, COMPOSITION: 47,000 ohms, ±5°; 1/2 watt.	RC20GF473J
R1536	Same as R1502.	
R1537	RESISTOR, FIXED, COMPOSITION: 110,000 ohms, $\pm 5\%$; 1/2 watt.	RC20GF114J
R1538	RESISTOR, FIXED, COMPOSITION: 680 ohms, ±5%; 1/2 watt.	RC20GF681J
R1541	RESISTOR, FIXED, COMPOSITION: 330 ohms, $\pm 5^{\circ}$; 1/2 watt.	RC20GF331J
R1542	RESISTOR, FIXED, COMPOSITION: 1 megohm, ±5%; 1/2 watt.	RC20GF105J
R1543	Same as R1500.	
R1544	Same as R1500.	
R1545	NOT USED	
thru R1547		
R1548	RESISTOR, FIXED, COMPOSITION: 330,000 ohms, +10%; 1/2 watt.	RC20GF334K
R1549	RESISTOR, FIXED, COMPOSITION: 22 ohms, +10%; 1/2 watt.	RC20GF220K
R1550	RESISTOR, FIXED, COMPOSITION: 1,800 ohms, +10%; 1/2 watt.	RC20GF182K
R1551	RESISTOR, FIXED, COMPOSITION: 33,000 ohms, +10%; 1/2 watt.	RC20GF333K
R1552	Same as R1500.	
R1553	Same as R1500.	
R1554	NOT USED	
R1555	NOT USED	
R1556	RESISTOR, FIXED, COMPOSITION: 100,000 ohms, $\pm 5^{\circ}$; 1/2 watt.	RC20GF104J
S1500	SWITCH, ROTARY: tap; 3 decks, 3 non-shorting type contacts: AC current type; max. voltage 115 V; max. current switching capacity 1 amp resistive; 10 amps continuous current rating; solder lug type terminals.	SW336-4
S1501	SWITCH, ROTARY: tap: 1 deck, 2 non-shorting type contacts; AC current type; max. voltage 115 V; max. current switching capacity 1 amp resistive: 10 amps continuous current rating: solder lug type terminals.	SW336-1
S1502 thru S1504	Same as \$1501.	
S1505	SWITCH, ROTARY: 2 sections, 5 positions, 30° angle of throw; non-shorting type contacts and rotors.	SW340
S1506	SWITCH, ROTARY: tap: 2 decks, 2 non-shorting type contacts; AC current type; max. voltage 115 V; max. current switching capacity 1 amp resistive; 10 amps continuous current rating; solder lug type terminals	SW336-2
S1507	SWITCH, ROTARY: 5 sections, 5 positions, 30° angle of throw; non-shorting type contacts and rotors.	SW338
S1508	SWITCH, ROTARY: 5 sections, 4 positions, 30° angle of throw, non-shorting type contacts and rotors.	SW337

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REF	ES 1500	TMC
SYMBOL	DESCRIPTION	PART NUMBER
S1509	SWITCH, ROTARY: 5 sections, 4 positions, 30° angle of throw; non-shorting type contacts and rotors.	SW339
S1510	SWITCH, ROTARY: 3 sections, 4 positions, 30° angle of throw; non-shorting type, silver alloy, contacts and rotors.	SW334
S1511	SWITCH, ROTARY: tap; 2 decks, 3 non-shorting type contacts; AC current type; max. voltage 115 V; max. current switching capacity 1 amp resistive; 10 amps continuous current rating; solder lug type terminals.	SW336-3
S1512	SWITCH, ROTARY	SW393
S1513	SWITCH, SENSITIVE: with actuator; SPDT; current rating 5.0 amps at 125/250 VAC; 7 amps resistive; 4 amps inductive at 28 VDC; style 1 type, stainless steel actuator; plastic body.	SW353-2
T1500	TRANSFORMER, HIGH FREQUENCY: toroidal core; potted plastic compound.	TF173
T1501	TRANSFORMER, AUDIO FREQUENCY: miniature; frequency range 100 cps to 20 KC; primary impedance 200,000 ohms, 6,500 ohms DC resistance; secondary impedance 1,000 ohms, 245 ohms DC resistance; fully enclosed black molded epoxy case.	TF246-6X
TB1500	TERMINAL BOARD, BARRIER: 12 terminals; 6-32 thd. x $1/4$ " lg. binder head screws; phenolic black bakelite.	TM100-12
TB1501	Same as TB1500.	
TB1502	TERMINAL BOARD, BARRIER: 11 terminals; 6-32 thd. x $1/4$ " lg. binder head screws; phenolic black bakelite. (Supplied when Antenna Coupler, TTC-1 is required by customer)	TM100-11
V1500	TUBE, ELECTRON: power pentode; 9 pin miniature.	6 GK 6
V1501	TUBE, ELECTRON: twin tetrode; 7 pin miniature.	8117
W1500	CABLE ASSEMBLY: RF; consists of various lengths of RG188/U coaxial cable; no ferrules.	CA418-6
W1501	WIRING HARNESS, BRANCHED, ELECTRICAL: consists of various lengths and colors of MWC and LWC wire; RG174/U coaxial cable; insulation sleeving; cable clamps and hardware; 9 cable connectors, J1500, J1507 thru J1514.	CA833
W1502	LEAD, ELECTRICAL: consists of 2" length of MWC wire and terminal lugs.	CA409-32-2.00
XDS1500	LAMPHOLDER: accommodates TMC part No. BI112 type lamp; phosphor bronze, silver plated and gold finished contacts; black anodized aluminum body.	TS164
XV1500	SOCKET, ELECTRON TUBE: 9 pin miniature.	TS103P01
XV1501	SOCKET, ELECTRON TUBE: 7 pin contact.	TS168-1

IF AND AUDIO RECEIVER BOARD ASSEMBLIES MAIN CHASSIS (SYMBOL SERIES 1600)

r	MAIN CHASSIS	(SYMBOL SERIES 1600)
REF SYMBOL	DESCRIPTION	PART NUMBER
C1601	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 100,000 uuf, +80% -20%; 100 WVDC.	CC100-28
C1602	CAPACITOR, VARIABLE, MICA DIELECTRIC: 280 uuf max. when tight, 25 uuf max. at 3 turns; 175 WVDC.	CV114-1
C1603	CAPACITOR, FIXED, MICA DIELECTRIC: 1,800 uuf, +2%; 500 WVDC.	CM100-13
C1604	CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 10-75 uuf, operating temperature range -55°C to +85°C; 350 WVDC.	CV109-8
C1605	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 200,000 uuf, +80% -20%; 25 WVDC.	CC100-33
C1606	Same as C1601.	
C1607	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 25,000 uuf, +80% -20%; 500 WVDC.	CC100-25
C1608	CAPACITOR, FIXED, MICA DIELECTRIC: 68 uuf, ±2%; 500 WVDC; char. C.	CM15C680G
C1609	CAPACITOR, FIXED, MICA DIELECTRIC: 510 uuf, ±5%; 500 WVDC; char. B.	CM15B511J
C1610	CAPACITOR, FIXED, MICA DIELECTRIC: 180 uuf, +2%; 500 WVDC; straight wire leads.	CM111D181G5S
C1611	Same as C1610.	
C1612	Same as C1607.	
C1613	Same as C1607.	
C1614	CAPACITOR, FIXED, ELECTROLYTIC: 25 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-25-15
C1615	CAPACITOR, FIXED, ELECTROLYTIC: 50 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-50-15
C1616	CAPACITOR, FIXED, ELECTROLYTIC: 4 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-4-15
C1617	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 10,000 uuf, GMV; 500 WVDC.	CC100-16
C1618	Same as C1605.	
C1619	Same as C1605.	
C1620	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 5,000 uuf, GMV; 500 WVDC.	CC100-15
C1621	CAPACITOR, FIXED, MICA DIELECTRIC: 270 uuf, +5%; 500 WVDC; char. C.	CM15C271J
C1622	Same as C1617.	
C1623	CAPACITOR, FIXED, MICA DIELECTRIC: 47 uuf, ±5%; 500 WVDC; char. C.	CM15C470J
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IF AND AUDIO RECEIVER BOARD ASSEMBLIES MAIN CHASSIS (SYMBOL SERIES 1600)

	MAIN CHASSIS (SYMBOL SERIES 1600)		
R E F SYMBOL	DESCRIPTION	TMC PART NUMBER	
C1624	Same as C1601.		
C1625	Same as C1601.		
C1626	Same as C1601.		
C1627	Same as C1621.		
C1628	Same as C1605.		
C1629	CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 8-50 uuf; operating temperature range -55°C to +85°C; 350 WVDC.	CV109-6	
C1630	CAPACITOR, FIXED, MICA DIELECTRIC: 24 uuf, ±5%; 500 WVDC; char. C.	CM15C240J	
C1631	Same as C1629.		
C1632	Same as C1630.		
C1633	Same as C1621.		
C1634	Same as C1605.		
C1635	Same as C1601.		
C1636	Same as C1601.		
C1637	Same as C1617.		
C1638	Same as C1605.		
C1639	Same as C1617.		
C1640	CAPACITOR, FIXED, ELECTROLYTIC: 6 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-6-15	
C1641	Same as C1614.		
C1642	Same as C1617.		
C1643	Same as C1601.		
C1644	Same as C1601.		
C1645	CAPACITOR, FIXED, MICA DIELECTRIC: 1,000 uuf, +2%; 500 WVDC; char. F.	CM20F102G	
C1646	CAPACITOR, FIXED, ELECTROLYTIC: 10 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-10-15	
C1647	Same as C1615.		
C1648	Same as C1646.		
C1649	Same as C1615.		
C1650	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 1,000 uuf, GMV; 500 WVDC.	CC100-29	
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, —————	MAIN CHASSIS	(SYMBOL SERIES 1600)
R E F SYMBOL	DESCRIPTION	TMC PART NUMBER
C1651	Same as C1601.	
C1652	Same as C1615.	
C1653	Same as C1601.	
C1654	Same as C1605.	
C1655	CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 9-35 uuf; operating temperature range -55°C to +125°C; 100 WVDC.	CV112-2
C1656	Same as C1655.	
C1657	Same as C1601.	
C1658	CAPACITOR, FIXED, MICA DIELECTRIC: 10 uuf, +5%; 500 WVDC; char. C.	CM15C100J
C1659	NOT USED	
C1660	CAPACITOR, FIXED, ELECTROLYTIC: 200 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-200-15
C1661	CAPACITOR, FIXED, MICA DIELECTRIC: 680 uuf, ±5%; 500 WVDC; straight wire leads.	CM111E681J5S
CR1601	SEMICONDUCTOR DEVICE, DIODE: germanium; max. peak inverse voltage 60 V; continuous average forward current 50 ma; max. peak forward current 150 ma; max. surge current 500 ma; max. inverse current 500 ua at 50 volts or 30 ua at 10 volts.	1N3 4 A
CR1602 thru CR1604	Same as CR1601.	
CR1605	SEMICONDUCTOR DEVICE, DIODE: silicon; forward current 5 ma at 1 volt; reverse current 625 ua at 100 volts, 25°C.	1N68
CR1606	Same as CR1605.	
CR1607	Same as CR1605.	
EQ1601 thru EQ1615	NOT USED.	
EQ1616	HEAT SINK: transistor heat dissipating element.	HD101-1
EQ1617	Same as EQ1616.	
FL1601	FILTER, BANDPASS: operating frequency 250 KC; bandwidth, 250.3 KC to 253.3 KC; input and output impedance 100K ohms nom.; hermetically sealed brass case.	FX195-1
K1601	RELAY, ARMATURE: 4PDT; 185 ohms, +10% DC resistance; operating voltage 12 VDC; current rating 60 ma; 700 mu at 25°C; 14 contacts rated for 2 amps at 20 VDC resistance; clear high impact styrene dust cover case.	RL136-2
L1601	COIL, RADIO FREQUENCY: fixed; 47,000 uh, ±5%; 452 ohms DC resistance; current rating 27 ma; molded case.	CL275-473

MAIN CHASSIS (SYMBOL SERIES 1600) REF		
SYMBOL	DESCRIPTION	PART NUMBER
L1602	COIL, RADIO FREQUENCY: fixed; . 220 uh, +10%; current rating 200 ma; molded case.	CL140-6
L1603	NOT USED.	
L1604	Same as L1602.	
L1605	Same as L1602.	
L1606	NOT USED.	
L1607	COIL, RADIO FREQUENCY: fixed; 1,000 uh, ±5%; 1,600 ohms DC resistance; current rating 140 ma; molded case.	CL275-102
L1608	Same as L1602.	
L1609	NOT USED	
L1610	COIL, RADIO FREQUENCY: fixed; 150 uh, $\pm 5\%$; 3.3 ohms DC resistance; current rating 315 ma; molded case.	CL275-151
Q1601	TRANSISTOR: germanium; PNP; JEDEC type 2N2084 transistor with a controlled hie limit of 100-150; JEDEC type TO33 case.	TX109
Q1602	Same as Q1601.	
Q1603	TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled hie limit of 60-75; JEDEC type TO9 case.	TX107
Q1604	Same as Q1603.	
Q1605 thru Q1609	Same as Q1601.	
Q1610	TRANSISTOR: germanium; PNP; collector to base voltage 45 V; collector to emitter voltage 30 V; emitter to base voltage 15 V; collector current (continuous), 500 ma DC; collector dissipation 200 mw; junction-storage temperature range -65°C to +100°C.	2N1190
Q1611	TRANSISTOR: NPN; silicon mesa; collector to base voltage 60 V; collector to emitter voltage 40 V; emitter to base voltage 5 V; collector current 175 ma; power dissipation 2 watts at 25°C; junction temperature 175°C; hermetically sealed metal case.	2N697
Q1612	TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled hee limit of 80-150; JEDEC type TO5 case.	TX106
Q1613 thru Q1615	Same as Q1603.	
Q1616	TRANSISTOR: germanium; PNP; collector to base and collector to emitter voltage 60 V; emitter to base voltage 20 V; collector current 3 amps, base current 1 amp; junction and storage temperature range -55°C to +100°C; power dissipation 20 watts at 25°C.	2N1039
Q1617	Same as Q1616.	
Q1618	TRANSISTOR: germanium; PNP; JEDEC type 2N1370-7 transistor with a controlled hie limit of 120-150; JEDEC type TO5 case.	TX108
	with a controlled me limit of 120-150; JEDEC type 105 case.	,

7	MAIN CHASSIS (SYMBOL SERIES 1600)	
REF SYMBOL	DESCRIPTION	TMC PART NUMBER
Q1619	Same as Q1603.	
Q1620	Same as Q1603.	
Q1621	TRANSISTOR: germanium; PNP; max. collector dissipation 300 mw; Fab. = 6 MC; collector current 1 ma; collector cut-off current 100 ua; hfe limit 80.	2N2001
R1601	RESISTOR, FIXED, COMPOSITION: 1,000 ohms, ±5%; 1/2 watt.	RC20GF102J
R1602	RESISTOR, FIXED, COMPOSITION: 220 ohms, +5%; 1/2 watt.	RC20GF221J
R1603	RESISTOR, FIXED, COMPOSITION: 10,000 ohms, ±5%; 1/2 watt.	RC20GF103J
R1604	Same as R1601.	
R1605	Same as R1603.	
R1606	NOT USED.	
R1607	NOT USED.	
R1608	Same as R1601.	
R1609	Same as R1601.	
R1610	RESISTOR, FIXED, COMPOSITION: 470 ohms, ±5%; 1/2 watt.	RC20GF471J
R1611	Same as R1603.	
R1612	RESISTOR, VARIABLE, COMPOSITION: 500 ohms, ±10%; nom. power rating 0.25 watt at 70°C; linear taper.	RV111U501A
R1613	Same as R1603.	
R1614	RESISTOR, FIXED, COMPOSITION: 4,700 ohms, ±5%; 1/2 watt.	RC20GF472J
R1615	Same as R1614.	
R1616	RESISTOR, FIXED, COMPOSITION: 22 ohms, ±5%; 1/2 watt.	RC20GF220J
R1617	Same as R1603.	
R1618	RESISTOR, FIXED, COMPOSITION: 3,300 ohms, $\pm 5\%$; $1/2$ watt.	RC20GF332J
R1619	Same as R1601.	
R1620	Same as R1601.	
R1621	Same as R1614.	
R1622	Same as R1601.	
R1623	Same as R1601.	
R1624	Same as Ribi4.	
R16 2 5	Same as R1603.	
R16 2 6	Same as R1601.	

R E F SYMBOL	DESCRIPTION	TMC PART NUMBER
R1627	Same as R1614.	
R1628	Same as R1603.	
R16 2 9	RESISTOR, FIXED, COMPOSITION: 560 ohms, ±5%; 1/2 watt.	RC20GF561J
R1630	RESISTOR, FIXED, COMPOSITION: 6,800 ohms, ±5%; 1/2 watt.	RC20GF682J
R1631	Same as R1601.	
R1632	Same as R1603.	
R1633	Same as R1603.	
R1634	RESISTOR, FIXED, COMPOSITION: 2,700 ohms, ±5%; 1/2 watt.	RC20GF272J
R1635	Same as R1601.	
R1636	Same as R1602.	
R1637	RESISTOR, FIXED, COMPOSITION: 100,000 ohms, ±5%; 1/2 watt.	RC20GF104J
R1638	Same as R1603.	
R1639	Same as R1614.	
R1640	RESISTOR, FIXED, COMPOSITION: 22 ohms, ±5%; 2 watts.	RC42GF220J
R1641	Same as R1618.	
R1642	Same as R1603.	
R1643	Same as R1618.	
R1644	Same as R1618.	
R1645	RESISTOR, FIXED, COMPOSITION: 680 ohms, $\pm 5\%$; 1/2 watt.	RC20GF681J
R1646	RESISTOR, FIXED, COMPOSITION: 10 ohms, $\pm 5\%$; 1/2 watt.	RC20GF100J
R1647	Same as R1637.	
R1648	NOT USED.	
R1649	NOT USED.	
R1650	NOT USED.	
R1651	Same as R1603.	
R1652	RESISTOR, FIXED, COMPOSITION: 3,900 ohms, $\pm 5\%$; 1/2 watt.	RC20GF392J
R1653	RESISTOR, FIXED, COMPOSITION: 2,200 ohms, $\pm 5\%$; 1/2 watt.	RC20GF222J
R1654	Same as R1601.	
R1655	Same as R1637.	
R1656	Same as R1618.	

R E F SYMBOL	DESCRIPTION	TMC PART NUMBER
R1657	RESISTOR, FIXED, COMPOSITION: 22,000 ohms, ±5%; 1/2 watt.	RC20GF223J
R1658	Same as R1653.	
R1659	RESISTOR, FIXED, COMPOSITION: 33 ohms, ±5%; 1/2 watt.	RC20GF330J
R1660	RESISTOR, FIXED, COMPOSITION: 3.3 ohms, ±5%; 1 watt.	RC32GF3R3J
R1661	Same as R1610.	
R1662	RESISTOR, FIXED, COMPOSITION: 1,800 ohms, ±5%; 1/2 watt.	RC20GF182J
R1663	Same as R1612.	
R1664	NOT USED	
R1665	Same as R1614.	
R1666	Same as R1640.	
R1667	RESISTOR, FIXED, COMPOSITION: 27 ohms, ±5%; 2 watts.	RC42GF270J
R1668	Same as R1601.	
T1601	TRANSFORMER, INTERMEDIATE FREQUENCY: fixed; operating frequency 1.75 mc; nom. primary inductance 4.5 uhy, \pm . 200 uhy; 4 terminals, wire lead type.	TZ126
T1602	TRANSFORMER, PULSE: 3 windings; winding number one, 4.7 mh; turns ratio 5:5:1.	TF228K15
T1603	TRANSFORMER, AUDIO FREQUENCY: fixed; primary impedance 4,000 ohms, CT; DC resistance 370 ohms, ±20%; secondary impedance 600 ohms, CT; DC resistance 60 ohms, ±20%; operating frequency range 200-15,000 cps; frequency response ±3 db at 250 to 3,500 cps.	TF267-3
T1604	TRANSFORMER, AUDIO FREQUENCY: fixed; primary impedance 3,000 ohms, CT; DC resistance 260 ohms, ±20%; secondary impedance 1,000 ohms, CT; DC resistance 105 ohms, ±20%; operating frequency range 200-15,000 cps; frequency response ±3 db at 250 to 3,500 cps.	TF267-2
T1605	TRANSFORMER, AUDIO FREQUENCY: fixed; primary impedance 500 ohms, CT; DC resistance 26 ohms, +20%; secondary impedance 3.2 ohms; DC resistance 0.3 ohms, +20%; operating frequency range 150-45,000 cps; frequency response +0-2 db at 1,000 cps, ref; 150-45,000 cps.	TF267-5
XY1601	SOCKET, CRYSTAL: 2 silver plated beryllium copper contacts; for crystals having a 0.050 pin dia. and 0.486 spacing between pins.	TS104-2
XY1602	Same as XY1601.	
XY1603	Same as XY1601.	
Y1601	CRYSTAL UNIT, QUARTZ: 250 KC, ±.002%; operating temperature range 75°C, ±5°C; parallel resonance; load capacitance 20 uuf, ±0.5 uuf; HC-6/U type holder.	CR47A/U250. 000KC

IF AND AUDIO RECEIVER BOARD ASSEMBLIES MAIN CHASSIS (SYMBOL SERIES 1600)

R E F SYMBOL	(SYMBOL SERIES 1600) DESCRIPTION	TMC PART NUMBER
Y1602	CRYSTAL UNIT, QUARTZ: 2 MC, +.005%; operating temperature range -55°C to +30°C; max. capacitance 7.0 uuf; parallel resonance; load capacitance 32.0 uuf, +0.5 uuf; HC-6/U type holder.	CR18A/U2.00- 0000MC
Y1603	CRYSTAL UNIT, QUARTZ: 1.5 MC, ±.005%; operating temperature range -55°C to +30°C; max. capacitance 7.0 uuf; parallel resonance; load capacitance 32.0 uuf, ±0.5 uuf; HC-6/U type holder.	CR18A/U1.500- 000MC

	MAIN CHASSIS	(SYMBOL SERIES 1700)
R E F SYMBO	L DESCRIPTION	TMC PART NUMBER
C1701	CAPACITOR, FIXED, ELECTROLYTIC: 6 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-6-15
C1702	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 200,000 uuf, +80% -20%; 25 WVDC.	CC100-33
C1703	CAPACITOR, FIXED, ELECTROLYTIC: 50 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized, insulated tubular case.	CE105-50-15
C1704	Same as C1701.	
C1705	CAPACITOR, FIXED, ELECTROLYTIC: 10 uf, -10% +150% at 120 cps at 25°C; i5 WVDC; polarized, insulated tubular case.	CE105-10-15
C1706	Same as C1703.	
C1707	Same as C1705.	
C1708	CAPACITOR, FIXED, ELECTROLYTIC: 4 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-4-15
C1709	Same as C1701.	
C1710	Same as C1703.	
C1711	Same as C1702.	
C1712	CAPACITOR, FIXED, ELECTROLYTIC: 20 uf, -10% +150% at 120 cps at 25°C; 15 WVDC; polarized; insulated tubular case.	CE105-20-15
C1713	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 10,000 uuf, GMV; 500 WVDC.	CC100-16
C1714	Same as C1713.	
C1715	CAPACITOR, VARIABLE MICA DIELECTRIC: 280 uuf max. when tight, 25 uuf max. at 3 turns; 175 WVDC.	CV114-1
C1716	CAPACITOR, FIXED, MICA DIELECTRIC: 160 uuf, ±5%; 500 WVDC; char. F.	CM151'161J
C1717	CAPACITOR, FIXED, MICA DIELECTRIC: 100 uuf, ±5%; 500 WVDC; char. F.	CM15F101J
C1718	CAPACITOR, FIXED, MICA DIELECTRIC: 180 uuf, ±5%; 500 WVDC; char. B.	CM15B181J
C1719	Same as C1718.	
C1720	CAPACITOR, FIXED, MICA DIELECTRIC: 180 uuf, ±2%; 500 WVDC; straight wire leads.	CM111D181G5S
C1721	Same as C1720.	
C1722	CAPACITOR, FIXED, MICA DIELECTRIC: 1,000 uuf, ±5%; 500 WVDC; char. B.	CM20B102J
C1723	Same as C1702.	
C1724	Same as C1702.	
	A second	L

R E F SYMBOL	(SYMBOL SERIES 1700) DESCRIPTION	TMC PART NUMBER
C1725	Same as C1715.	
C1726	CAPACITOR, FIXED, MICA DIELECTRIC: 1,500 uuf, $\pm 2\%$; 500 WVDC; char. F.	CM100-10
C1727	CAPACITOR, FIXED, CERAMIC DIELECTRIC: 100,000 uuf, +80% -20%; 100 WVDC.	CC100-28
C1728	Same as C1702.	
C1729	Same as C1705.	
C1730	Same as C1715.	
C1731	Same as C1726.	
C1732	Same as C1727.	
C1733	CAPACITOR, FIXED, MICA DIELECTRIC: 47 uuf, $\pm 5\%$; 500 WVDC; char. B.	CM15B470J
C1734	NOT USED	
C1735	CAPACITOR, FIXED, MICA DIELECTRIC: 270 uuf, $\pm 5\%$; 500 WVDC; char. F.	CM15F271J
C1736	CAPACITOR, FIXED, MICA DIELECTRIC: 5,100 uuf, $\pm 10\%$; 300 WVDC; straight wire leads.	CM112E512K3S
C1737	Same as C1702.	
C1738	Same as C1727.	
C1739	Same as C1702.	
C1740	Same as C1713.	
C1741	Same as C1727.	
C1742	Same as C1702.	
C1743	Same as C1713.	
C1744	Same as C1727.	
C1745	Same as C1722.	
C1746	CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 8-50 uuf; operating temperature range -55°C to +85°C; 350 WVDC.	CV109-6
C1747	CAPACITOR, FIXED, MICA DIELECTRIC: 24 uuf, $\pm 5\%$; 500 WVDC; char. C.	CM15C240J
C1748	Same as C1727.	
C1749	Same as C1746.	
C1750	Same as C1747.	
C1751	Same as C1735.	

IF AND AUDIO TRANSMITTER BOARD ASSEMBLIES MAIN CHASSIS (SYMBOL SERIES 1700)

C1752	<i>-</i>	MAIN CHASSIS	(SYMBOL SERIES 1700)
C1753	-	DESCRIPTION	1
C1754 Same as C1735. C1755 Same as C1702. C1756 thru C1760 Same as C1727. C1761 Same as C1722. C1762 CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 9-35 uuf; operating temperature range -55°C to +125°C; 100 WVDC. C1763 Same as C1762. C1764 Same as C1702. C1764 Same as C1702. CR1701 SEMICONDUCTOR DEVICE, DIODE: germanium; max. peak inverse voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current 500 us at 50 volts or 30 us at 10 volts. CR1702 thru CR1709 FILTER, SIDEBAND: low 1747.000 Kc max. at 3 db, high 1749.700 Kc min. at 60 db, high 1751.000 max. at 60 db; for USB operation. CIL RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Same as L1701. TRANSISTOR: germanium: NPN; JEDEC type 2N1308 transistor with a controlled hie limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type T09 case. TRANSISTOR: germanium; PNP; JEDEC type T09 case. Same as Q1702. TRANSITOR: germanium; PNP; JEDEC type T09 case. Same as Q1702. THANSITOR: germanium; PNP, max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 us; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 us; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 us;	C1752	Same as C1702.	
C1755 Same as C1702. C1756 thru C1760 C1761 Same as C1727. C1762 CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 9-35 uuf; operating temperature range -55°C to +125°C; 100 WVDC. C1763 Same as C1762. C1764 Same as C1702. CR1701 SEMICONDUCTOR DEVICE, DIODE: germanium; max. peak inverse voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current 500 us at 50 volts or 30 us at 10 volts. CR1702 thru CR1709 FL1702 FILTER, SIDEBAND: low 1747.000 Kc max. at 3 db, high 1749.700 Kc min. at 60 db, high 1751.000 max. at 60 db; for USB operaction. COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 CR1702 TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled life limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type T09 case. Q1703 Same as Q1702. Q1705 Same as Q1701. CR1706 Same as Q1702. Q1707 Same as Q1702. Q1708 TRANSITOR: germanium; PNP, max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 us; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 us;	C1753	Same as C1727.	
C1756	C1754	Same as C1735.	
C1760 C1761 Same as C1702. C1762 CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 9-35 uuf; operating temperature range -55°C to +125°C; 100 WVDC. C1763 Same as C1762. C1764 Same as C1702. C1764 Same as C1702. C1765 SEMICONDUCTOR DEVICE, DIODE: germanium; max. peak inverse voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current 500 ua at 50 volts or 30 ua at 10 volts. C1702 thru C1709 C1702 thru C1709 C1704 C1705 C1705	C1755	Same as C1702.	
C1762 CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 9-35 uuf; operating temperature range -55°C to +125°C; 100 WVDC. C1763 Same as C1762. C1764 Same as C1702. CR1701 SEMICONDUCTOR DEVICE, DIODE: germanium; max. peak inverse voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current 500 ma; max. surge current 500 ma; max. inverse current 500 ma; max. at 3 db, high 1749.700 Kc min. at 3 db, low 1745.000 Kc min. at 60 db, high 1751.000 max. at 60 db; for USB operation. COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Same as L1701. TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled high limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; NPP; JEDEC type 2N1370 transistor with a controlled high limit of 60-75; JEDEC type T09 case. Q1703 thru Q1705 Same as Q1702. Q1706 Same as Q1701. Q1707 Same as Q1702. TRANSITOR: germanium; PNP, max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	thru	Same as C1727.	
ating temperature range -55°C to +125°C; 100 WVDC. Same as C1762. C1764 Same as C1702. CR1701 SEMICONDUCTOR DEVICE, DIODE: germanium; max. peak inverse voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current 500 ua at 50 volts or 30 ua at 10 volts. CR1702 thru CR1709 FILTR, SIDEBAND: low 1747.000 Kc max. at 3 db, high 1749.700 Kc min. at 3 db, low 1745.000 Kc min. at 60 db, high 1751.000 max. at 60 db; for USB operation. COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Q1701 TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled high limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled high limit of 60-75; JEDEC type T09 case. Q1703 thru Q1705 Q1706 Same as Q1702. TRANSITOR: germanium; PNP, max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	C1761	Same as C1702.	
C1764 Same as C1702. CR1701 SEMICONDUCTOR DEVICE, DIODE: germanium; max. peak inverse voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current 500 ua at 50 volts or 30 ua at 10 volts. CR1702 Same as CR1701. FILTER, SIDEBAND: low 1747.000 Kc max. at 3 db, high 1749.700 Kc min. at 3 db, low 1745.000 Kc min. at 60 db, high 1751.000 max. at 60 db; for USB operation. COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Same as L1701. TRANSISTOR: germanium; NPN; JEDEC type 2N1306 transistor with a controlled hie limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled hie limit of 60-75; JEDEC type T09 case. Same as Q1702. Q1703 thru Q1705 Same as Q1702. Q1706 Same as Q1701. Q1707 Same as Q1702. Q1708 TRANSITOR: germanium; PNP, max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	C1762	CAPACITOR, VARIABLE, CERAMIC DIELECTRIC: 9-35 uuf; operating temperature range -55°C to +125°C; 100 WVDC.	CV112-2
CR1701 SEMICONDUCTOR DEVICE, DIODE: germanium; max. peak inverse voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current 500 ua at 50 volts or 30 ua at 10 volts. CR1702 CR1702 FILTER, SIDEBAND: low 1747.000 Kc max. at 3 db, high 1749.700 Kc min. at 3 db, low 1745.000 Kc min. at 60 db, high 1751.000 max. at 60 db; for USB operation. COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Q1701 TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled high limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled high limit of 60-75; JEDEC type T09 case. Q1703 thru Q1705 Q1706 Same as Q1702. TRANSITOR: germanium; PNP, max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	C1763	Same as C1762.	
voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current 500 ua at 50 volts or 30 ua at 10 volts. CR1702 thru CR1709 FILTER, SIDEBAND: low 1747.000 Kc max. at 3 db, high 1749.700 Kc min. at 3 db, low 1745.000 Kc min. at 60 db, high 1751.000 max. at 60 db; for USB operation. COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Q1701 TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled high limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled high limit of 60-75; JEDEC type T09 case. Q1703 thru Q1705 Q1706 Same as Q1702. Q1707 Same as Q1702. TRANSITOR: germanium; PNP, max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua; 2N2001	C1764	Same as C1702.	
thru CR1709 FL1702 FILTER, SIDEBAND: low 1747.000 Kc max. at 3 db, high 1749.700 Kc min. at 3 db, low 1745.000 Kc min. at 60 db, high 1751.000 max. at 60 db; for USB operation. COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Q1701 TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled hfe limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled hfe limit of 60-75; JEDEC type T09 case. Q1703 thru Q1705 Q1706 Same as Q1702. TRANSITOR: germanium; PNP, max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	CR1701	voltage 60 V; continuous average forward current 50 ma; max. peak forward 150 ma; max. surge current 500 ma; max. inverse current	1N34A
L1701 COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Same as L1701. TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled high limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled high limit of 60-75; JEDEC type T09 case. Q1703 Same as Q1702. Q1706 Same as Q1701. Q1707 Same as Q1702. TRANSITOR: germanium; PNP; max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	thru	Same as CR1701.	
L1701 COIL, RADIO FREQUENCY: fixed; .220 uh, ±10%; current rating 200 ma; molded case. L1702 thru L1705 Same as L1701. Q1701 TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled high limit of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled high limit of 60-75; JEDEC type T09 case. Q1703 thru Q1705 Same as Q1702. Q1706 Same as Q1701. Q1707 TRANSITOR: germanium; PNP; max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	FL1702	1/49./00 Kc min. at 3 db, low 1745.000 Kc min. at	FX10014-2
thru L1705 Q1701 TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled him it of 80-150; JEDEC type T05 case. Q1702 TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled him it of 60-75; JEDEC type T09 case. Q1703 thru Q1705 Same as Q1702. Q1706 Same as Q1701. Q1707 TRANSITOR: germanium; PNP; max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	L1701	COIL, RADIO FREQUENCY: fixed; .220 uh, +10%; current rating	CL140-6
a controlled high limit of 80-150; JEDEC type T05 case. TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled high limit of 60-75; JEDEC type T09 case. Same as Q1702. Same as Q1701. Q1706 Same as Q1701. Q1707 Same as Q1702. TRANSITOR: germanium; PNP; max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	thru	Same as L1701.	
a controlled high limit of 60-75; JEDEC type T09 case. Q1703 thru Q1705 Q1706 Same as Q1701. Q1707 Same as Q1702. TRANSITOR: germanium; PNP; max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	Q1701	TRANSISTOR: germanium; NPN; JEDEC type 2N1308 transistor with a controlled hie limit of 80-150; JEDEC type T05 case.	TX106
thru Q1705 Q1706 Same as Q1701. Q1707 Same as Q1702. Q1708 TRANSITOR: germanium; PNP; max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	Q1702	TRANSISTOR: germanium; PNP; JEDEC type 2N1370 transistor with a controlled hee limit of 60-75; JEDEC type T09 case.	TX107
Q1707 Same as Q1702. Q1708 TRANSITOR: germanium; PNP; max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	thru	Same as Q1702.	
Q1708 TRANSITOR: germanium; PNP; max. collector dissipation 300 mw; fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	Q1706	Same as Q1701.	
fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	Q1707	Same as Q1702.	
	Q1708	fab. = 6 mc; collector current 1 ma; collector cut-off current 100 ua;	2N2001

IF AND AUDIO TRANSMITTER BOARD ASSEMBLIES

REF	(SYMBOL SERIES 1700) DESCRIPTION	TMC PART NUMBER
Q1709	TRANSISTOR: germanium; PNP; JEDEC type 2N2084 transistor with a controlled hee limit of 100-150; JEDEC type T033 case.	TX109
Q1710 thru Q1717	Same as Q1709.	
R1701	RESISTOR, FIXED, COMPOSITION: 22,000 ohms, $\pm 5\%$; 1/2 watt.	RC20GF223J
R1702	RESISTOR, FIXED, COMPOSITION: 10,000 ohms, ±5%; 1/2 watt.	RC20GF103J
R1703	NOT USED	
R1704	RESISTOR, FIXED, COMPOSITION: 4,700 ohms, $\pm 5\%$; $1/2$ watt.	RC20GF472J
R1705	RESISTOR, FIXED, COMPOSITION: 2,200 ohms, $\pm 5\%$; $1/2$ watt.	RC20GF222J
R1706	Same as R1702.	
R1707	Same as R1705.	
R1708	RESISTOR, FIXED, COMPOSITION: 68,00 ohms, +5%; 1/2 watt.	RC20GF683J
R1709	Same as R1702.	
R1710	RESISTOR, FIXED, COMPOSITION: 3,300 ohms, ±5%; 1/2 watt.	RC20GF332J
R1711	Same as R1710.	
R1712	RESISTOR, FIXED, COMPOSITION: 220 ohms, $\pm 5\%$; 1/2 watt.	RC20GF221J
R1713	Same as R1702.	
R1714	Same as R1702.	
R1715	RESISTOR, FIXED, COMPOSITION: 8,200 ohms, $\pm 5\%$; 1/2 watt.	RC20GF822J
R1716	RESISTOR, FIXED, COMPOSITION: 3,900 ohms, $\pm 5\%$; 1/2 watt.	RC20GF392J
R1717	RESISTOR, FIXED, COMPOSITION: 1,000 ohms, $\pm 5\%$; 1/2 watt.	RC20GF102J
R1718	RESISTOR, VARIABLE, COMPOSITION: 500 ohms, ±10%; nom. power rating 0.25 watt at 70°C; linear taper.	RV111U501A
R1719	RESISTOR, VARIABLE, COMPOSITION: 250,000 ohms, ±10%; nom. power rating 0.25 watt at 70°C; linear taper.	RV111U254A
R1720	RESISTOR, FIXED, COMPOSITION: 1.5 megohms, $\pm 5\%$; $1/2$ watt.	RC20GF155J
R1721	NOT USED	
R1722	Same as R1702.	
R1723	RESISTOR, FIXED, COMPOSITION: 5,600 ohms, $\pm 5\%$; $1/2$ watt.	RC20GF562J
R1724	Same as R1704.	
R1725	Same as R1702.	
R1726	Same as R1717.	

REF SYMBOL	DESCRIPTION	TMC PART NUMBER
R1727	Same as R1723.	
R1728	RESISTOR, FIXED, COMPOSITION: 100,000 ohms, ±5%; 1/2 watt.	RC20GF104J
R1729	RESISTOR, FIXED, COMPOSITION: 150,000 ohms, $\pm 5\%$; $1/2$ watt.	RC20GF154J
R1730	Same as R1704.	
R1731	Same as R1705.	
R1732	Same as R1715.	
R1733	Same as R1729.	
R1734	RESISTOR, FIXED, COMPOSITION: 33 ohms, $\pm 5\%$; 1 watt.	RC32GF330J
R1735	Same as R1729.	
R1736 thru R1739	Same as R1717.	
R1740	RESISTOR, FIXED, COMPOSITION: 330 ohms, ±5%; 1/2 watt.	RC20GF331J
R1741	Same as R1740.	
R1742	RESISTOR, VARIABLE, COMPOSITION: 10,000 ohms, $\pm 10\%$; nom. power rating 0.25 watt at 70° C; linear taper.	RV111U103A
R1743	RESISTOR, FIXED, COMPOSITION: 30,000 ohms, $\pm 5\%$; $1/2$ watt.	RC20GF303J
R1744	Same as R1717.	ŕ
R1745	Same as R1717.	
R1746	Same as R1702.	
R1747	Same as R1702.	
R1748	Same as R1742.	
R1749	Same as R1702.	
R1750	Same as R1717.	
R1751	Same as R1704.	
R1752	Same as R1717.	
R1753	NOT USED	
R1754	Same as R1717.	
R1755	Same as R1704.	
R1756	Same as R1717.	
R1757	Same as R1717.	
R1758	Same as R1702.	

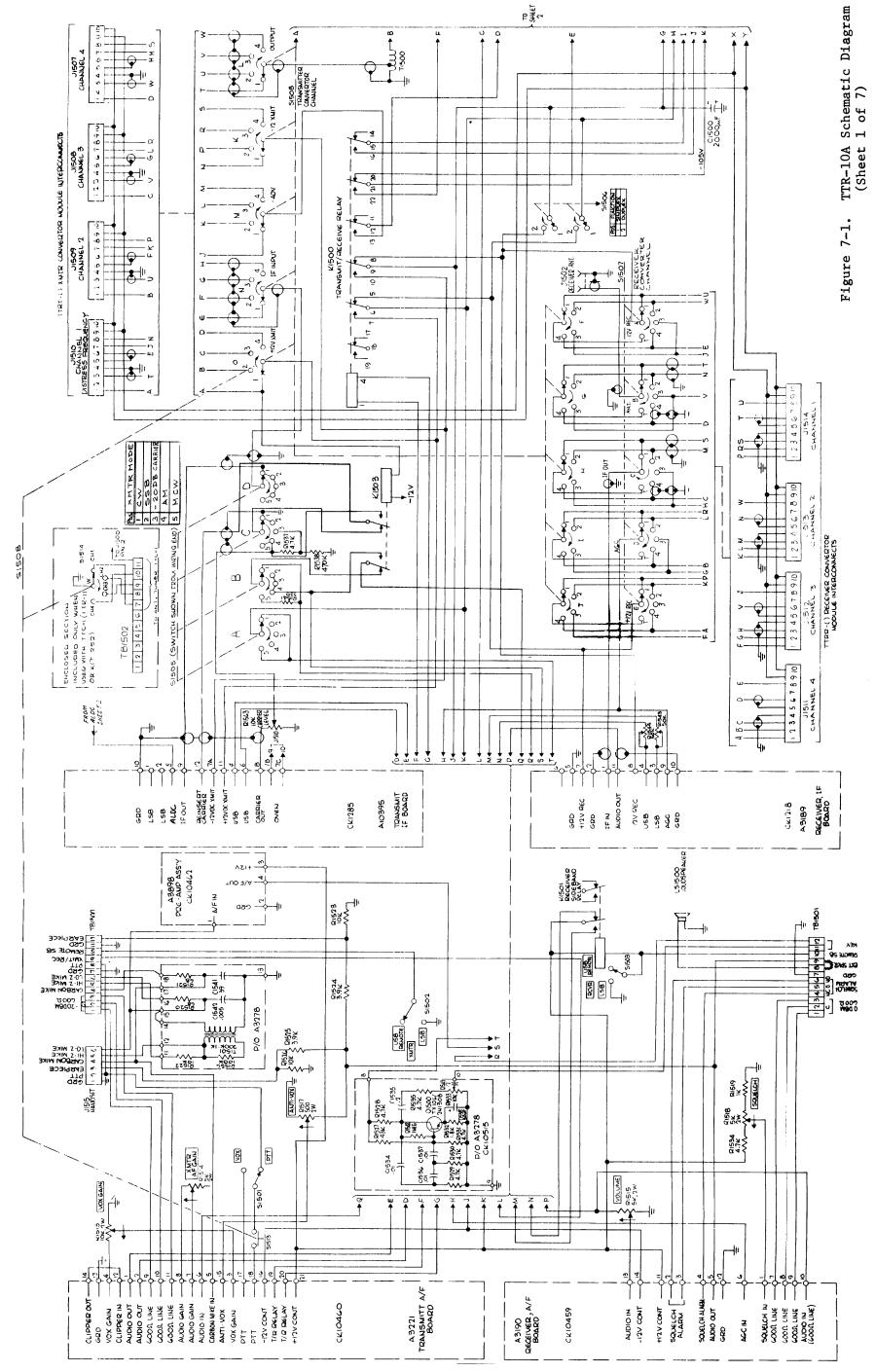
IF AND AUDIO TRANSMITTER BOARD ASSEMBLIES MAIN CHASSIS (SYMBOL SERIES 1700)

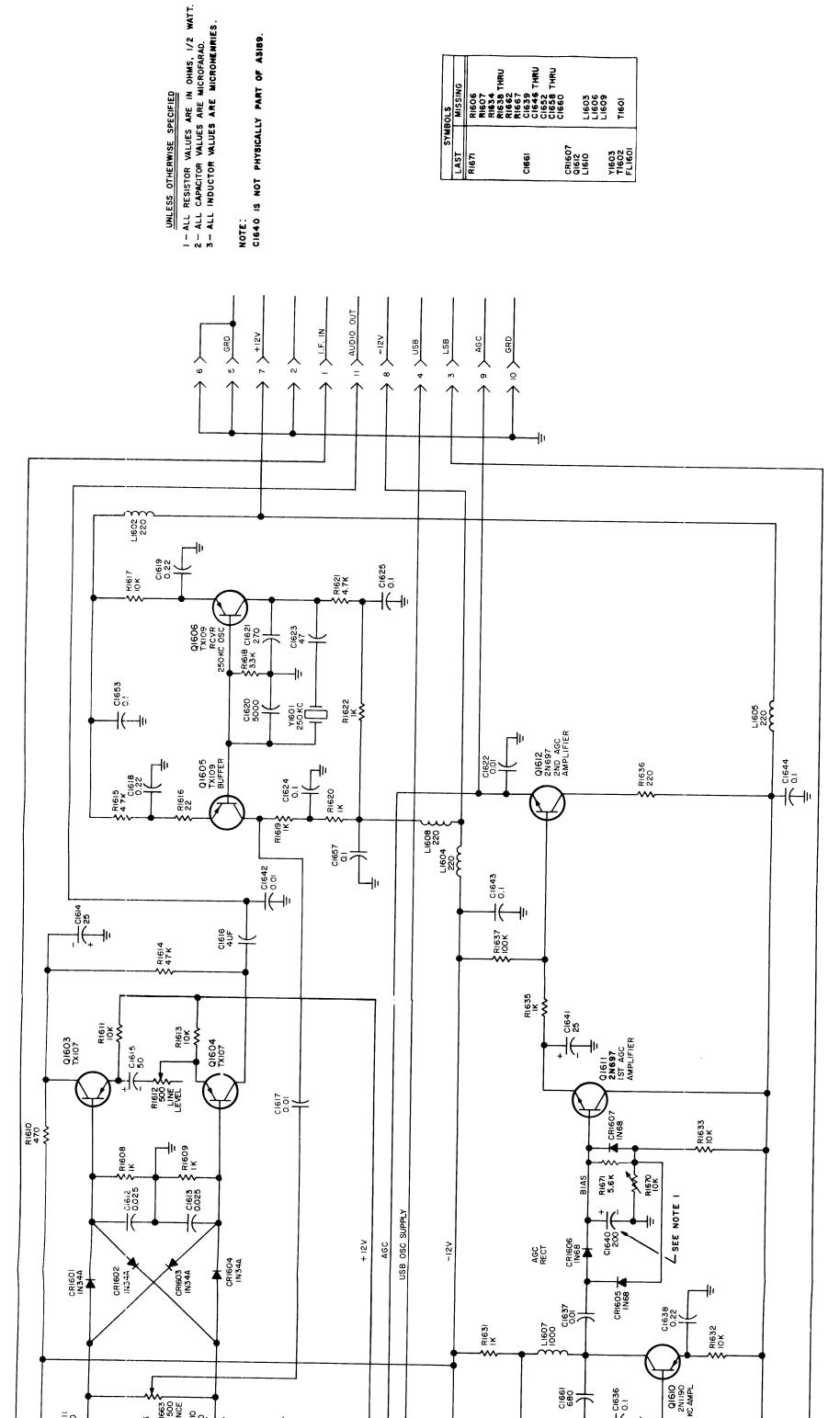
MAIN CHASSIS (SYMBOL SERIES 1700) REF		
SYMBOL	DESCRIPTION	PART NUMBER
R1759	RESISTOR, FIXED, COMPOSITION: 22 ohms, ±5%; 1/2 watt.	RC20GF220J
R1760	Same as R1704.	
R1761	Same as R1710.	
R1762	Same as R1717.	
R 1763	Same as R1717.	
R1764	Same as R1759.	
R1765	Same as R1704.	
R1766	Same as R1717.	
R1767	Same as R1704.	
R1768	Same as R1717.	
R1769	Same as R1704.	
R1770	Same as R1702.	
R1771	Same as R1717.	
R1772	Same as R1704.	
R1773	Same as R1702.	
R1774	RESISTOR, FIXED, COMPOSITION: 100 ohms, $\pm 5\%$; 1/2 watt.	RC20GF101J
T1701	TRANSFORMER, AUDIO FREQUENCY: fixed; primary impedance 25,000 ohms, CT; DC resistance 1,550 ohms, ±20%; secondary impedance 1,200 ohms, CT; DC resistance 88 ohms, ±20%; operating frequency range 200 to 15,000 cps; frequency response ±3 db at 250 to 3,500 cps.	TF267-4
Т1702	TRANSFORMER, AUDIO FREQUENCY: primary impedance 500 ohms, CT; DC resistance 60 ohms; secondary impedance 600 ohms; DC resistance 105 ohms; frequency range 100 cps to 20 KC; miniature open frame type, lacquer coated.	TF246-17Z
Т1703	TRANSFORMER, INTERMEDIATE FREQUENCY: fixed; operating frequency 1.75 mc; nom. primary inductance 5.5 uh, +0.300 uh; 5 terminals, wire lead type.	TZ124
Т1704	TRANSFORMER, INTERMEDIATE FREQUENCY: fixed; operating frequency 1.75 mc; nom. primary inductance 5.0 uh, ±0.250 uh; 4 terminals, wire lead type.	TZ125
XY1701	SOCKET, CRYSTAL: 2 silver plated beryllium copper contacts; for crystals having a 0.050 pin dia. and 0.486 spacing between pins.	TS104-2
XY1702	Same as XY1701.	
XY1703	Same as XY1701.	
Y1701	CRYSTAL UNIT, QUARTZ: 250 KC, \pm 002%; operating temperature range 75°C, \pm 0°C: parallel resonance; load capacitance 20 uuf, \pm 0.5 uuf; HC-6/U type holder.	CU47A/U250.000 KC

IF AND AUDIO TRANSMITTER BOARD ASSEMBLIES MAIN CHASSIS (SYMBOL SERIES 1700)

	MAIN CHASSIS (SYMBOL SERIES 1700)
REF SYMBOL	DESCRIPTION	TMC PART NUMBER
Y1702	CRYSTAL UNIT, QUARTZ: 2 MC, +.005%; operating temperature range -55°C to +30°C; max. capaci ⁷ ance 7.0 uuf; parallel resonance; load capacitance 32.0 uuf, +0.5 uuf; HC-6/U type holder.	CR18A/U2.000 000 MC
Y1703	CRYSTAL UNIT, QUARTZ: 1.5 MC, ±.005%; operating temperature range -55°C to +30°C; max. capacitance 7.0 uuf; parallel resonance; load capacitance 32.0 uuf, ±0.5 uuf; HC-6/U type holder.	CR18A/U1.500 000 MC
		,

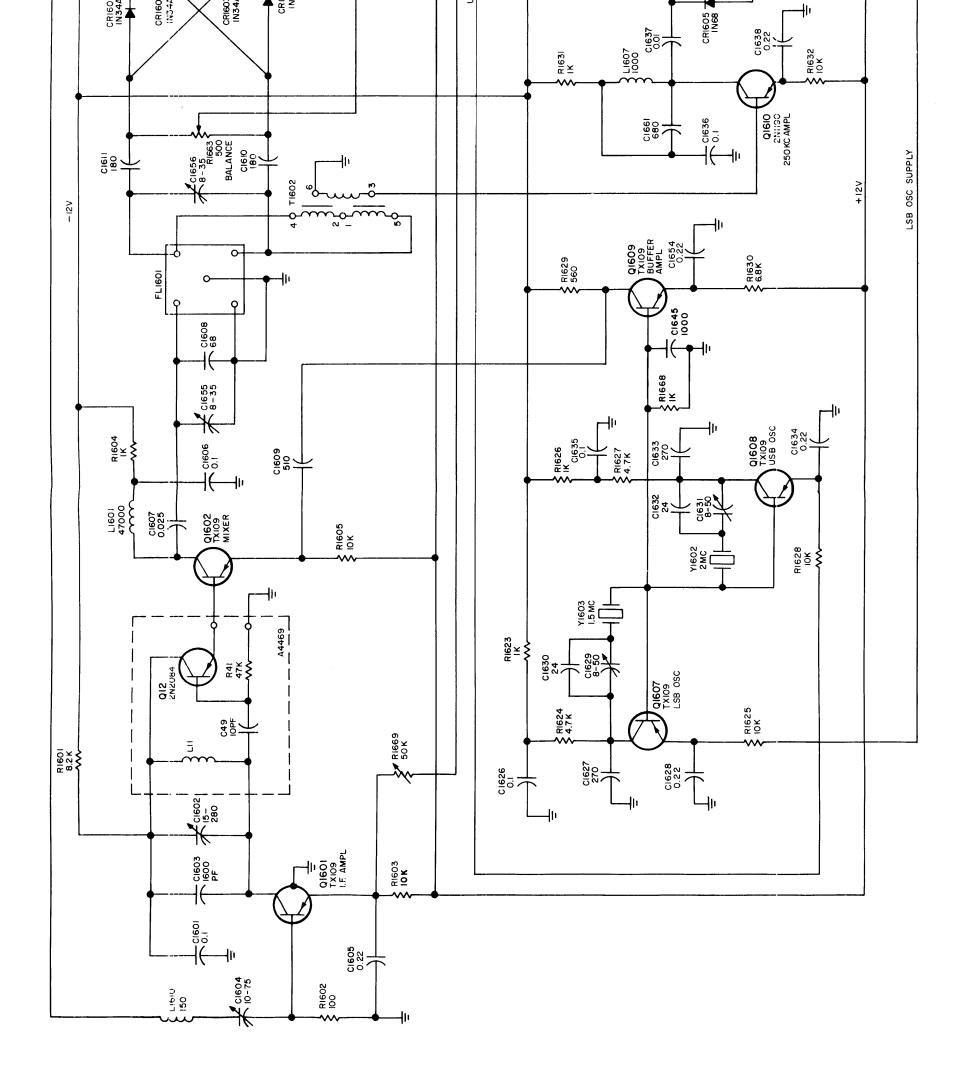
SECTION 7 SCHEMATIC DIAGRAMS





RIGOG RIGOT RIGOT RIGOT RIGOS RIGOS CIGOS CIGOS CIGOS CIGOS CIGOS

L1603 L1606 L1609 T1601



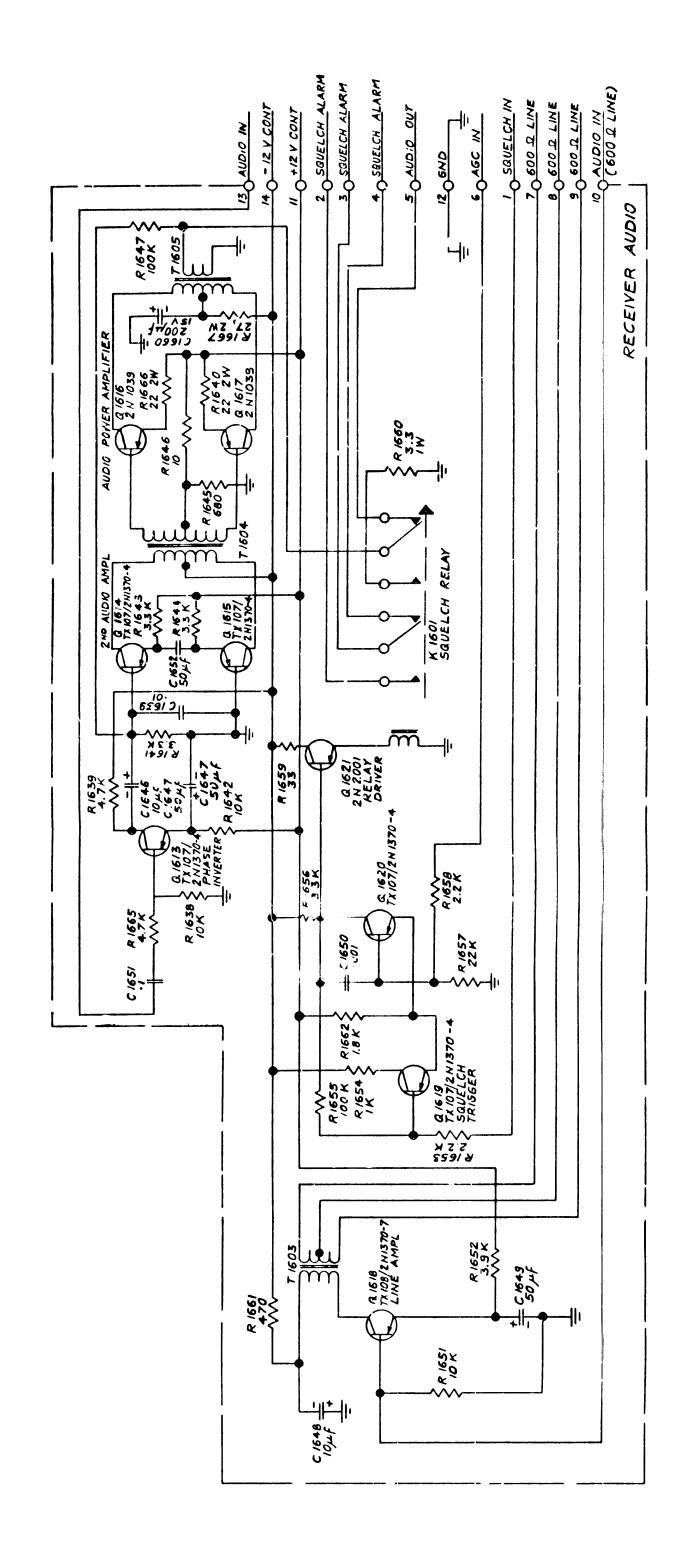


Figure 7-1. TTR-10A Schematic Diagram (Sheet 3 of 7)

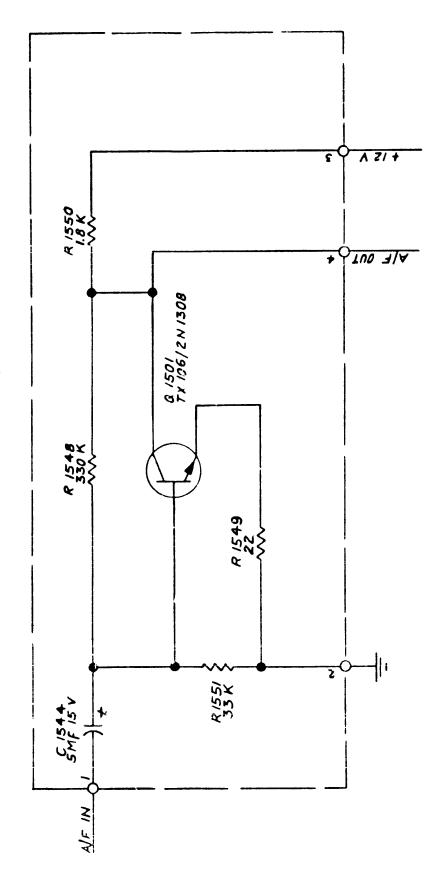


Figure 7-1. TTR-10A Schematic Diagram (Sheet 4 of 7)

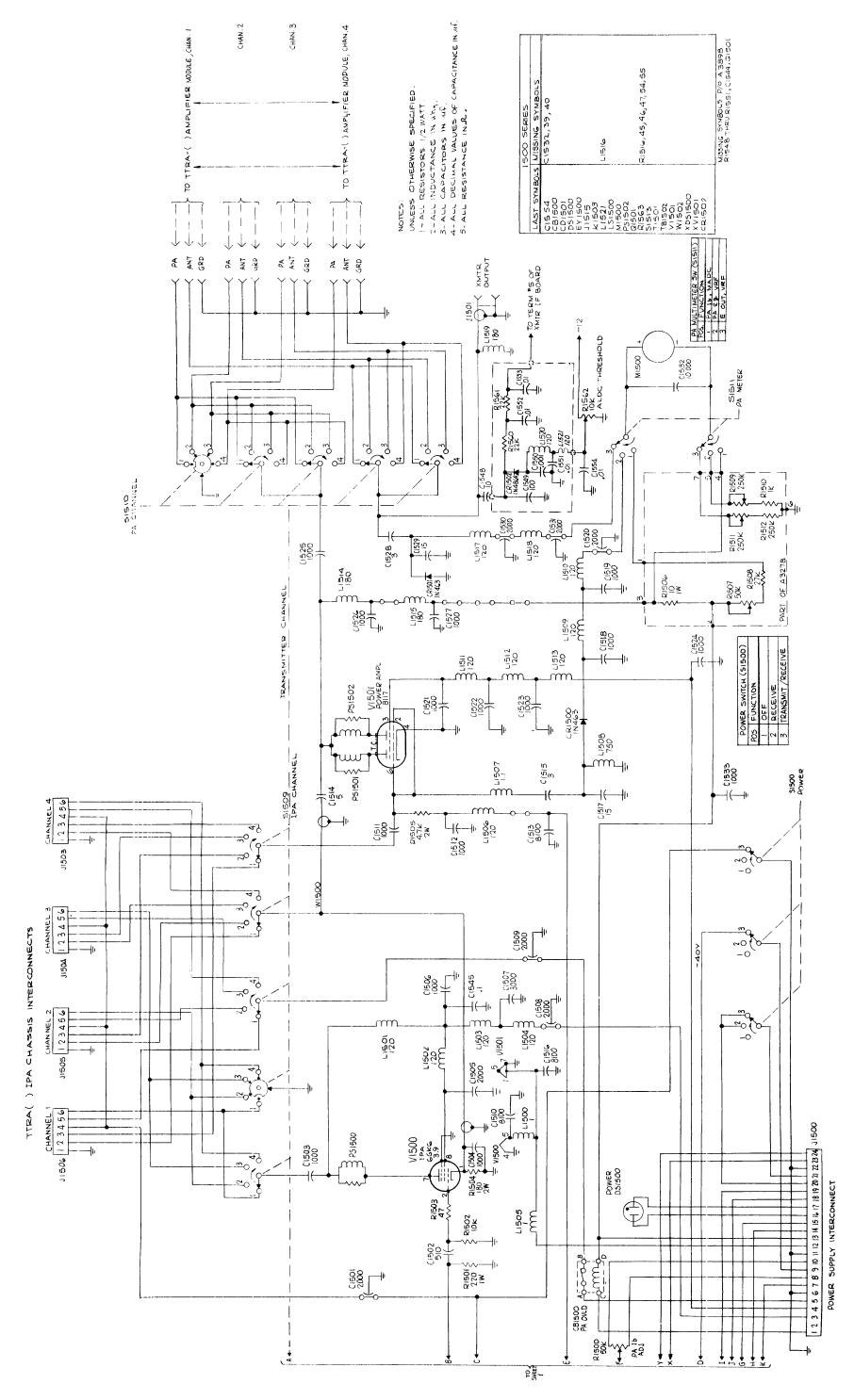
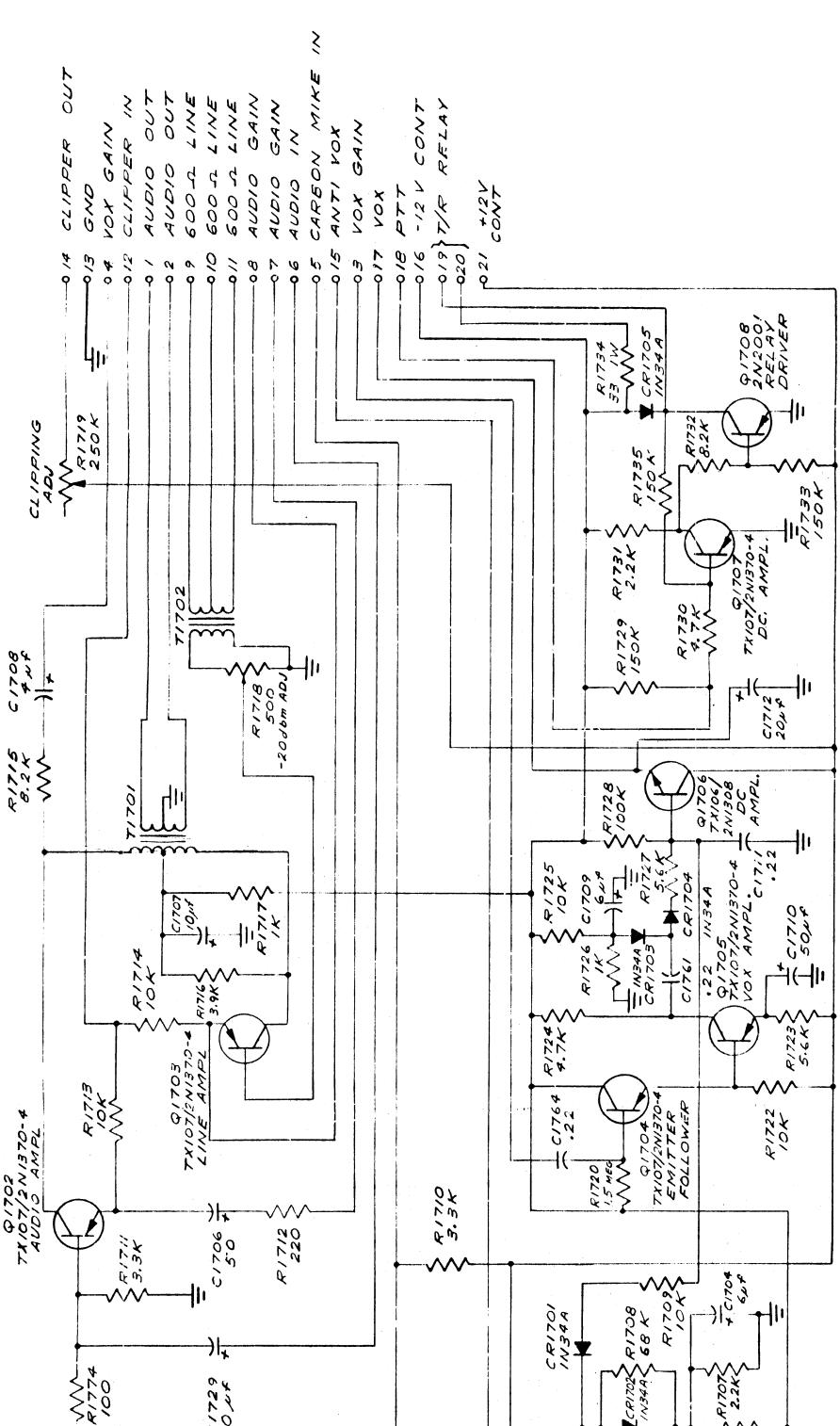
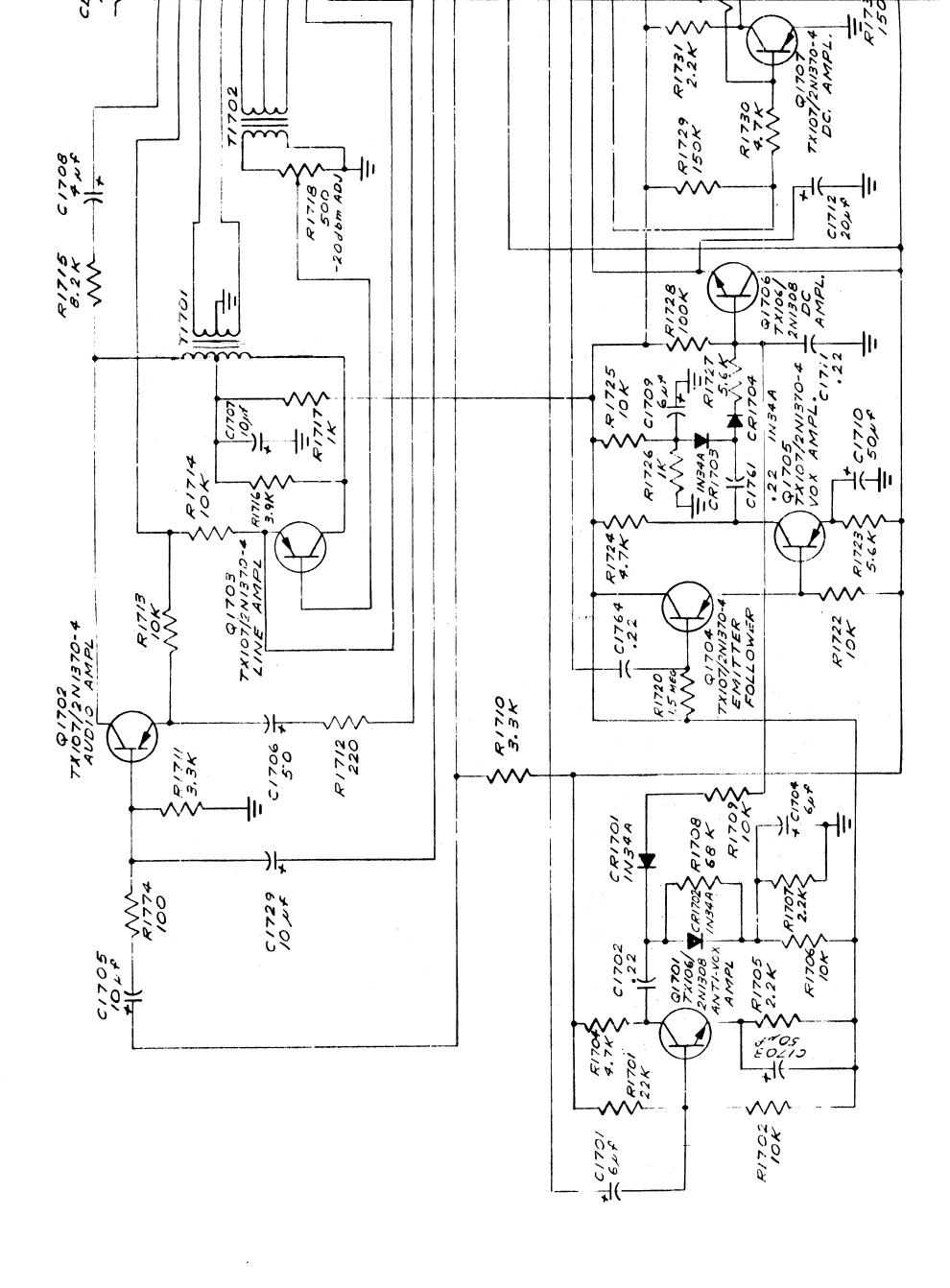
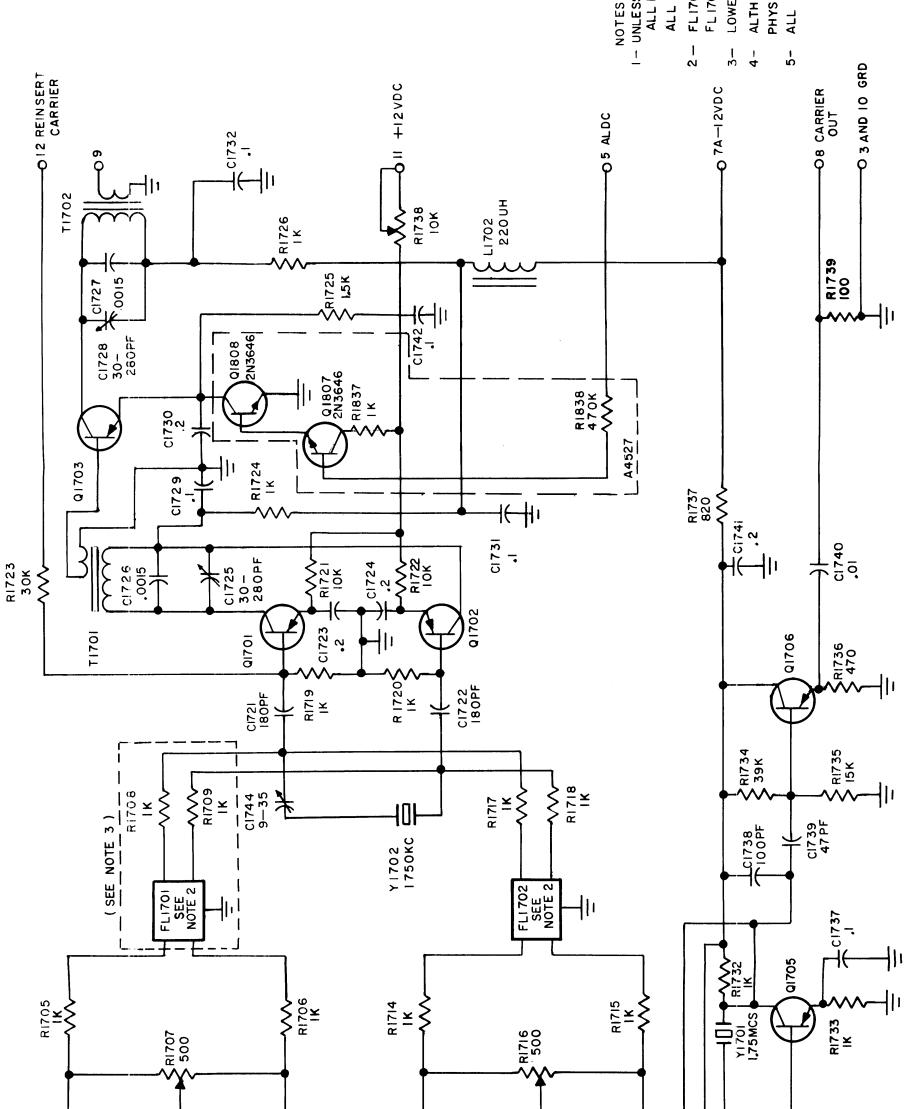


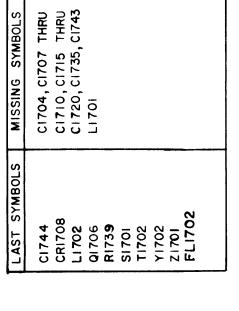
Figure 7-1. TTR-10A Schematic Diagram (sheet 5 of 7)





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I - UNLESS OTHERWISE SPECIFIED ALL RESISTORS IN OHMS, 1/2 WATT. ALL CAPACITORS MICROFARADS.

FLI701 IS FXI0014-1 FLI702 IS FXI0014-2

LOWER SIDEBAND FILTER REMOVED FOR "USB - ONLY APPLICATION

ALTHOUGH LSB AUDIO CIRCUITRY IS PHYSICALLY CONTAINED IN UNIT IT IS DISCONNECTED

ALL TRANSISTORS 2N2084.

TTR-10A Schematic Diagram
(Sheet 7 of 7) Figure 7-1.

